



电子元器件系列 (中国.厦门)

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	(Mini-Circuits)	
BLK-18	DC block, coaxial, 50 Ohm, F= 0,01-18 GHz, IL= 0,02-1 dB, Vin= 50 Vdc, Topr= -55° to +100°C, connector SMA(f)/SMA(m)	30,73
	(Mini-Circuits)	
SM-BF50	Adapter, SMA(m)/BNC(f), 50 Ohm, F= DC-2 GHz, VSWR= 1,20:1, Topr= -55° to +100°C	5,53
SM-BM50	Adapter, SMA(m)/BNC(m), 50 Ohm, F= DC-2 GHz, VSWR= 1,20:1, Topr= -55° to +100°C	5,53
	(Hittite Microwave Corp.)	
HMC230MS8	Attenuator, digital, 3-bit, F= 0,75-2 GHz, Att range= 28 dB, Step= 4 dB, IL= 1,8 dB, IP3= +45 dBm, Vcntrl= 0/ +3 V, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	3,34
HMC274QS16	Attenuator, digital, 5-bit, F= 0,7-2,7 GHz, Att range= 31 dB, Step= 1 dB, IL= 2,3 dB, IP3= +54 dBm, Vcntrl= 0/ +3 V, Topr= -40° to +85°C, plastic SM pkg 16L QSOP	4,45
HMC291	Attenuator, digital, 2-bit, F= 0,7-4 GHz, Att range= 12 dB, Step= 4 dB, IL= 0,9 dB, IP3= +54 dBm, Vcntrl= 0/ +3 V, Topr= -40° to +85°C, plastic SM pkg SOT26	2,89
HMC306MS10	Attenuator, digital, 5-bit, F= 0,7-3,8 GHz, Att range= 15,5 dB, Step= 0,5 dB, IL= 1,5 dB, IP3= +52 dBm, Vcntrl= 0/ +3 V, Topr= -40° to +85°C, plastic SM pkg 10L MSOP	4,88
HMC307QS16G	Attenuator, digital, 5-bit, F= DC-4 GHz, Att range= 31 dB, Step= 1 dB, IL= 1,9 dB, IP3= +44 dBm, Vcntrl= 0/ -5 V, Topr= -40° to +85°C, plastic SM pkg 16L QSOP	6,69
HMC346LP3	Attenuator, voltage variable, F= DC-14 GHz, Att range= 30 dB, IL= 2 dB, IP3= +10 dBm, Vcntrl= 0 to -3 V, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	21,28
HMC425LP3	Attenuator, digital, 6-bit, F= 2,4-8 GHz, Att range= 31,5 dB, Step= 0,5 dB, IL= 3,2 dB, IP3= +40 dBm, Vcntrl= 0/ +5 V, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	18,38
HMC468LP3	Attenuator, digital, 3-bit, F= DC-6 GHz, Att range= 1-7 dB, Step= 1 dB, IL= 0,7 dB, IP3= +50 dBm, Vcntrl= 0/ +5 V, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	4,45
HMC540LP3	Attenuator, digital, 4-bit, F= DC-5,5 GHz, Att range= 15 dB, Step= 1 dB, IL= 0,8 dB, IP3= +48 dBm, Vcntrl= TTL/CMOS, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	4,45
HMC541LP3	Attenuator, digital, 1-bit, F= DC-5 GHz, Att range= 10 dB, Step= dB, IL= 0,5 dB, IP3= +50 dBm, Vcntrl= TTL/CMOS, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	3,47
	(Honeywell)	
HRF-AT4510	Attenuator, digital, 5-bit, parallel interfce, 50 Ohm, F= DC-4 GHz, Att range= 15,5 dB, Step= 0,5 dB, IL= 1,6-4,4 dB, P1dB= +28,5 dBm, SM pkg 24L LPCC	4,30
HRF-AT4511	Attenuator, digital, 5-bit, seriall interfce, 50 Ohm, F= DC-4 GHz, Att range= 15,5 dB, Step= 0,5 dB, IL= 1,6-3,6 dB, P1dB= +29 dBm, SM pkg 16L LPCC	4,75
HRF-AT4520	Attenuator, digital, 5-bit, parallel interfce, 50 Ohm, F= DC-2,5 GHz, Att range= 31 dB, Step= 1 dB, IL= 2-2,8 dB, P1dB= +29 dBm, SM pkg 24L LPCC	3,65
HRF-AT4521	Attenuator, digital, 5-bit, seriall interfce, 50 Ohm, F= DC-2,5 GHz, Att range= 31 dB, Step= 1 dB, IL= 2-2,8 dB, P1dB= +29 dBm, SM pkg 16L LPCC	3,95
	(M/A-COM)	
AT65-0213	Attenuator, digital, 4-bit, TTL driver, 50 Ohm, F= DC-3 GHz, Att range= 15 dB, Step= 1dB, IL= 2,8 dB, P1dB= +28 dBm, Topr= -40° to +85°C, plastic SM pkg SOIC-16	24,36
AT90-1107	Attenuator, digital, 6-bit, TTL driver, 50 Ohm, F= DC-4 GHz, Att range= 31,5 dB, Step= 0,5 dB, IL= 4,5 dB, P1dB= +29 dBm, Topr= -40° to +85°C, plastic SM pkg FQFP-32	18,75
	(Mini-Circuits)	
BW-S7W2	Attenuator, fixed, precision, coaxial, 50 Ohm, F= DC-18 GHz, Att= 7 -0,4/+0,9 dB, P= 2 W, Topr= -55° to +100°C, connector SMA(m)/SMA(f)	41,93
DAT-15R5-PP	Attenuator, digital, 5-bit, parallel interfce, 50 Ohm, F= DC-4 GHz, Att range= 15,5 dB, Step= 0,5 dB, IL= 1,5 dB, IP3= +52 dBm, Vcntrl= 0,8/ +2,3 V, plastic SM pkg, 20L QFN 4x4 mm	9,00
DAT-15R5-SP	Attenuator, digital, 5-bit, serial interfce, 50 Ohm, F= DC-4 GHz, Att range= 15,5 dB, Step= 0,5 dB, IL= 1,5 dB, IP3= +52 dBm, Vcntrl= 0,8/ +2,3 V, plastic SM pkg, 20L QFN 4x4 mm	9,00
DAT-31R5-PP	Attenuator, digital, 6-bit, parallel interfce, 50 Ohm, F= DC-2,4 GHz, Att range= 31,5 dB, Step= 0,5 dB, IL= 1,5 dB, IP3= +52 dBm, Vcntrl= 0,8/ +2,3 V, plastic SM pkg, 20L QFN 4x4 mm	9,00
DAT-31R5-SP	Attenuator, digital, 6-bit, serial interfce, 50 Ohm, F= DC-2,4 GHz, Att range= 31,5 dB, Step= 0,5 dB, IL= 1,5 dB, IP3= +52 dBm, Vcntrl= 0,8/ +2,3 V, plastic SM pkg, 20L QFN 4x4 mm	9,00
GAS-2	Attenuator/Switches, bi-phase, 50 Ohm, BW= 10-1000 MHz, IL= 5,2 dB, Iso= 35 dB, P1dB= +20 dBm, Topr= -55° to +100°C, plug-in pkg	22,33
GAT-6	Attenuator, fixed, 50 Ohm, F= DC-8 GHz, Att= 6 ±0,30 dB, P= 0,5 W, Topr= -45° to +85°C, plastic SM pkg 3x3 mm	9,35
GAT-15	Attenuator, fixed, 50 Ohm, F= DC-8 GHz, Att= 15±0,40 dB, P= 0,5 W, Topr= -45° to +85°C, plastic SM pkg 3x3 mm	9,35
GAT-20	Attenuator, fixed, 50 Ohm, F= DC-8 GHz, Att= 20±0,40 dB, P= 0,5 W, Topr= -45° to +85°C, plastic SM pkg 3x3 mm	9,35
LAT-1	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 1 ±0,30 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-3	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 3 ±0,30 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-3+	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 3 ±0,30 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95

LAT-4	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 4 ±0,30 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-5	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 5 ±0,30 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-6	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 6 ±0,30 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-7	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 7 ±0,30 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-8	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 8 ±0,40 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-9	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 9 ±0,40 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-12	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 12±0,80 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-15	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 15±0,80 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
LAT-20	Attenuator, fixed, 50 Ohm, F= DC-2,5 GHz, Att= 20±1,50 dB, P= 0,5 W, Topr= -55° to +85°C, plastic SM pkg SOT-143	8,95
NF-BM-6	Adaptenuator, fixed, coaxial, 50 Ohm, F= DC-2000 MHz, Att= 6 ±0,30 dB, P= 0,5 W, Topr= -55° to +100°C, connector N(f)/BNC(m)	27,93
PAT-1	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 1 ±0,20 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X,	9,95
PAT-2	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 2 ±0,20 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-3	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 3 ±0,30 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-4	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 4 ±0,30 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-5	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 5 ±0,30 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-6	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 6 ±0,30 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-7	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 7 ±0,30 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-8	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 8 ±0,40 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-9	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 9 ±0,40 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-10	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 10±0,40 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-12	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 12±0,60 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-15	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 15±0,60 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-20	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 20±1,30 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
PAT-30+	Attenuator, fixed, 50 Ohm, F= DC-7 GHz, Att= 30±1,70 dB, P= 1 W, Topr= -55° to +100°C, ceramic SM pkg 4L Micro-X	9,95
RVA-2500	Attenuator, voltage variable, 50 Ohm, F= 10-2500 MHz, Att range= 40 dB, IL= 3,3 dB, IP3= +43 dBm, Vcntrl= 0/ +17 V, Topr= -55° to +85°C, metal SM pkg	14,95
SM-BM-6	Adaptenuator, fixed, coaxial, 50 Ohm, F= DC-2000 MHz, Att= 6 ±0,30 dB, P= 0,5 W, Topr= -55° to +100°C, connector SMA(m)/BNC(m)	27,93
SYAS-1	Attenuator/Switches, bi-phase, 50 Ohm, BW= 2-400 MHz, IL= 1,6 dB, Iso= 45 dB, P1dB= +20 dBm, Topr= -40° to +85°C, metal SM pkg	13,93
ZFAT-124	Attenuator, digital, 3-bit, precision, pin diode, 50 Ohm, F= 10-1000 MHz, Att range= 7 dB, Step= 1 dB, P= +15 dBm, Vcntrl= TTL, Topr= -55°C to +100°C, connector SMA(f)	125,93
ZFAT-3610	Attenuator, digital, 3-bit, precision, pin diode, 50 Ohm, F= 10-1000 MHz, Att range= 19 dB, Step= 3 dB, P= +15 dBm, Vcntrl= TTL, Topr= -55°C to +100°C, connector SMA(f)	125,93
ZFAT-51020	Attenuator, digital, 3-bit, precision, pin diode, 50 Ohm, F= 10-1000 MHz, Att range= 35 dB, Step= 5 dB, P= +15 dBm, Vcntrl= TTL, Topr= -55°C to +100°C, connector SMA(f)	125,93
ZFAT-R512	Attenuator, digital, 3-bit, precision, pin diode, 50 Ohm, F= 10-1000 MHz, Att range= 3,5 dB, Step= 0,5 dB, P= +15 dBm, Vcntrl= TTL, Topr= -55°C to +100°C, connector SMA(f)	125,93
	(RF Micro Devices)	
RF2494	Front- End (LNA/mixer), F= 2400-2500 MHz, Gn= 28 dB, NF= 4,5 dB, supply= 2,7-3,6 V/ 17 mA, Topr= -40° to +85°C, plastic SM pkg QFN-16	15,15
	(Hittite Microwave Corp.)	
HMC358MS8 G	VCO, w/Buffer, F= 5,6-6,8 GHz, Ph N= -105 dBc/Hz (100 kHz), OP= +10,0 dBm, Vtune= 0-10 V, supply= 3 V/ 100 mA, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	13,09
HMC384LP4	VCO, w/Buffer, F= 2,05-2,25 GHz, Ph N= -112 dBc/Hz (100 kHz), OP= +3,5 dBm, Vtune= 0-10 V, supply= 3 V/ 35 mA, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	7,93

HMC385LP4	VCO, w/Buffer, F= 2,25-2,5 GHz, Ph N= -115 dBc/Hz (100 kHz), OP= +4,5 dBm, Vtune= 0-10 V, supply= 3 V/ 35 mA, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	7,93
HMC389LP4	VCO, w/Buffer, F= 3,35-3,55 GHz, Ph N= -112 dBc/Hz (100 kHz), OP= +4,7 dBm, Vtune= 0-10 V, supply= 3 V/ 41 mA, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	11,78
HMC390LP4	VCO, w/Buffer, F= 3,55-3,9 GHz, Ph N= -112 dBc/Hz (100 kHz), OP= +4,7 dBm, Vtune= 0-10 V, supply= 3 V/ 42 mA, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	11,78
HMC391LP4	VCO, w/Buffer, F= 3,9-4,45 GHz, Ph N= -106 dBc/Hz (100 kHz), OP= +5,0 dBm, Vtune= 0-10 V, supply= 3 V/ 30 mA, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	12,46
HMC416LP4	VCO, w/Buffer, F= 2,75-3 GHz, Ph N= -114 dBc/Hz (100 kHz), OP= +4,5 dBm, Vtune= 0-10 V, supply= 3 V/ 37 mA, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	11,78
HMC431LP4	VCO, w/Buffer, F= 5,5-6,1 GHz, Ph N= -102 dBc/Hz (100 kHz), OP= +2,0 dBm, Vtune= 0-10 V, supply= 3 V/ 27 mA, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	13,09
HMC466LP4	VCO, w/Buffer, F= 6,1-6,72 GHz, Ph N= -101 dBc/Hz (100 kHz), OP= +4,5 dBm, Vtune= 0-10 V, supply= 3 V/ 31 mA, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	16,63
	(MICRONETICS)	
M3500C-0102T	VCO, F= 100-200 MHz, Ph N= -102 dBc/Hz (10 kHz), OP= +11,0 dBm, Vtune= 1,3-12,9 V, supply= 12 V/ 27 mA, Topr= 0° to +70°C, plug-in pkg	55,70
MW500-1231	VCO, F= 3300-4000 MHz, Ph N= -95 dBc/Hz (10 kHz), OP= 7 ±2,0 dBm, Vtune= 1-18 V, supply= 12 V/35 mA, Topr= -20° to +75°C, .5"x .5" SMD	136,50
MW500-1262	VCO, F= 4900-6500 MHz, Ph N= -80 dBc/Hz (10 kHz), OP= 10 ±2,5 dBm, Vtune= 1-22 V, supply= 15 V/50 mA, Topr= -20° to +75°C, .5"x .5" SMD	136,50
	(Mini-Circuits)	
JTOS-50P	VCO, F= 24-29 MHz, Ph N= -108 dBc/Hz (10 kHz), OP= +9,5 dBm, Vtune= 0,5-5 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	27,93
JTOS-100	VCO, F= 50-100 MHz, Ph N= -108 dBc/Hz (10 kHz), OP= +8,3 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	26,53
JTOS-150	VCO, F= 75-150 MHz, Ph N= -106 dBc/Hz (10 kHz), OP= +9,5 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	26,53
JTOS-200	VCO, F= 100-200 MHz, Ph N= -105 dBc/Hz (10 kHz), OP= +10,0 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	26,53
JTOS-200P	VCO, F= 95-120 MHz, Ph N= -102 dBc/Hz (10 kHz), OP= +10,0 dBm, Vtune= 0,5-5 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	27,93
JTOS-300	VCO, F= 150-280 MHz, Ph N= -102 dBc/Hz (10 kHz), OP= +9,0 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	29,33
JTOS-300P	VCO, F= 148-174 MHz, Ph N= -102 dBc/Hz (10 kHz), OP= +10,0 dBm, Vtune= 0,5-5 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	30,73
JTOS-400P	VCO, F= 194-220 MHz, Ph N= -102 dBc/Hz (10 kHz), OP= +11,0 dBm, Vtune= 0,5-5 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	30,73
JTOS-535	VCO, F= 300-525 MHz, Ph N= -97 dBc/Hz (10 kHz), OP= +9,5 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	29,33
JTOS-765	VCO, F= 485-765 MHz, Ph N= -98 dBc/Hz (10 kHz), OP= +8,0 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	30,73
JTOS-1025	VCO, F= 680-1025 MHz, Ph N= -94 dBc/Hz (10 kHz), OP= +8,6 dBm, Vtune= 1-16 V, supply= 12 V/ 22 mA, Topr= -55° to +85°C, metal SM pkg	33,53
JTOS-1550	VCO, F= 1150-1550 MHz, Ph N= -101 dBc/Hz (10 kHz), OP= +7,0 dBm, Vtune= 0,5-20 V, supply= 12 V/ 30 mA, Topr= -55° to +85°C, metal SM pkg	34,93
JTOS-1650	VCO, F= 1200-1650 MHz, Ph N= -95 dBc/Hz (10 kHz), OP= +7,0 dBm, Vtune= 1-13 V, supply= 12 V/ 30 mA, Topr= -55° to +85°C, metal SM pkg	34,93
JTOS-1750	VCO, F= 1350-1750 MHz, Ph N= -101 dBc/Hz (10 kHz), OP= +7,0 dBm, Vtune= 0,5-20 V, supply= 12 V/ 30 mA, Topr= -55° to +85°C, metal SM pkg	34,93
JTOS-1910	VCO, F= 1625-1910 MHz, Ph N= -97 dBc/Hz (10 kHz), OP= +7,0 dBm, Vtune= 1-12 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	34,93
JTOS-2000	VCO, F= 1370-2000 MHz, Ph N= -95 dBc/Hz (10 kHz), OP= +12,0 dBm, Vtune= 1-22 V, supply= 8 V/ 30 mA, Topr= -55° to +85°C, metal SM pkg	34,93
JTOS-2700V	VCO, F= 2050-2700 MHz, Ph N= -94 dBc/Hz (10 kHz), OP= +8,0 dBm, Vtune= 0,5-18 V, supply= 5 V/ 20 mA, Topr= -55° to +85°C, metal SM pkg	37,73
JTOS-3000	VCO, F= 2300-3000 MHz, Ph N= -90 dBc/Hz (10 kHz), OP= +10,0 dBm, Vtune= 0,5-12 V, supply= 5 V/ 25 mA, Topr= -55° to +85°C, metal SM pkg	36,33
POS-25	VCO, F= 15-25 MHz, Ph N= -105 dBc/Hz (10 kHz), OP= +7,0 dBm, Vtune= 1-11 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	30,73
POS-50	VCO, F= 25-50 MHz, Ph N= -110 dBc/Hz (10 kHz), OP= +8,5 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	23,73
POS-75	VCO, F= 37,5-75 MHz, Ph N= -110 dBc/Hz (10 kHz), OP= +8,0 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	23,73
POS-75P	VCO, F= 35-43 MHz, Ph N= -113 dBc/Hz (10 kHz), OP= +9,0 dBm, Vtune= 0,5 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	25,13
POS-100	VCO, F= 50-100 MHz, Ph N= -107 dBc/Hz (10 kHz), OP= +8,3 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	23,73
POS-400	VCO, F= 200-380 MHz, Ph N= -98 dBc/Hz (10 kHz), OP= +9,5 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	26,53

POS-500W	VCO, F= 250-500 MHz, Ph N= -100 dBc/Hz (10 kHz), OP= +10,0 dBm, Vtune= 1-16 V, supply= 12 V/ 25 mA, Topr= -55° to +85°C, metal plug-in pkg	33,53
POS-535	VCO, F= 300-525 MHz, Ph N= -93 dBc/Hz (10 kHz), OP= +8,8 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	26,53
POS-765	VCO, F= 485-765 MHz, Ph N= -85 dBc/Hz (10 kHz), OP= +9,5 dBm, Vtune=1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	27,93
POS-800W	VCO, F= 400-800 MHz, Ph N= -93 dBc/Hz (10 kHz), OP= +8,0 dBm, Vtune= 0,5-18 V, supply= 10 V/ 25 mA, Topr= -55° to +85°C, metal plug-in pkg	30,73
POS-1000W	VCO, F= 500-1000 MHz, Ph N= -93 dBc/Hz (10 kHz), OP= +7,0 dBm, Vtune= 1-16 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, metal plug-in pkg	34,93
POS-1025	VCO, F= 685-1025 MHz, Ph N= -84 dBc/Hz (10 kHz), OP= +9,0 dBm, Vtune= 1-16 V, supply= 12 V/ 22 mA, Topr= -55° to +85°C, metal plug-in pkg	30,73
POS-1060	VCO, F= 750-1060 MHz, Ph N= -90 dBc/Hz (10 kHz), OP= +12,0 dBm, Vtune= 1-20 V, supply= 8 V/ 30 mA, Topr= -55° to +85°C, metal plug-in pkg	27,93
POS-1400A	VCO, F= 975-1400 MHz, Ph N= -95 dBc/Hz (10 kHz), OP= +13,0 dBm, Vtune= 1-20 V, supply= 8 V/ 30 mA, Topr= -55° to +85°C, metal plug-in pkg	27,93
POS-2000A	VCO, F= 1370-2000 MHz, Ph N= -97 dBc/Hz (10 kHz), OP= +11,8 dBm, Vtune= 1-20 V, supply= 8 V/ 30 mA, Topr= -55° to +85°C, metal plug-in pkg	27,93
POS-2120W	VCO, F= 1060-2120 MHz, Ph N= -97 dBc/Hz (10 kHz), OP= +8,0 dBm, Vtune= 0,5-20 V, supply= 12 V/ 28 mA, Topr= -55° to +85°C, metal plug-in pkg	37,73
ROS-100	VCO, F= 50-100 MHz, Ph N= -105 dBc/Hz (10 kHz), OP= +8,3 dBm, Vtune= 0,5-17 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	25,13
ROS-150	VCO, F= 1000-1500 MHz, Ph N= -104 dBc/Hz (10 kHz), OP= +8,0 dBm, Vtune= 0,5-20 V, supply= 10 V/ 26 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	25,13
ROS-285PV	VCO, F= 245-285 MHz, Ph N= -100 dBc/Hz (10 kHz), OP= +3,0 dBm, Vtune= 0,5-5 V, supply= 5 V/ 20 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	32,13
ROS-400	VCO, F= 200-380 MHz, Ph N= -100 dBc/Hz (10 kHz), OP=+9,5 dBm, Vtune= 0,5-17 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	27,93
ROS-535	VCO, F= 300-525 MHz, Ph N= -98 dBc/Hz (10 kHz), OP= +6,0 dBm, Vtune= 1-17 V, supply= 12 V/ 20 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	27,93
ROS-660PV	VCO, F= 640-660 MHz, Ph N= -107 dBc/Hz (10 kHz), OP= 0 dBm, Vtune= 0,5-5 V, supply= 5 V/ 15 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	34,93
ROS-715+	VCO, F= 680-715 MHz, Ph N= -113 dBc/Hz (10 kHz), OP= -0,5 dBm, Vtune= 0,5-5 V, supply= 5 V/ 16 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	34,93
ROS-1000V	VCO, F= 900-1000 MHz, Ph N= -102 dBc/Hz (10 kHz), OP= 0 dBm, Vtune= 0,5-12 V, supply= 5 V/ 25 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	29,33
ROS-1100V	VCO, F= 1000-1100 MHz, Ph N= -103 dBc/Hz (10 kHz), OP= 0 dBm, Vtune= 0,5-12 V, supply= 5 V/ 30 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	29,33
ROS-1410	VCO, F= 850-1410 MHz, Ph N= -99 dBc/Hz (10 kHz), OP= +7,0 dBm, Vtune= 0,5-11 V, supply= 12 V/ 25 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	34,93
ROS-1435PV	VCO, F= 1375-1435 MHz, Ph N= -101 dBc/Hz (10 kHz), OP= +3,0 dBm, Vtune= 0,5-5 V, supply= 5 V/ 20 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	34,93
ROS-1900	VCO, F= 1450-1900 MHz, Ph N= -106 dBc/Hz (10 kHz), OP= +7,0 dBm, Vtune= 0,5-20 V, supply= 10 V/ 25 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	32,13
ROS-2160W	VCO, F= 1160-2160 MHz, Ph N= -97 dBc/Hz(10 kHz), OP= +5,0 dBm, Vtune= 0,5-20 V, supply= 10 V/ 30 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	41,93
ROS-2500	VCO, F= 1600-2500 MHz, Ph N= -90 dBc/Hz (10 kHz), OP= +6,5 dBm, Vtune= 0,5-14 V, supply= 12 V/ 25 mA, Topr= -55° to +85°C, ,5"x ,5" SMD	37,73
ZX95-1700W-S	VCO, F= 770-1700 MHz, Ph N= -100 dBc/Hz (10 kHz), OP= +9,0 dBm, Vtune= 1-24 V, supply= 12 V/35 mA, Topr= -55° to +85°C, connector SMA(f)	69,93
	(Z-Communications, Inc.)	
V-0120S	VCO, F= 90-140 MHz, Ph N= -103 dBc/Hz (10 kHz), OP= 5±3 dBm, Vtune= 0-12 V, supply= 12 V/ 14 mA, Topr= 0° to +70°C, ,91"x ,91" SMD	11,98
V-0350	VCO, F= 300-400 MHz, Ph N= -95 dBc/Hz (10 kHz), OP= 10±2 dBm, Vtune= 0-15 V, supply= 15 V/ 30 mA, Topr= 0° to +70°C, ,5"x ,5" SMD	11,98
V-0450	VCO, F= 400-500 MHz, Ph N= -95 dBc/Hz (10 kHz), OP= 10±3 dBm, Vtune= 0-15 V, supply= 15 V/ 26 mA, Topr= 0° to +70°C, ,5"x ,5" SMD	11,98
V-0550	VCO, F= 500-600 MHz, Ph N= -90 dBc/Hz (10 kHz), OP= 11±2 dBm, Vtune= 0-15 V, supply= 15 V/ 25 mA, Topr= 0° to +70°C, ,5"x ,5" SMD	11,98
V900ME01	VCO, F= 3500-4000 MHz, Ph N= -91 dBc/Hz (10 kHz), OP= 6±3 dBm, Vtune= 2-18 V, supply= 8 V/ 25 mA, Topr= -30° to +75°C, ,5"x ,5" SMD	31,83
	(Mini-Circuits)	
ADP-2-10	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 5-1000 MHz, Iso= 23 dB, IL= 0,4 dB, IP= 0,5 W, Topr= -40° to +85°C, plastic SM pkg	25,13
ADP-2-20	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 20-2000 MHz, Iso= 18 dB, IL= 0,7 dB, IP= 1 W, Topr= -40° to +85°C, plastic SM pkg	30,73
BP4C	Power splitter/combiner, 4 way, 0°, 50 Ohm, F= 810-960 MHz, Iso= 25 dB, IL= 1 dB, IP= 1,5 W, Topr= -40° to +85°C, plastic SM pkg	9,95
HPQ-05W	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 380-490 MHz, Iso= 25 dB, IL= 0,2 dB, IP= 1 W, Topr= -40° to +85°C, open style, ceramic base, SM pkg	11,95

HPQ-08	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 680-790 MHz, Iso= 24 dB, IL= 0,25 dB, IP= 1 W, Topr= -40° to +85°C, open style, ceramic base, SM pkg	11,95
JPS-2-1W	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 3-750 MHz, Iso= 36-19 dB, IL= 0,5-0,9 dB, IP= 1 W, Topr= -40° to +85°C, ceramic SM pkg	12,53
JSPQ-80	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 10-80 MHz, Iso=44 dB, IL=0,45 dB, IP= 1 W, Topr= -40° to +85°C, metal SM pkg	27,93
LRPQ-700	Power splitter/combiner, 2 way, 90°, 50 Ohm, F=500-700 MHz, Iso=23 dB, IL=0,2 dB, IP= 1 W, Topr= -40° to +85°C, ceramic SM pkg	13,93
LRPQ-700J	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 500-700 MHz, Iso= 23 dB, IL= 0,2 dB, IP= 1 W, Topr= -40° to +85°C, ceramic SM pkg	13,93
LRPS-2-1J	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 5-500 MHz, Iso= 33 dB, IL= 0,3 dB, IP= 1 W, Topr= -40° to +85°C, ceramic SM pkg	12,53
LRPS-2-4	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 10-1000 MHz, Iso= 23 dB, IL= 0,4 dB, IP= 1 W, Topr= -40° to +85°C, ceramic SM pkg, case QQQ130 (non-waterproof)	27,93
LRPS-2-11	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 20-2000 MHz, Iso= 21 dB, IL= 0,7 dB, IP= 1 W, Topr= -40° to +85°C, ceramic SM pkg, case QQQ130 (non-waterproof)	34,93
LRPS-2-25	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 1700-2500 MHz, Iso= 20 dB, IL= 0,8 dB, IP= 1 W, Topr= -40° to +85°C, ceramic SM pkg	30,73
PSC-2-1	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 0,1-400 MHz, Iso= 20-25 dB, IL= 0,2-0,6 dB, IP= 1 W, Topr= -55° to +100°C, metal plug-in pkg	16,73
PSC-2-1W	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 2-650 MHz, Iso= 22-30 dB, IL= 0,3-0,8 dB, IP= 1 W, Topr= -55° to +100°C, metal plug-in pkg	26,53
PSC-2-4	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 10-1000 MHz, Iso= 30-25 dB, IL= 0,6-0,7 dB, IP= 1 W, Topr= -55° to +100°C, metal plug-in pkg	36,33
PSC-3-1	Power splitter/combiner, 3 way, 0°, 50 Ohm, F= 1- 200 MHz, Iso=40-45 dB, IL=-0,6 dB, IP= 1 W, Topr= -55° to +100°C, metal plug-in pkg	36,33
PSC-4-1W+	Power splitter/combiner, 4 way, 0°, 50 Ohm, F= 1- 500 MHz, Iso= 29-25 dB, IL= 0,4-0,8 dB, IP= 0,5 W, Topr= -55° to +100°C, metal plug-in pkg	57,33
QBA-12	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 800-1200 MHz, Iso= 23 dB, IL= 0,25 dB, IP= 50 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	11,95
QBA-24	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 1900-2400 MHz, Iso= 21 dB, IL= 0,55 dB, IP= 20 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	11,95
QCC-20+	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 1200-2200 MHz, Iso= 25 dB, IL= 0,4 dB, IP= 17,5 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	14,95
QCN-7	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 425-675 MHz, Iso= 17 dB, IL= 0,4 dB, IP= 15 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	12,50
QCN-25	Power splitter/combiner, 2 way, 90°, 50 Ohm, F= 1350-2450 MHz, Iso= 25 dB, IL= 0,4 dB, IP= 150 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	12,50
SBA-2-14	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 1200-1600 MHz, Iso= 16 dB, IL= 0,6 dB, IP= 2 W, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,95
SBB-2-13	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 950-1300 MHz, Iso= 24 dB, IL= 0,6 dB, IP= 10 W, Topr= -40° to +85°C, blue cell technology, ceramic SM pkg	9,95
SBB-2-21W	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 1700-2100 MHz, Iso= 22 dB, IL= 0,6 dB, IP= 10 W, Topr= -40° to +85°C, blue cell technology, ceramic SM pkg	9,95
SBB-2-23	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 2000-2300 MHz, Iso= 24 dB, IL= 0,6 dB, IP= 10 W, Topr= -40° to +85°C, blue cell technology, ceramic SM pkg	9,95
SBTC-2-20	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 200-2000 MHz, Iso= 20 dB, IL= 0,8 dB, IP= 0,5 W, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,45
SBTC-2-25	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 1000-2500 MHz, Iso= 20 dB, IL= 1,4 dB, IP= 1 W, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,45
SCA-4-10+	Power splitter/combiner, 4 way, 0°, 50 Ohm, F= 5-1000 MHz, Iso= 25 dB, IL= 0,8 dB, IP= 0,5 W, Topr= -40° to +85°C, blue cell technology, ceramic SM pkg	11,95
SCN-2-45	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 3700-4200 MHz, Iso= 22 dB, IL= 0,7 dB, IP= 4 W, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	10,95
SCN-2-65	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 5500-6500 MHz, Iso= 17 dB, IL= 0,5 dB, IP= 4 W, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	10,95
SCP-4-1W-75	Power splitter/combiner, 4 way, 0°, 75 Ohm, F=10-750 MHz, Iso= 36-24 dB, IL= 0,5-0,8 dB, IP= 0,5 W, Topr= -40° to +85°C, plastic SM pkg	39,13
TCP-2-25	Power splitter/combiner, 2 way, 0°, 50 Ohm, F= 200-2500 MHz, Iso= 18 dB, IL= 0,8 dB, IP= 0,5 W, Topr= -40° to +85°C, plastic SM pkg	9,95
ZFSC-6-1-75	Power splitter/combiner, 6 way, 0°, 75 Ohm, F= 1-200 MHz, Iso= 26 dB, IL= 0,75 dB, IP= 1 W, Topr= -55° to +100°C, connector BNC	144,13
	(Atmel Corp.)	
U832BS-FP	Frequency divider (: 2), F= 300-3000 MHz, supply= 5 V/12 mA, Topr= -25° to +85°C, plastic SM pkg SO8	7,30
	(California Eastern Laboratories)	
UPB1508GV	Frequency divider (: 2), F< 3000 MHz, supply= 5 V/12 mA, Topr= -40° to +85°C, plastic SM pkg 8L SSOP	2,70
	(Centellax, Inc.)	
UXN14M9P	Frequency divider, programmable, integer (: 8 to :511), F= DC-14 GHz, OP=4 dBm, Topr= -40° to +85°C, SM pkg 6x6, 40L QFN	118,80

	(Gec Plessey Semiconductors)	
SP8719/NA/D P	Frequency divider (: 80/81), programmable, F= DC-520 MHz, supply= 5 V/10,5 mA, Topr= -40° to +85°C, plastic SM pkg	3,55
	(Hittite Microwave Corp.)	
HMC251MS8	Frequency divider (: 2), F= 3-6,5 GHz, Ph N= -130 dBc/Hz (10 kHz), supply= 5 V/27 mA, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	4,67
HMC362	Frequency divider (: 4), F= DC-11 GHz, Ph N= -149 dBc/Hz (100 kHz), supply= 5 V/68 mA, Topr= -55° to +85°C, chip DIE	-
HMC362S8G	Frequency divider (: 4), F= DC-12 GHz, Ph N= -149 dBc/Hz (100 kHz), supply= 5 V/68 mA, Topr= -40° to +85°C, plastic SM pkg 8L SOIC	13,62
HMC363S8G	Frequency divider (: 8), F= DC-12 GHz, Ph N= -153 dBc/Hz (100 kHz), supply= 5 V/70 mA, Topr= -40° to +85°C, plastic SM pkg 8L SOIC	13,62
HMC364S8G	Frequency divider (: 2), F= DC-12,5 GHz, Ph N= -145 dBc/Hz (100 kHz), supply= 5 V/105 mA, Topr= -40° to +85°C, plastic SM pkg 8L SOIC	13,62
HMC365S8G	Frequency divider (: 4), F= DC-13 GHz, Ph N= -151 dBc/Hz (100 kHz), supply= 5 V/110 mA, Topr= -40° to +85°C, plastic SM pkg 8L SOIC	13,62
HMC394LP4	Frequency divider (: 2 to 32), 5-bit Counter, F= DC- 2,2 GHz, Ph N= -153 dBc/Hz (100 kHz), supply= 5 V/194 mA, Topr= -55° to +85°C, plastic SM pkg QFN 4x4 mm	20,60
HMC438MS8 G	Frequency divider (: 5), F= DC- 7 GHz, Ph N= -153 dBc/Hz (100 kHz), supply= 5 V/80 mA, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	26,37
HMC492LP3	Frequency divider (: 2), F= DC- 18 GHz, Ph N= -150 dBc/Hz (100 kHz), supply= 5 V/78 mA, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	30,10
HMC493LP3	Frequency divider (: 4), F= DC- 18 GHz, Ph N= -150 dBc/Hz (100 kHz), supply= 5 V/96 mA, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	19,83
	(Peregrine Semiconductor Corp.)	
PE3502-21	Frequency divider (: 4), F= 1500-3500 MHz, supply= 3 V/12 mA, Topr= -40° to +85°C, CMOS technology, plastic SM pkg 8L MSOP	4,43
PE3503-21	Frequency divider (: 8), F= 1500-4000 MHz, supply= 3 V/12 mA, Topr= -40° to +85°C, CMOS technology, plastic SM pkg 8L MSOP	4,43
PE3512-01	Frequency divider (: 4), F= DC-1000 MHz, supply= 3 V/10 mA, Topr= -40° to +85°C, CMOS technology, plastic SM pkg 6LSC70	4,43
PE3513-01	Frequency divider (: 8), F= DC-1000 MHz, supply= 3 V/10 mA, Topr= -40° to +85°C, CMOS technology, plastic SM pkg 6LSC70	4,43
	(Zarlink Semiconductor, Inc.)	
SP8902KG/M P1S	Frequency divider (: 2), F= 1-5 GHz, Ph N= -140 dBc/Hz (1 kHz), supply= 5 V/67 mA, Topr= -40° to +85°C, plastic SM pkg 8L SOIC	22,95
	(Mini-Circuits)	
MIQC-60WD	Demodulator, I/Q, F(RF/LO)= 20-60 MHz, F(I/Q)= DC-5 MHz, CL= 7 dB, Amp Bal= 0,15 dB, Ph Bal= ± 1°, supply= 2,7-3,3 V/ 20 mA, Topr= -55° to +100°C, plug-in pkg	111,93
	(RF Micro Devices)	
RF2667	Demodulator, I/Q, F= 50-300 MHz, F(LO)= 2x IF, Gn= -55 to +50 dB, Amp Bal= 0,1 dB, Ph Bal= ± 1°, supply= 2,7-3,3 V/ 20 mA, Topr= -40° to +85°C, plastic SM pkg SSOP-24	7,50
	(Mini-Circuits)	
RPD-1	Detector, phase, F(RF1/RF2)= 1-100 MHz, Fout= DC-50 MHz, IP(RF1/RF2)= +7 dBm, Iso(RF1/RF2)= 40 dB, DC output= 1000 mV, Topr= -55° to +100°C, metal plug-in pkg	25,83
SYPD-1	Detector, phase, F(RF1/ RF2)= 1-100 MHz, Fout= DC-50 MHz, IP(RF1/RF2)= +7 dBm, Iso(RF1/RF2)= 40 dB, DC output= 1000 mV, Topr= -40° to +85°C, plastic SM pkg	20,93
SYPD-2	Detector, phase, F(RF1/RF2)= 10-200 MHz, Fout= DC-50 MHz, IP(RF1/RF2)= +7 dBm, Iso(RF1/RF2)= 40 dB, DC output= 1000 mV, Topr= -40° to +85°C, plastic SM pkg	26,53
ZRPD-1	Detector, phase, F(RF1/ RF2)= 1-100 MHz, Fout= DC-50 MHz, IP(RF1/RF2)= 7 dBm, Iso(RF1/RF2)= 40 dB, DC output= 1000 mV, Topr= -55° to +100°C, connector BNC	81,13
	(Mini-Circuits)	
ADCH-80	Choke, RF wideband, 50 Ohm, BW= 0,05-10 GHz, IL= 0,3 dB, Idc= 100 mA, L= 1 uH /100 mA, Topr= -20° to +85°C, plastic SM pkg	14,75
ADCH-80A	Choke, RF wideband, 50 Ohm, BW= 0,05-10 GHz, IL= 0,3 dB, Idc= 100 mA, L= 1 uH /100 mA, Topr= -40° to +85°C, plastic SM pkg	14,75
	(Mica Microwave)	
SMF950- F0720	Isolator, ferrite, F= 7,1-7,9 GHz, Iso= 20 dB, IL= 0,5 dB, VSWR= 1,25:1, P fwd= 5 W, Prev= 1 W, Topr= -40° to +85°C, drop-in pkg	168,75
	(Coilcraft, Inc.)	
0402CS- 10NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 10 nH, Q= 21, SRF= 3900 MHz, DCR= 0,2 Ohm, Irms= 480 mA, Topr= -40° to +125°C	0,32
0402CS- 10NXGL_	Inductor, chip, ceramic core, 402, 2%, L= 10 nH, Q= 21, SRF= 3900 MHz, DCR= 0,20 Ohm, Irms= 480 mA, Topr= -40° to +125°C	0,32
0402CS- 10NXJL_	Inductor, chip, ceramic core, 402, 5%, L= 10 nH, Q= 21, SRF= 3900 MHz, DCR= 0,20 Ohm, Irms= 480 mA, Topr= -40° to +125°C	0,27
0402CS- 11NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 11 nH, Q= 24, SRF= 3680 MHz, DCR= 0,12 Ohm, Irms= 640 mA, Topr= -40° to +125°C	0,32
0402CS- 12NXJB_	Inductor, chip, ceramic core, 402, 5%, L= 12 nH, Q= 24, SRF= 3600 MHz, DCR= 0,12 Ohm, Irms= 640 mA, Topr= -40° to +125°C	0,27

0402CS-13NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 13 nH, Q= 24, SRF= 3450 MHz, DCR= 0,21 Ohm, Irms= 440 mA, Topr= -40° to +125°C	0,32
0402CS-15NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 15 nH, Q= 24, SRF= 3280 MHz, DCR= 0,17 Ohm, Irms= 560 mA, Topr= -40° to +125°C	0,32
0402CS-15NXGL_	Inductor, chip, ceramic core, 402, 2%, L= 15 nH, Q= 24, SRF= 3280 MHz, DCR= 0,17 Ohm, Irms= 560 mA, Topr= -40° to +125°C	0,32
0402CS-15NXJB_	Inductor, chip, ceramic core, 402, 5%, L= 15 nH, Q= 24, SRF= 3280 MHz, DCR= 0,17 Ohm, Irms= 560 mA, Topr= -40° to +125°C	0,27
0402CS-16NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 16 nH, Q= 24, SRF= 3100 MHz, DCR= 0,22 Ohm, Irms= 560 mA, Topr= -40° to +125°C	0,32
0402CS-18NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 18 nH, Q= 25, SRF= 3100 MHz, DCR= 0,23 Ohm, Irms= 420 mA, Topr= -40° to +125°C	0,32
0402CS-18NXJB_	Inductor, chip, ceramic core, 402, 5%, L= 18 nH, Q= 25, SRF= 3100 MHz, DCR= 0,23 Ohm, Irms= 420 mA, Topr= -40° to +125°C	0,27
0402CS-1N0XJL_	Inductor, chip, ceramic core, 402, 5%, L= 1 nH, Q= 16, SRF= 12,7 GHz, DCR= 0,045 Ohm, Irms= 1360 mA, Topr=-40° to +125°C	0,27
0402CS-1N9XJB_	Inductor, chip, ceramic core, 402, 5%, L= 1,9 nH, Q= 16, SRF= 11,3 GHz, DCR= 0,07 Ohm, Irms= 1040 mA, Topr=-40° to +125°C	0,27
0402CS-22NXGL_	Inductor, chip, ceramic core, 402, 2%, L= 22 nH, Q= 25, SRF= 2800 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,32
0402CS-22NXJL_	Inductor, chip, ceramic core, 402, 5%, L= 22 nH, Q= 25, SRF= 2800 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,27
0402CS-23NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 23 nH, Q= 22, SRF= 2720 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,32
0402CS-24NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 24 nH, Q= 25, SRF= 2700 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,32
0402CS-27NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 27 nH, Q= 24, SRF= 2480 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,32
0402CS-27NXGL_	Inductor, chip, ceramic core, 402, 2%, L= 27 nH, Q= 24, SRF= 2480 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,32
0402CS-27NXJB_	Inductor, chip, ceramic core, 402, 5%, L= 27 nH, Q= 24, SRF= 2480 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,27
0402CS-27NXJL_	Inductor, chip, ceramic core, 402, 5%, L= 27 nH, Q= 24, SRF= 2480 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,27
0402CS-2N0XJL_	Inductor, chip, ceramic core, 402, 5%, L= 2 nH, Q= 16, SRF= 11,1 GHz, DCR= 0,07 Ohm, Irms= 1040 mA, Topr=-40° to +125°C	0,27
0402CS-2N2XJL_	Inductor, chip, ceramic core, 402, 10%, L= 2,2 nH, Q= 19, SRF= 10,8 GHz, DCR= 0,07 Ohm, Irms= 960 mA, Topr=-40° to +125°C	0,27
0402CS-2N7XJB_	Inductor, chip, ceramic core, 402, 5%, L= 2,7 nH, Q= 16, SRF= 10,4 GHz, DCR= 0,12 Ohm, Irms= 640 mA, Topr=-40° to +125°C	0,48
0402CS-30NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 30 nH, Q= 25, SRF= 2350 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,32
0402CS-33NXJL_	Inductor, chip, ceramic core, 402, 5%, L= 33 nH, Q= 24, SRF= 2350 MHz, DCR= 0,30 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,27
0402CS-36NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 36 nH, Q= 24, SRF = 2320 MHz, DCR = 0,44 Ohm, Irms = 320 mA, Topr= -40° to +125°C	0,32
0402CS-36NXJL_	Inductor, chip, ceramic core, 402, 5%, L= 36 nH, Q= 24, SRF = 2320 MHz, DCR = 0,44 Ohm, Irms = 320 mA, Topr= -40° to +125°C	0,27
0402CS-39NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 39 nH, Q= 25, SRF= 2100 MHz, DCR= 0,55 Ohm, Irms= 200 mA, Topr= -40° to +125°C	0,32
0402CS-39NXJB_	Inductor, chip, ceramic core, 402, 5%, L= 39 nH, Q= 25, SRF= 2100 MHz, DCR= 0,55 Ohm, Irms= 200 mA, Topr= -40° to +125°C	0,27
0402CS-3N3XGB_	Inductor, chip, ceramic core, 402, 2%, L= 3,3 nH, Q=19, SRF= 7000 MHz, DCR= 0,066 Ohm, Irms= 840 mA, Topr= -40° to +125°C	0,32
0402CS-3N3XJB_	Inductor, chip, ceramic core, 402, 5%, L= 3,3 nH, Q=19, SRF= 7000 MHz, DCR= 0,066 Ohm, Irms= 840 mA, Topr= -40° to +125°C	0,27
0402CS-3N6XGB_	Inductor, chip, ceramic core, 402, 2%, L= 3,6 nH, Q= 19, SRF= 6800 MHz, DCR= 0,066 Ohm, Irms= 840 mA, Topr=-40° to +125°C	0,32
0402CS-3N6XGL_	Inductor, chip, ceramic core, 402, 2%, L= 3,6 nH, Q= 19, SRF= 6800 MHz, DCR= 0,066 Ohm, Irms= 840 mA, Topr=-40° to +125°C	0,32
0402CS-3N9XGL_	Inductor, chip, ceramic core, 402, 2%, L= 3,9 nH, Q= 19, SRF= 6000 MHz, DCR= 0,066 Ohm, Irms= 840 mA, Topr= -40° to +125°C	0,32
0402CS-3N9XJL_	Inductor, chip, ceramic core, 402, 5%, L= 3,9 nH, Q= 19, SRF= 6000 MHz, DCR= 0,066 Ohm, Irms= 840 mA, Topr= -40° to +125°C	0,27
0402CS-40NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 40 nH, Q= 24, SRF= 2240 MHz, DCR= 0,44 Ohm, Irms= 320 mA, Topr= -40° to +125°C	0,32
0402CS-47NXGL_	Inductor, chip, ceramic core, 402, 2%, L= 47nH, Q= 20, SRF= 2100 MHz, DCR= 0,83 Ohm, Irms= 150 mA, Topr= -40° to +125°C	0,32
0402CS-47NXJL_	Inductor, chip, ceramic core, 402, 5%, L= 47nH, Q= 20, SRF= 2100 MHz, DCR= 0,83 Ohm, Irms= 150 mA, Topr= -40° to +125°C	0,27

0402CS-4N3XGB_	Inductor, chip, ceramic core, 402, 2%, L= 4,3 nH, Q=18, SRF= 6000 MHz, DCR= 0,091 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,32
0402CS-4N7XGL_	Inductor, chip, ceramic core, 402, 2%, L= 4,7 nH, Q= 15, SRF= 4770 MHz, DCR= 0,13 Ohm, Irms= 640 mA, Topr=-40° to +125°C	0,32
0402CS-4N7XJL_	Inductor, chip, ceramic core, 402, 5%, L= 4,7 nH, Q= 15, SRF= 4770 MHz, DCR= 0,13 Ohm, Irms= 640 mA, Topr=-40° to +125°C	0,27
0402CS-56NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 56 nH, Q= 22, SRF= 1760 MHz, DCR= 0,97 Ohm, Irms= 100 mA, Topr= -40° to +125°C	0,32
0402CS-5N6XGL_	Inductor, chip, ceramic core, 402, %, L= 5,6 nH, Q= 20, SRF= 4800 MHz, DCR= 0,083 Ohm, Irms= 760 mA, Topr= -40° to +125°C	0,32
0402CS-68NXGB_	Inductor, chip, ceramic core, 402, 2%, L= 68 nH, Q= 22, SRF= 1620 MHz, DCR= 1,12 Ohm, Irms= 100 mA, Topr= -40° to +125°C	0,32
0402CS-68NXGL_	Inductor, chip, ceramic core, 402, 2%, L= 68 nH, Q= 22, SRF= 1620 MHz, DCR= 1,12 Ohm, Irms= 100 mA, Topr= -40° to +125°C	0,32
0402CS-68NXJB_	Inductor, chip, ceramic core, 402, 5%, L= 68 nH, Q= 22, SRF= 1620 MHz, DCR= 1,12 Ohm, Irms= 100 mA, Topr= -40° to +125°C	0,27
0402CS-6N2XJB_	Inductor, chip, ceramic core, 402, 5%, L= 6,2 nH, Q= 20, SRF= 4800 MHz, DCR= 0,083 Ohm, Irms= 760 mA, Topr= -40° to +125°C	0,27
0402CS-6N8XGL_	Inductor, chip, ceramic core, 402, 2%, L= 6,8 nH, Q= 20, SRF= 4800 MHz, DCR= 0,083 Ohm, Irms= 680 mA, Topr= -40° to +125°C	0,32
0402CS-7N5XGL_	Inductor, chip, ceramic core, 402, 2%, L= 7,5 nH, Q= 22, SRF= 4800 MHz, DCR= 0,10 Ohm, Irms= 680 mA, Topr= -40° to +125°C	0,32
0402CS-8N2XGB_	Inductor, chip, ceramic core, 402, 2%, L= 8,2 nH, Q= 22, SRF= 4400 MHz, DCR= 0,10 Ohm, Irms= 680 mA, Topr= -40° to +125°C	0,32
0402CS-8N2XJB_	Inductor, chip, ceramic core, 402, 5%, L= 8,2 nH, Q= 22, SRF= 4400 MHz, DCR= 0,10 Ohm, Irms= 680 mA, Topr= -40° to +125°C	0,48
0402CS-8N7XGB_	Inductor, chip, ceramic core, 402, 2%, L= 8,7 nH, Q= 18, SRF= 4100 MHz, DCR= 0,20 Ohm, Irms= 680 mA, Topr= -40° to +125°C	0,32
0402CS-9N0XGB_	Inductor, chip, ceramic core, 402, 2%, L= 9,0 nH, Q= 22, SRF= 4160 MHz, DCR= 0,10 Ohm, Irms=680 mA, Topr= -40° to +125°C	0,32
0402CS-9N0XJB_	Inductor, chip, ceramic core, 402, 5%, L= 9,0 nH, Q= 22, SRF= 4160 MHz, DCR= 0,10 Ohm, Irms=680 mA, Topr= -40° to +125°C	0,48
0402CS-9N5XGB_	Inductor, chip, ceramic core, 402, 2%, L= 9,5 nH, Q= 18, SRF= 4160 MHz, DCR= 0,20 Ohm, Irms= 480 mA, Topr= -40° to +125°C	0,32
0603CS-10NXJL_	Inductor, chip, ceramic core, 603, 5%, L= 10 nH, Q= 31, SRF= 4800 MHz, DCR= 0,130 Ohm, Irms=700 mA, Topr= -40° to +125°C	0,22
0603CS-12NXJB_	Inductor, chip, ceramic core, 603, 5%, L= 12 nH, Q= 35, SRF= 4000 MHz, DCR= 0,130 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-15NXJL_	Inductor, chip, ceramic core, 603, 5%, L= 15 nH, Q= 35, SRF= 4000 MHz, DCR= 0,170 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-18NXJL_	Inductor, chip, 603, ceramic core, 5%, L= 18 nH, Q= 35, SRF= 3100 MHz, DCR= 0,17 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-1N6XJL_	Inductor, chip, ceramic core, 603, 5%, L= 1,6 nH, Q= 24, SRF= 12500 MHz, DCR= 0,03 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-1N8XJL_	Inductor, chip, ceramic core, 603, 5%, 603, 2%, L= 1,8 nH, Q= 16, SRF= 12500 MHz, DCR = 0,045 Ohm, Irms = 700 mA, Topr= -40° to +125°C,	0,22
0603CS-22NXGL_	Inductor, chip, ceramic core, 603, 2%, L= 22 nH, Q= 38, SRF= 3000 MHz, DCR= 0,19 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,23
0603CS-23NXJL_	Inductor, chip, ceramic core, 603, 5%, L= 23 nH, Q= 38, SRF= 2850 MHz, DCR= 0,19 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-24NXJB_	Inductor, chip, ceramic core, 603, 5%, L= 24 nH, Q= 36, SRF= 2650 MHz, DCR= 0,135 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-2N2XJL_	Inductor, chip, ceramic core, 603, 5%, L= 2,2 nH, Q= 13, SRF= 12500 MHz, DCR= 0,025 Ohm, Irms= 100 mA, Topr= -40° to +125°C	0,22
0603CS-33NXGL_	Inductor, chip, ceramic core, 603, 2%, L= 33 nH, Q= 40, SRF= 2300 MHz, DCR= 0,22 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0603CS-33NXJL_	Inductor, chip, ceramic core, 603, 5%, L= 33 nH, Q= 40, SRF= 2300 MHz, DCR= 0,22 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,22
0603CS-39NXGB_	Inductor, chip, ceramic core, 603, 2%, L= 39 nH, Q= 40, SRF= 2200 MHz, DCR= 0,25 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0603CS-39NXGL_	Inductor, chip, ceramic core, 603, 2%, L= 39 nH, Q= 40, SRF= 2200 MHz, DCR= 0,25 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0603CS-39NXJB_	Inductor, chip, ceramic core, 603, 5%, L= 39 nH, Q= 40, SRF= 2200 MHz, DCR= 0,25 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,22
0603CS-3N3XGL_	Inductor, chip, ceramic core, 603, 2%, L= 3,3 nH, Q= 35, SRF= 5900 MHz, DCR= 0,045 Ohm, Irms=700 mA, Topr=-40° to +125°C	0,23
0603CS-3N3XJB_	Inductor, chip, ceramic core, 603, 5%, L= 3,3 nH, Q= 35, SRF= 5900 MHz, DCR= 0,045 Ohm, Irms=700 mA, Topr=-40° to +125°C	0,22
0603CS-3N6XGB_	Inductor, chip, ceramic core, 603, 2%, L= 3,6 nH, Q= 22, SRF= 5900 MHz, DCR= 0,063 Ohm, Irms=700 mA, Topr=-40° to +125°C	0,23

0603CS-3N6XJB_	Inductor, chip, ceramic core, 603, 5%, L= 3,6 nH, Q= 22, SRF= 5900 MHz, DCR= 0,063 Ohm, Irms=700 mA, Topr=-40° to +125°C	0,22
0603CS-3N9XGB_	Inductor, chip, ceramic core, 603, 2%, L= 3,9 nH, Q= 22, SRF= 6900 MHz, DCR= 0,080 Ohm, Irms=700 mA, Topr=-40° to +125°C	0,23
0603CS-47NXGL_	Inductor, chip, ceramic core, 603, 2%, L= 47 nH, Q= 38, SRF= 2000 MHz, DCR= 0,280 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0603CS-4N3XJB_	Inductor, chip, ceramic core, 603, 5%, L= 4,3 nH, Q= 22, SRF= 5900 MHz, DCR= 0,063 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-4N7XJL_	Inductor, chip, ceramic core, 603, 5%, L= 4,7 nH, Q= 20, SRF= 5800 MHz, DCR= 0,116 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-56NXGB_	Inductor, chip, ceramic core, 603, 2%, L= 56 nH, Q= 38, SRF= 1900 MHz, DCR= 0,31 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0603CS-56NXGL_	Inductor, chip, ceramic core, 603, 2%, L= 56 nH, Q= 38, SRF= 1900 MHz, DCR= 0,31 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0603CS-5N1XGB_	Inductor, chip, ceramic core, 603, 2%, L= 5,1 nH, Q= 20, SRF= 5700 MHz, DCR= 0,140 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,23
0603CS-5N1XJB_	Inductor, chip, ceramic core, 603, 5%, L= 5,1 nH, Q= 20, SRF= 5700 MHz, DCR= 0,140 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-68NXGL_	Inductor, chip, ceramic core, 603, 2%, L= 68 nH, Q= 37, SRF= 1700 MHz, DCR= 0,34 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0603CS-68NXJB_	Inductor, chip, ceramic core, 603, 5%, L= 68 nH, Q= 37, SRF= 1700 MHz, DCR= 0,34 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,22
0603CS-68NXJL_	Inductor, chip, ceramic core, 603, 5%, L= 68 nH, Q= 37, SRF= 1700 MHz, DCR= 0,34 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,22
0603CS-6N8XGL_	Inductor, chip, ceramic core, 603, 2%, L= 6,8 nH, Q= 27, SRF= 5800 MHz, DCR= 0,11 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,23
0603CS-6N8XJB_	Inductor, chip, ceramic core, 603, 5%, L= 6,8 nH, Q= 27, SRF= 5800 MHz, DCR= 0,11 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-6N8XJL_	Inductor, chip, ceramic core, 603, 5%, L= 6,8 nH, Q= 27, SRF= 5800 MHz, DCR= 0,11 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-82NXGB_	Inductor, chip, ceramic core, 603, 2%, L= 82 nH, Q= 34, SRF= 1700 MHz, DCR= 0,54 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,23
0603CS-8N2XJL_	Inductor, chip, ceramic core, 603, 5%, L= 8,2 nH, Q= 30, SRF= 4200 MHz, DCR= 0,115 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,22
0603CS-8N7XGB_	Inductor, chip, ceramic core, 603, 2%, L= 8,7 nH, Q= 28, SRF= 4600 MHz, DCR= 0,109 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,23
0603CS-9N5XGB_	Inductor, chip, ceramic core, 603, 2%, L= 9,5 nH, Q= 28, SRF= 5400 MHz, DCR= 0,135 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,23
0603CS-R10XJL_	Inductor, chip, ceramic core, 603, 5%, L= 100 nH, Q= 34, SRF= 1400 MHz, DCR= 0,58 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,22
0603CS-R11XJB_	Inductor, chip, ceramic core, 603, 5%, L= 110 nH, Q= 32, SRF= 1350 MHz, DCR= 0,61 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,23
0603CS-R12XGB_	Inductor, chip, ceramic core, 603, 2%, L= 120 nH, Q= 32, SRF= 1300 MHz, DCR= 0,65 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,23
0603CS-R12XGL_	Inductor, chip, ceramic core, 603, 2%, L= 120 nH, Q= 32, SRF= 1300 MHz, DCR= 0,65 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,23
0603CS-R12XJL_	Inductor, chip, ceramic core, 603, 5%, L= 120 nH, Q= 32, SRF= 1300 MHz, DCR= 0,65 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,22
0603CS-R15XGB_	Inductor, chip, ceramic core, 603, 2%, L= 150 nH, Q= 28, SRF= 990 MHz, DCR= 0,92 Ohm, Irms= 280 mA, Topr= -40° to +125°C	0,23
0603CS-R20XGB_	Inductor, chip, ceramic core, 603, 2%, L= 200 nH, Q= 25, SRF= 900 MHz, DCR= 1,98 Ohm, Irms= 200 mA, Topr= -40° to +125°C	0,23
0603CS-R20XJB_	Inductor, chip, ceramic core, 603, 5%, L= 200 nH, Q= 25, SRF= 900 MHz, DCR= 1,98 Ohm, Irms= 200 mA, Topr= -40° to +125°C	0,22
0603CS-R22XGL_	Inductor, chip, ceramic core, 603, 2%, L= 220 nH, Q= 25, SRF= 900 MHz, DCR= 2,10 Ohm, Irms= 200 mA, Topr= -40° to +125°C	0,23
0603CS-R22XJL_	Inductor, chip, ceramic core, 603, 5%, L= 220 nH, Q= 25, SRF= 900 MHz, DCR= 2,10 Ohm, Irms= 200 mA, Topr= -40° to +125°C	0,22
0603CS-R25XGB_	Inductor, chip, ceramic core, 603, 2%, L= 250 nH, Q= 25, SRF= 822 MHz, DCR= 3,55 Ohm, Irms= 120 mA, Topr= -40° to +125°C	0,23
0603CS-R39XGL_	Inductor, chip, ceramic core, 603, 2%, L= 390 nH, Q= 25, SRF= 900 MHz, DCR= 4,35 Ohm, Irms= 100 mA, Topr= -40° to +125°C	0,23
0603CS-R39XJL_	Inductor, chip, ceramic core, 603, 5%, L= 390 nH, Q= 25, SRF= 900 MHz, DCR= 4,35 Ohm, Irms= 100 mA, Topr= -40° to +125°C	0,22
0603HC-10NXGL_	Inductor, chip, ceramic core, 0603, 2%, L= 10 nH, Q= 38, SRF= 3700 MHz, DCR= 0,071 Ohm, Irms= 2 A, Topr= -40° to +125°C	0,23
0603HC-3N6XJL_	Inductor, chip, ceramic core, 0603, 5%, L= 3,6 nH, Q= 24, SRF= 5900 MHz, DCR= 0,048 Ohm, Irms= 2,3 A, Topr= -40° to +125°C	0,22
0603LS-103XJL_	Inductor, chip, ferrite core, 603, 5%, L=10 uH, Q= 12, SRF= 25 MHz, DCR= 4,8 Ohm, Irms= 180 mA, Topr= -40° to +85°C	0,27

0603LS-152XJL_	Inductor, chip, ferrite core, 603, 5%, L= 1500 nH, Q= 15, SRF= 100 MHz, DCR= 0,96 Ohm, Irms= 0,35 A, Topr= -40° to +85°C	0,27
0603LS-182XJL_	Inductor, chip, ferrite core, 603, 5%, L=1800 nH, Q= 15, SRF= 80 MHz, DCR= 1,1 Ohm, Irms= 350 mA, Topr= -40° to +85°C	0,27
0603LS-222XJL_	Inductor, chip, ferrite core, 603, 5%, L= 2,2 uH, Q= 15, SRF= 68 MHz, DCR= 1,2 Ohm, Irms= 320 mA, Topr= -40° to +85°C	0,27
0603LS-472XJL_	Inductor, chip, ferrite core, 603, 5%, L= 4700 nH, Q= 15, SRF= 34 MHz, DCR= 2,1 Ohm, Irms= 0,26 A, Topr= -40° to +85°C	0,27
0603LS-47NXJL_	Inductor, chip, ferrite core, 603, 5%, L= 47 uH, Q= 12, SRF= 1500 MHz, DCR= 0,075 Ohm, Irms= 1,4 A, Topr= -40° to +85°C	0,27
0603LS-561XJL_	Inductor, chip, ferrite core, 603, 5%, L= 560 nH, Q= 15, SRF= 525 MHz, DCR= 0,44 Ohm, Irms= 0,55 A, Topr= -40° to +85°C	0,27
0603LS-681XJL_	Inductor, chip, ferrite core, 603, 5%, L= 680 nH, Q= 15, SRF= 260 MHz, DCR= 0,52 Ohm, Irms= 470 mA, Topr= -40° to +85°C	0,27
0604HQ-1N1XJL_	Inductor, chip, ceramic core, 604, 5%, L= 1,15 nH, Q= 25, SRF= 12,3 GHz, DCR= 0,021 Ohm, Irms= 3,0 A, Topr= -40° to +125°C	0,34
0604HQ-2N6XJL_	Inductor, chip, ceramic core, 604, 5%, L= 2,6 nH, Q= 45, SRF= 9,3 GHz, DCR= 0,026 Ohm, Irms= 2,0 A, Topr= -40° to +125°C	0,34
0805CS-050XJL_	Inductor, chip, ceramic core, 805, 5%, L= 5,6 nH, Q= 65, SRF= 5900 MHz, DCR= 0,08 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,20
0805CS-060XJL_	Inductor, chip, ceramic core, 805, 5%, L= 6,8 nH, Q= 50, SRF= 5600 MHz, DCR= 0,11 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,20
0805CS-070XJB_	Inductor, chip, ceramic core, 805, 5%, L= 7,5 nH, Q= 50, SRF=4500 MHz, DCR= 0,14 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,34
0805CS-070XJL_	Inductor, chip, ceramic core, 805, 5%, L= 7,5 nH, Q= 50, SRF= 4800 MHz, DCR= 0,14 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,20
0805CS-100XGL_	Inductor, chip, 805, 2%, L= 10 nH, Q= 60, SRF= 4300 MHz, DCR= 0,1 Ohm, Irms= 600 mA, Topr= -40° to +125°C,	0,23
0805CS-100XJL_	Inductor, chip, 805, 5%, L= 10 nH, Q= 60, SRF= 4300 MHz, DCR= 0,1 Ohm, Irms= 600 mA, Topr= -40° to +125°C,	0,20
0805CS-101XGL_	Inductor, chip, ceramic core, 805, 2%, L= 100 nH, Q= 65, SRF= 1250 MHz, DCR= 0,46 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,23
0805CS-101XJL_	Inductor, chip, ceramic core, 805, 5%, L= 100 nH, Q= 65, SRF= 1250 MHz, DCR= 0,46 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,20
0805CS-111XJB_	Inductor, chip, ceramic core, 805, 5%, L= 110 nH, Q= 50, SRF= 1000 MHz, DCR= 0,48 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,34
0805CS-121XGL_	Inductor, chip, ceramic core, 805, 2%, L= 120 nH, Q= 50, SRF= 1100 MHz, DCR= 0,51 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,23
0805CS-121XJL_	Inductor, chip, ceramic core, 805, 5%, L= 120 nH, Q= 50, SRF= 1100 MHz, DCR= 0,51 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,20
0805CS-150XJL_	Inductor, chip, ceramic core, 805, 5%, L= 15 nH, Q= 50, SRF= 3200 MHz, DCR= 0,17 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,20
0805CS-151XGL_	Inductor, chip, ceramic core, 805, 2%, L= 150 nH, Q= 50, SRF= 920 MHz, DCR= 0,56 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,23
0805CS-151XJL_	Inductor, chip, ceramic core, 805, 5%, L= 150 nH, Q= 50, SRF= 920 MHz, DCR= 0,56 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,20
0805CS-180XJL_	Inductor, chip, ceramic core, 805, 5%, L= 18 nH, Q= 50, SRF= 3100 MHz, DCR= 0,2 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,20
0805CS-181XGL_	Inductor, chip, ceramic core, 805, 2%, L= 180 nH, Q= 50, SRF= 870 MHz, DCR= 0,64 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,23
0805CS-181XJL_	Inductor, chip, ceramic core, 805, 5%, L= 180 nH, Q= 50, SRF= 920 MHz, DCR= 0,64 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,20
0805CS-220XJL_	Inductor, chip, ceramic core, 805, 5%, L= 22 nH, Q= 55, SRF= 2600 MHz, DCR= 0,22 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805CS-221XGL_	Inductor, chip, ceramic core, 805, 5%, L= 220 nH, Q= 50, SRF= 820 MHz, DCR= 0,7 Ohm, Irms= 400 mA, Topr= -40° to +125°C,	0,23
0805CS-221XJL_	Inductor, chip, ceramic core, 805, 2%, L= 220 nH, Q= 50, SRF= 820 MHz, DCR= 0,7 Ohm, Irms= 400 mA, Topr= -40° to +125°C,	0,20
0805CS-240XGL_	Inductor, chip, ceramic core, 805, 2%, L= 24 nH, Q= 50, SRF= 2400 MHz, DCR= 0,22 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805CS-240XJB_	Inductor, chip, ceramic core, 805, 5%, L= 24 nH, Q= 50, SRF= 2000 MHz, DCR= 0,22 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,34
0805CS-241XGL_	Inductor, chip, ceramic core, 805, 2%, L= 240 nH, Q= 44, SRF= 770 MHz, DCR= 1 Ohm, Irms= 350 mA, Topr= -40° to +125°C	0,23
0805CS-241XJB_	Inductor, chip, ceramic core, 805, 5%, L= 240 nH, Q= 44, SRF= 690 MHz, DCR= 1 Ohm, Irms= 350 mA, Topr= -40° to +125°C	0,34
0805CS-270XJL_	Inductor, chip, ceramic core, 805, 5%, L= 27 nH, Q= 55, SRF= 2580 MHz, DCR= 0,25 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805CS-271XGL_	Inductor, chip, ceramic core, 805, 2%, L= 270 nH, Q= 48, SRF= 730 MHz, DCR=1 Ohm, Irms= 350 mA, Topr= -40° to +125°C	0,23

0805CS-271XJL_	Inductor, chip, ceramic core, 805, 5%, L= 270 nH, Q= 48, SRF= 730 MHz, DCR=1 Ohm, Irms= 350 mA, Topr= -40° to +125°C	0,20
0805CS-330XJB_	Inductor, chip, ceramic core, 805, 5%, L= 33 nH, Q= 60, SRF= 2050 MHz, DCR= 0,27 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805CS-330XJL_	Inductor, chip, ceramic core, 805, 5%, L= 33 nH, Q= 60, SRF= 2150 MHz, DCR= 0,27 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805CS-331XGL_	Inductor, chip, ceramic core, 805, 2%, L= 330 nH, Q= 48, SRF= 650 MHz, DCR= 1,4 Ohm, Irms= 310 mA, Topr= -40° to +125°C	0,23
0805CS-331XJB_	Inductor, chip, ceramic core, 805, 5%, L= 330 nH, Q= 48, SRF= 600 MHz, DCR= 1,4 Ohm, Irms= 310 mA, Topr= -40° to +125°C	0,20
0805CS-331XJL_	Inductor, chip, ceramic core, 805, 5%, L= 330 nH, Q= 48, SRF= 650 MHz, DCR= 1,4 Ohm, Irms= 310 mA, Topr= -40° to +125°C	0,20
0805CS-360XGB_	Inductor, chip, ceramic core, 805, 2%, L= 36 nH, Q= 55, SRF= 1700 MHz, DCR= 0,27 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805CS-360XJB_	Inductor, chip, ceramic core, 805, 5%, L= 36 nH, Q= 55, SRF= 1700 MHz, DCR= 0,27 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,34
0805CS-390XGL_	Inductor, chip, ceramic core, 805, 2%, L= 39 nH, Q= 60, SRF= 2000 MHz, DCR= 0,29 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805CS-390XJB_	Inductor, chip, ceramic core, 805, 5%, L= 39 nH, Q= 60, SRF= 2000 MHz, DCR= 0,29 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,34
0805CS-390XJL_	Inductor, chip, ceramic core, 805, 5%, L= 39 nH, Q= 60, SRF= 2000 MHz, DCR= 0,29 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805CS-391XGB_	Inductor, chip, ceramic core, 805, 2%, L= 390 nH, Q= 48, SRF= 560 MHz, DCR= 1,5 Ohm, Irms= 290 mA, Topr= -40° to +125°C	0,23
0805CS-391XGL_	Inductor, chip, ceramic core, 805, 2%, L= 390 nH, Q= 48, SRF= 600 MHz, DCR= 1,5 Ohm, Irms= 290 mA, Topr= -40° to +125°C	0,23
0805CS-391XJL_	Inductor, chip, ceramic core, 805, 5%, L= 390 nH, Q= 48, SRF= 600 MHz, DCR= 1,5 Ohm, Irms= 290 mA, Topr= -40° to +125°C	0,20
0805CS-3N0XJB_	Inductor, chip, ceramic core, 805, 5%, L= 3 nH, Q= 65, SRF= 7900 MHz, DCR= 0,06 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,29
0805CS-430XGL_	Inductor, chip, ceramic core, 805, 2%, L= 43 nH, Q= 60, SRF= 1650 MHz, DCR= 0,34 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805CS-430XJB_	Inductor, chip, ceramic core, 805, 5%, L= 43 nH, Q= 60, SRF= 1650 MHz, DCR= 0,34 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,34
0805CS-470XGL_	Inductor, chip, ceramic core, 805, 2%, L= 47 nH, Q= 60, SRF= 1700 MHz, DCR= 0,31 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805CS-470XJL_	Inductor, chip, ceramic core, 805, 5%, L= 47 nH, Q= 60, SRF= 1700 MHz, DCR= 0,31 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805CS-471XGL_	Inductor, chip, ceramic core, 805, 2%, L= 470 nH, Q= 33, SRF= 375 MHz, DCR= 1,76 Ohm, Irms= 250 mA, Topr= -40° to +125°C	0,23
0805CS-471XJB_	Inductor, chip, ceramic core, 805, 5%, L= 470 nH, Q= 33, SRF= 375 MHz, DCR= 1,76 Ohm, Irms= 250 mA, Topr= -40° to +125°C	0,20
0805CS-560XGL_	Inductor, chip, ceramic core, 805, 2%, L= 56 nH, Q= 60, SRF= 1600 MHz, DCR= 0,34 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805CS-560XJL_	Inductor, chip, ceramic core, 805, 5%, L= 56 nH, Q= 60, SRF= 1600 MHz, DCR= 0,34 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805CS-561XJL_	Inductor, chip, ceramic core, 805, 5%, L= 560 nH, Q= 23, SRF= 330 MHz, DCR= 1,90 Ohm, Irms= 230 mA, Topr= -40° to +125°C	0,20
0805CS-680XGL_	Inductor, chip, ceramic core, 805, 2%, L= 68 nH, Q= 60, SRF= 1500 MHz, DCR= 0,38 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805CS-680XJL_	Inductor, chip, ceramic core, 805, 5%, L= 68 nH, Q= 60, SRF= 1500 MHz, DCR= 0,38 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805CS-681XJB_	Inductor, chip, ceramic core, 805, 5%, L= 680 nH, Q= 33, SRF= 188 MHz, DCR= 2,2 Ohm, Irms= 190 mA, Topr= -40° to +125°C	0,20
0805CS-681XJL_	Inductor, chip, ceramic core, 805, 5%, L= 680 nH, Q= 33, SRF= 188 MHz, DCR= 2,2 Ohm, Irms= 190 mA, Topr= -40° to +125°C	0,20
0805CS-820XGL_	Inductor, chip, ceramic core, 805, 2%, L= 82 nH, Q= 65, SRF= 1300 MHz, DCR= 0,42 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,23
0805CS-820XJL_	Inductor, chip, ceramic core, 805, 5%, L= 82 nH, Q= 65, SRF= 1330 MHz, DCR= 0,42 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,20
0805CS-821XGL_	Inductor, chip, ceramic core, 805, 2%, L= 820 nH, Q= 23, SRF= 310 MHz, DCR= 2,35 Ohm, Irms= 180 mA, Topr= -40° to +125°C	0,23
0805CS-821XJL_	Inductor, chip, ceramic core, 805, 5%, L= 820 nH, Q= 23, SRF= 310 MHz, DCR= 2,35 Ohm, Irms= 180 mA, Topr= -40° to +125°C	0,20
0805CS-910XGB_	Inductor, chip, ceramic core, 805, 2%, L= 91 nH, Q= 65, SRF= 1200 MHz, DCR= 0,48 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,23
0805CS-910XJB_	Inductor, chip, ceramic core, 805, 5%, L= 91 nH, Q= 65, SRF= 1200 MHz, DCR= 0,48 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,34
0805HQ-16NXGB_	Inductor, chip, ceramic core, 805, 2%, L= 16 nH, Q= 72, SRF= 2,95 GHz, DCR= 0,060 Ohm, Irms= 1,5 A, Topr= -40° to +125°C	0,23

0805HQ-16NXJB_	Inductor, chip, ceramic core, 805, 5%, L= 16 nH, Q= 72, SRF= 2,95 GHz, DCR= 0,060 Ohm, Irms= 1,5 A, Topr= -40° to +125°C	0,20
0805HQ-18NXGL_	Inductor, chip, ceramic core, 805, 2%, L= 18 nH, Q= 75, SRF= 2,55 GHz, DCR= 0,060 Ohm, Irms= 1,4 A, Topr= -40° to +125°C	0,23
0805HQ-18NXJB_	Inductor, chip, ceramic core, 805, 5%, L= 18 nH, Q= 75, SRF= 2,55 GHz, DCR= 0,060 Ohm, Irms= 1,4 A, Topr= -40° to +125°C	0,20
0805HQ-20NXJB_	Inductor, chip, ceramic core, 805, 5%, L= 20 nH, Q= 70, SRF= 2,05 GHz, DCR= 0,055 Ohm, Irms= 1,4 A, Topr= -40° to +125°C	0,20
0805HQ-2N5XJL_	Inductor, chip, ceramic core, 805, 5%, L= 2,5 nH, Q= 80, SRF= 10,3 GHz, DCR= 0,020 Ohm, Irms= 1,6 A, Topr= -40° to +125°C	0,20
0805HQ-30NXGL_	Inductor, chip, ceramic core, 805, 2%, L= 30 nH, Q= 65, SRF= 1,95 GHz, DCR= 0,095 Ohm, Irms= 1,2 A, Topr= -40° to +125°C	0,23
0805HQ-30NXJB_	Inductor, chip, ceramic core, 805, 5%, L= 30 nH, Q= 65, SRF= 1,95 GHz, DCR= 0,095 Ohm, Irms= 1,2 A, Topr= -40° to +125°C	0,20
0805HQ-39NXGL_	Inductor, chip, ceramic core, 805, 2%, L= 39 nH, Q=65, SRF= 1,6 GHz, DCR= 0,11 Ohm, Irms= 1,1 A, Topr= -40° to +125°C	0,23
0805HQ-39NXJB_	Inductor, chip, ceramic core, 805, 5%, L= 39 nH, Q=65, SRF= 1,6 GHz, DCR= 0,11 Ohm, Irms= 1,1 A, Topr= -40° to +125°C	0,20
0805HS-181TGB_	Inductor, chip, ceramic core, 805, 2%, L= 180 nH, Q= 50, SRF= 870 MHz, DCR= 0,64 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,23
0805HS-220TGL_	Inductor, chip, ceramic core, 805, 2%, L= 22 nH, Q= 55, SRF= 2600 MHz, DCR= 0,22 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805HS-330TJL_	Inductor, chip, ceramic core, 805, 5%, L= 33 nH, Q= 60, SRF= 2050 MHz, DCR= 0,27 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805HS-470TGL_	Inductor, chip, ceramic core, 805, 2%, L= 47 nH, Q= 60, SRF= 1650 MHz, DCR= 0,31 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805HS-470TJL_	Inductor, chip, ceramic core, 805, 5%, L= 47 nH, Q= 60, SRF= 1650 MHz, DCR= 0,31 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805HS-560TJL_	Inductor, chip, ceramic core, 805, 5%, L= 56 nH, Q= 60, SRF= 1550 MHz, DCR= 0,34 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
0805HS-680TGL_	Inductor, chip, ceramic core, 805, 2%, L= 68 nH, Q= 60, SRF= 1450 MHz, DCR= 0,38 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805HT-10NTGL_	Inductor, chip, ceramic core, 805, 2%, L= 10 nH, Q= 55, SRF= 3300 MHz, DCR= 0,08 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,23
0805HT-15NTGL_	Inductor, chip, ceramic core, 805, 2%, L= 15 nH, Q= 50, SRF= 2950 MHz, DCR= 0,10 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,23
0805HT-22NTGL_	Inductor, chip, ceramic core, 805, 2%, L= 22 nH, Q= 50, SRF= 2900 MHz, DCR= 0,15 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,23
0805HT-22NTJL_	Inductor, chip, ceramic core, 805, 5%, L= 22 nH, Q= 50, SRF= 2900 MHz, DCR= 0,15 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,20
0805HT-33NTGL_	Inductor, chip, ceramic core, 805, 2%, L= 33 nH, Q= 55, SRF= 2350 MHz, DCR= 0,19 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0805HT-47NTGL_	Inductor, chip, ceramic core, 805, 2%, L= 47 nH, Q= 50, SRF= 2000 MHz, DCR= 0,30 Ohm, Irms= 600 mA, Topr= -40° to +125°C	0,23
0805HT-4N7TJL_	Inductor, chip, ceramic core, 805, 5%, L= 4,7 nH, Q= 50, SRF= 5500 MHz, DCR= 0,06 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,20
0805HT-6N8TJL_	Inductor, chip, ceramic core, 805, 5%, L= 6,8 nH, Q= 50, SRF= 5500 MHz, DCR= 0,08 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,20
0805HT-82NTGL_	Inductor, chip, ceramic core, 805, 2%, L= 82 nH, Q= 50, SRF= 1500 MHz, DCR= 0,44 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
0805HT-8N2TJL_	Inductor, chip, ceramic core, 805, 5%, L= 8,2 nH, Q= 50, SRF= 4800 MHz, DCR= 0,08 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,20
0805HT-R15TGL_	Inductor, chip, ceramic core, 805, 2%, L= 150 nH, Q= 40, SRF= 1050 MHz, DCR= 0,80 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,23
0805LS-102XJB_	Inductor, chip, ferrite core, 0805, 5%, L= 1 uH, Q= 20, SRF= 340 MHz, DCR= 0,69 Ohm, Irms= 0,5 A, Topr= -40° to +85°C	0,27
0805LS-103XJB_	Inductor, chip, ferrite core, 0805, 5%, L= 10 uH, Q= 18, SRF= 21 MHz, DCR= 3,45 Ohm, Irms= 0,2 A, Topr= -40° to +85°C	0,27
0805LS-111XJL_	Inductor, chip, ferrite core, 0805, 5%, L= 0,11 uH, Q= 19, SRF= 1200 MHz, DCR= 0,05 Ohm, Irms= 2 A, Topr= -40° to +85°C	0,27
0805LS-152XJL_	Inductor, chip, ferrite core, 0805, 5%, L= 1,5 uH, Q= 20, SRF= 275 MHz, DCR= 0,83 Ohm, Irms= 0,49 A, Topr= -40° to +85°C	0,27
0906-4GL_	Inductor, air core, micro spring, 2%, turns= 4, L= 3,85 nH, Q= 100, SRF= 7,5 MHz, DCR= 6 mOhm, Irms= 1,6 A, Topr= -40° to +125°C, SM pkg	0,25
0906-5GL_	Inductor, air core, micro spring, 2%, turns= 5, L= 5,4 nH, Q= 100, SRF= 7 MHz, DCR= 8 mOhm, Irms= 1,6 A, Topr= -40° to +125°C, SM pkg	0,25
1008CS-100XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 10 nH, Q= 50, SRF= 4100 MHz, DCR= 0,08 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-101XGL_	Inductor, chip, ceramic core, 1008, 2%, L= 100 nH, Q= 60, SRF= 1000 MHz, DCR= 0,56 Ohm, Irms= 650 mA, Topr= -40° to +125°C	0,23

1008CS-101XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 100 nH, Q= 60, SRF= 1000 MHz, DCR= 0,56 Ohm, Irms= 650 mA, Topr= -40° to +125°C	0,20
1008CS-102XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 1000 nH, Q= 35, SRF= 290 MHz, DCR= 1,75 Ohm, Irms= 370 mA, Topr= -40° to +125°C	0,20
1008CS-120XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 12 nH, Q= 50, SRF= 3300 MHz, DCR= 0,09 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-121XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 120 nH, Q= 60, SRF= 950 MHz, DCR= 0,63 Ohm, Irms= 650 mA, Topr= -40° to +125°C	0,33
1008CS-121XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 120 nH, Q= 60, SRF= 950 MHz, DCR= 0,63 Ohm, Irms= 650 mA, Topr= -40° to +125°C	0,33
1008CS-122XGL_	Inductor, chip, ceramic core, 1008, 2%, L= 1200 nH, Q= 35, SRF= 250 MHz, DCR= 2 Ohm, Irms= 310 mA, Topr= -40° to +125°C	0,23
1008CS-122XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 1200 nH, Q= 35, SRF= 250 MHz, DCR= 2,0 Ohm, Irms= 310 mA, Topr= -40° to +125°C	0,20
1008CS-150XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 15 nH, Q= 50, SRF= 2500 MHz, DCR= 0,1 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-151XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 150 nH, Q= 45, SRF= 850 MHz, DCR= 0,7 Ohm, Irms= 580 mA, Topr= -40° to +125°C	0,20
1008CS-152XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 1500 nH, Q= 28, SRF= 200 MHz, DCR= 2,3 Ohm, Irms= 330 mA, Topr= -40° to +125°C	0,33
1008CS-152XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 1500 nH, Q= 28, SRF= 200 MHz, DCR= 2,3 Ohm, Irms= 330 mA, Topr= -40° to +125°C	0,20
1008CS-180XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 18 nH, Q= 50, SRF= 2500 MHz, DCR= 0,11 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-180XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 18 nH, Q= 50, SRF= 2500 MHz, DCR= 0,11 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-181XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 180 nH, Q= 45, SRF= 750 MHz, DCR= 0,77 Ohm, Irms= 620 mA, Topr= -40° to +125°C	0,33
1008CS-181XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 180 nH, Q= 45, SRF= 750 MHz, DCR= 0,77 Ohm, Irms= 620 mA, Topr= -40° to +125°C	0,20
1008CS-182XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 1800 nH, Q= 28, SRF= 160 MHz, DCR= 2,6 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,20
1008CS-220XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 22 nH, Q= 55, SRF= 2400 MHz, DCR= 0,12 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-220XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 22 nH, Q= 55, SRF= 2400 MHz, DCR= 0,12 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-221XGL_	Inductor, chip, ceramic core, 1008, 2%, L= 220 nH, Q= 45, SRF= 700 MHz, DCR= 0,84 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,23
1008CS-221XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 220 nH, Q= 45, SRF= 700 MHz, DCR= 0,84 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,20
1008CS-222XGL_	Inductor, chip, ceramic core, 1008, 2%, L= 2200 nH, Q= 28, SRF= 160 MHz, DCR= 2,8 Ohm, Irms= 280 mA, Topr= -40° to +125°C	0,23
1008CS-222XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 2200 nH, Q= 28, SRF= 160 MHz, DCR= 2,8 Ohm, Irms= 280 mA, Topr= -40° to +125°C	0,20
1008CS-270XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 27 nH, Q= 55, SRF= 1600 MHz, DCR= 0,13 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-270XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 27 nH, Q= 55, SRF= 1600 MHz, DCR= 0,13 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-271XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 270 nH, Q= 45, SRF= 600 MHz, DCR= 0,91 Ohm, Irms= 500 mA, Topr= -40° to +125°C	0,33
1008CS-272XGL_	Inductor, chip, ceramic core, 1008, 2%, L= 2700 nH, Q= 22, SRF= 140 MHz, DCR= 3,2 Ohm, Irms= 290 mA, Topr= -40° to +125°C	0,23
1008CS-272XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 2700 nH, Q= 22, SRF= 140 MHz, DCR= 3,2 Ohm, Irms= 290 mA, Topr= -40° to +125°C	0,20
1008CS-272XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 2700 nH, Q= 22, SRF= 140 MHz, DCR= 3,2 Ohm, Irms= 290 mA, Topr= -40° to +125°C	0,20
1008CS-330XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 33 nH, Q= 60, SRF= 1600 MHz, DCR= 0,14 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-331XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 330 nH, Q= 45, SRF= 570 MHz, DCR= 1,05 Ohm, Irms= 450 mA, Topr= -40° to +125°C	0,20
1008CS-332XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 3300 nH, Q= 22, SRF= 110 MHz, DCR= 3,4 Ohm, Irms= 290 mA, Topr= -40° to +125°C	0,33
1008CS-332XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 3300 nH, Q= 22, SRF= 110 MHz, DCR= 3,4 Ohm, Irms= 290 mA, Topr= -40° to +125°C	0,33
1008CS-390XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 39 nH, Q= 60, SRF= 1500 MHz, DCR= 0,15 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-391XGL_	Inductor, chip, ceramic core, 1008, 2%, L= 390 nH, Q= 45, SRF= 500 MHz, DCR= 1,12 Ohm, Irms= 470 mA, Topr= -40° to +125°C	0,23
1008CS-391XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 390 nH, Q= 45, SRF= 500 MHz, DCR= 1,12 Ohm, Irms= 470 mA, Topr= -40° to +125°C	0,20

1008CS-392XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 3900 nH, Q= 20, SRF= 100 MHz, DCR= 3,6 Ohm, Irms= 260 mA, Topr= -40° to +125°C	0,23
1008CS-392XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 3900 nH, Q= 20, SRF= 100 MHz, DCR= 3,6 Ohm, Irms= 260 mA, Topr= -40° to +125°C	0,33
1008CS-470XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 47 nH, Q= 65, SRF= 1500 MHz, DCR= 0,16 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,20
1008CS-471XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 470 nH, Q= 45, SRF= 450 MHz, DCR= 1,19 Ohm, Irms= 470 mA, Topr= -40° to +125°C	0,20
1008CS-472XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 4700 nH, Q= 20, SRF= 90 MHz, DCR= 4 Ohm, Irms= 260 mA, Topr= -40° to +125°C	0,20
1008CS-560XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 56 nH, Q= 65, SRF= 1300 MHz, DCR= 0,18 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,20
1008CS-561XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 560 nH, Q= 45, SRF= 415 MHz, DCR= 1,33 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,33
1008CS-561XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 560 nH, Q= 45, SRF= 415 MHz, DCR= 1,33 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,33
1008CS-562XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 5600 nH, Q= 16, SRF= 20 MHz, DCR= 4 Ohm, Irms= 240 mA, Topr= -40° to +125°C	0,33
1008CS-621XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 620 nH, Q= 45, SRF= 375 MHz, DCR= 1,4 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,33
1008CS-621XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 620 nH, Q= 45, SRF= 375 MHz, DCR= 1,4 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,33
1008CS-680XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 68 nH, Q= 65, SRF= 1300 MHz, DCR= 0,2 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,20
1008CS-681XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 680 nH, Q= 45, SRF= 375 MHz, DCR= 1,47 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,33
1008CS-682XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 6800 nH, Q= 18, SRF= 40 MHz, DCR= 4,9 Ohm, Irms= 200 mA, Topr= -40° to +125°C	0,33
1008CS-751XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 750 nH, Q= 45, SRF= 360 MHz, DCR= 1,54 Ohm, Irms= 360 mA, Topr= -40° to +125°C	0,33
1008CS-751XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 750 nH, Q= 45, SRF= 360 MHz, DCR= 1,54 Ohm, Irms= 360 mA, Topr= -40° to +125°C	0,33
1008CS-820XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 82 nH, Q= 60, SRF= 1000 MHz, DCR= 0,22 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,33
1008CS-820XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 82 nH, Q= 60, SRF= 1000 MHz, DCR= 0,22 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,20
1008CS-821XJL_	Inductor, chip, ceramic core, 1008, 5%, L= 820 nH, Q= 45, SRF= 350 MHz, DCR= 1,61 Ohm, Irms= 350 mA, Topr= -40° to +125°C	0,20
1008CS-822XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 8200 nH, Q= 18, SRF= 25 MHz, DCR= 6 Ohm, Irms= 170 mA, Topr= -40° to +125°C	0,33
1008CS-911XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 910 nH, Q= 35, SRF= 320 MHz, DCR= 1,68 Ohm, Irms= 380 mA, Topr= -40° to +125°C	0,33
1008HQ-18NXJB_	Inductor, chip, ceramic core, 1008, 5%, L= 18 nH, Q= 62, SRF= 2,7 GHz, DCR= 0,07 Ohm, Irms= 1,4 A, Topr= -40° to +125°C	0,20
1008HQ-3N0XJB_	Inductor, chip, ceramic core, 1008, 5%, L= 3 nH, Q= 70, SRF= 8,1 GHz, DCR= 0,04 Ohm, Irms= 1,6 A, Topr= -40° to +125°C	0,19
1008HQ-82NXGB_	Inductor, chip, ceramic core, 1008, 2%, L= 82 nH, Q= 80, SRF= 1,06 GHz, DCR= 0,16 Ohm, Irms= 1,1 A, Topr= -40° to +125°C	0,23
1008HQ-R10XGB_	Inductor, chip, ceramic core, 1008, 2%, L= 100 nH, Q= 62, SRF= 0,82 GHz, DCR= 0,16 Ohm, Irms= 1 A, Topr= -40° to +125°C	0,23
1008LS-103XJB_	Inductor, chip, ferrite core, 1008, 5%, L= 10 uH, Q= 31, SRF= 60 MHz, DCR= 2,95 Ohm, Irms= 300 mA, Topr= -40° to +85°C	0,23
1008LS-122XJL_	Inductor, chip, ferrite core, 1008, 5%, L= 1,2 uH, Q= 48, SRF= 210 MHz, DCR= 0,68 Ohm, Irms= 650 mA, Topr= -40° to +85°C	0,23
1008LS-222XJL_	Inductor, chip, ferrite core, 1008, 5%, L= 2,2 uH, Q= 34, SRF= 150 MHz, DCR= 1,10 Ohm, Irms= 520 mA, Topr= -40° to +85°C	0,23
1008LS-472XJL_	Inductor, chip, ferrite core, 1008, 5%, L= 4,7 uH, Q= 31, SRF= 90 MHz, DCR= 1,68 Ohm, Irms= 400 mA, Topr= -40° to +85°C	0,23
1008LS-562XJL_	Inductor, chip, ferrite core, 1008, 5%, L= 5,6 uH, Q= 31, SRF= 80 MHz, DCR= 1,82 Ohm, Irms= 380 mA, Topr= -40° to +85°C	0,23
1008LS-682XJB_	Inductor, chip, ferrite core, 1008, 10%, L= 6,8 uH, Q= 31, SRF= 70 MHz, DCR= 2 Ohm, Irms= 360 mA, Topr= -40° to +85°C	0,23
1008LS-822XJB_	Inductor, chip, ferrite core, 1008, 5%, L= 8,2 uH, Q= 23, SRF= 65 MHz, DCR= 2,65 Ohm, Irms= 330 mA, Topr= -40° to +85°C	0,23
1008PS-472KL_	Inductor, chip, ferrite core, 1008, 10%, L= 4,7 uH, Q= 38, SRF= 160 MHz, DCR= 0,35 Ohm, Isat= 1,0 A, Irms= 1,10 A, Topr= -40° to +85°C	0,36
1206CS-030XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 3,3 nH, Q= 30, SRF= 6200 MHz, DCR= 0,05 Ohm, Irms= 1000 mA, Topr= -40°C to +125°C	0,20
1206CS-060XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 6,8 nH, Q= 30, SRF= 5500 MHz, DCR= 0,07 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,20

1206CS-100XJB_	Inductor, chip, ceramic core, 1206, 5%, L= 10 nH, Q= 40, SRF= 4000 MHz, DCR= 0,08 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,20
1206CS-101XGL_	Inductor, chip, ceramic core, 1206, 2%, L= 100 nH, Q= 55, SRF= 1100 MHz, DCR= 0,26 Ohm, Irms= 850 mA, Topr= -40° to +125°C	0,25
1206CS-101XJB_	Inductor, chip, ceramic core, 1206, 5%, L= 100 nH, Q= 55, SRF= 1100 MHz, DCR= 0,26 Ohm, Irms= 850 mA, Topr= -40° to +125°C	0,20
1206CS-120XJB_	Inductor, chip, ceramic core, 1206, 5%, L= 12 nH, Q= 40, SRF= 3200 MHz, DCR= 0,08 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,20
1206CS-121XJB_	Inductor, chip, ceramic core, 1206, 5%, L= 120 nH, Q= 60, SRF= 1100 MHz, DCR= 0,26 Ohm, Irms= 800 mA, Topr= -40° to +125°C	0,20
1206CS-122XJB_	Inductor, chip, ceramic core, 1206, 5%, L= 1200 nH, Q= 45, SRF= 380 MHz, DCR= 3,20 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,20
1206CS-122XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 1200 nH, Q= 45, SRF= 380 MHz, DCR= 3,20 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,20
1206CS-122XKB_	Inductor, chip, ceramic core, 1206, 10%, L= 1200 nH, Q= 45, SRF= 380 MHz, DCR= 3,2 Ohm, Irms= 300 mA, Topr= -40° to +125°C	0,53
1206CS-151XGB_	Inductor, chip, ceramic core, 1206, 2%, L= 150 nH, Q= 60, SRF= 950 MHz, DCR= 0,31 Ohm, Irms= 750 mA, Topr= -40° to +125°C	0,25
1206CS-181XGL_	Inductor, chip, ceramic core, 1206, 2%, L= 180 nH, Q= 60, SRF= 900 MHz, DCR= 0,43 Ohm, Irms= 700 mA, Topr= -40° to +125°C	0,25
1206CS-221XGL_	Inductor, chip, ceramic core, 1206, 2%, L= 220 nH, Q= 60, SRF= 760 MHz, DCR= 0,5 Ohm, Irms= 670 mA, Topr= -40° to +125°C	0,25
1206CS-221XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 220 nH, Q= 60, SRF= 760 MHz, DCR= 0,5 Ohm, Irms= 670 mA, Topr= -40° to +125°C	0,20
1206CS-271XGB_	Inductor, chip, ceramic core, 1206, 2%, L= 270 nH, Q= 55, SRF= 730 MHz, DCR= 0,56 Ohm, Irms= 630 mA, Topr= -40° to +125°C	0,25
1206CS-331XGB_	Inductor, chip, ceramic core, 1206, 2%, L= 330 nH, Q= 45, SRF= 650 MHz, DCR= 0,62 Ohm, Irms= 590 mA, Topr= -40° to +125°C	0,25
1206CS-391XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 390 nH, Q= 45, SRF= 600 MHz, DCR= 0,75 Ohm, Irms= 530 mA, Topr= -40° to +125°C	0,20
1206CS-470XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 47 nH, Q= 55, SRF= 1500 MHz, DCR= 0,13 Ohm, Irms=1000 mA, Topr= -40° to +125°C	0,20
1206CS-471XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 470 nH, Q= 45, SRF= 550 MHz, DCR= 0,13 Ohm, Irms= 490 mA, Topr= -40° to +125°C,	0,20
1206CS-561XJB_	Inductor, chip, ceramic core, 1206, 5%, L= 560 nH, Q= 45, SRF= 470 MHz, DCR= 1,34 Ohm, Irms= 460 mA, Topr= -40° to +125°C	0,20
1206CS-680XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 68 nH, Q= 55, SRF= 1200 MHz, DCR= 0,26 Ohm, Irms= 900 mA, Topr= -40° to +125°C,	0,20
1206CS-681XGB_	Inductor, chip, ceramic core, 1206, 2%, L= 680 nH, Q= 45, SRF= 450 MHz, DCR= 1,58 Ohm, Irms= 430 mA, Topr= -40° to +125°C	0,25
1206CS-820XJB_	Inductor, chip, ceramic core, 1206, 5%, L= 82 nH, Q= 55, SRF=1200 MHz, DCR= 0,21 Ohm, Irms= 1000 mA, Topr= -40° to +125°C	0,20
1206CS-821XGB_	Inductor, chip, ceramic core, 1206, 2%, L= 820 nH, Q= 45, SRF= 420 MHz, DCR= 1,82 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,25
1206CS-821XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 820 nH, Q= 45, SRF= 420 MHz, DCR= 1,82 Ohm, Irms= 400 mA, Topr= -40° to +125°C	0,20
1206CS-911XJL_	Inductor, chip, ceramic core, 1206, 5%, L= 910 nH, Q= 45, SRF= 410 MHz, DCR= 2,95 Ohm, Irms= 310 mA, Topr= -40° to +125°C	0,20
146-03J08S	Coils, tunable, 7 mm, shielded, turns= 3,5, L= 0,085 uH, Q= 78, DCR= 10,5 mOhm, SRF= 660 MHz, Topr= -40°C to +85°C, plug-in pkg	-
146-07J08SL	Coils, tunable, 7 mm, shielded, turns= 7,5, L= 0,194 uH, Q= 68, DCR= 15,6 mOhm, SRF= 430 MHz, Topr= -40°C to +85°C, plug-in pkg	0,23
164-02A06S	Coils, tunable, 5 mm, shielded, turns= 2,5, L= 22-27 nH, Q= 89/108, SRF= 1300 MHz, Irms= 5,1 A, Topr= -40°C to +85°C, plug-in pkg	0,59
164-04A06S	Coils, tunable, 5 mm, shielded, turns= 4,5, L= 43-56 nH, Q= 66/84, SRF= 940 MHz, Irms= 3,7 A, Topr= -40°C to +85°C, plug-in pkg	0,59
164-05A06SL	Coils, tunable, 5 mm, shielded, turns= 5,5, L= 53-71 nH, Q= 60/79, SRF= 980 MHz, Irms= 3,6 A, Topr= -40°C to +85°C, plug-in pkg	0,59
164-09A06L	Coils, tunable, 5 mm, unshielded, turns= 9,5, L= 131-190 nH, Q=53/62, SRF= 540 MHz, Irms= 2,7 A, Topr= -40°C to +85°C, plug-in pkg	0,58
164-10A06L	Coils, tunable, 5 mm, unshielded, turns= 10,5, L= 148-223 nH, Q= 51/55, SRF= 490 MHz, Irms= 2,5 A, Topr= -40°C to +85°C, plug-in pkg	0,58
164-11A06L	Coils, tunable, 5 mm, unshielded, turns= 11,5, L= 170-246 nH, Q= 51/55, SRF= 360 MHz, Irms= 2,3 A, Topr= -40°C to +85°C, plug-in pkg	0,58
164-11A06SL	Coils, tunable, 5 mm, shielded, turns= 11,5, L= 164 nH, Q= 60, SRF= 400 MHz, Irms= 2,3 A, Topr= -40°C to +85°C, plug-in pkg	0,59
165-03A06S	Coils, tunable, 5 mm, shielded, turns= 3,5, L= 33 nH, Q= 102, SRF= 1230 MHz, Irms= 4,2 A, Topr= -40°C to +85°C, plug-in pkg	0,59
165-04A06S	Coils, tunable, 5 mm, shielded, turns= 4,5, L= 41 nH, Q= 90, SRF= 1150 MHz, Irms= 3,8 A, Topr= -40°C to +85°C, plug-in pkg	0,59

165-07A06L	Coils, tunable, 5 mm, unshielded, turns= 7,5, L= 79-109 nH, Q= 69/92, SRF= 770 MHz, Irms= 3,1 A, Topr= -40°C to +85°C, plug-in pkg	0,58
1812CS-102XJL_	Inductor, chip, ceramic core, 1812, 5%, L= 1 uH, Q= 60, SRF= 310 MHz, DCR= 1,2 Ohm, Irms= 480 mA, Topr= -40 to +125°C	0,27
1812CS-103XJL_	Inductor, chip, ceramic core, 1812, 5%, L= 10 uH, Q= 36, SRF= 70 MHz, DCR= 7,7 Ohm, Irms= 190 mA, Topr= -40 to +125°C	0,27
1812CS-152XJL_	Inductor, chip, ceramic core, 1812, 5%, L= 1,5 uH, Q= 65, SRF= 210 MHz, DCR= 1,6 Ohm, Irms= 430 mA, Topr= -40 to +125°C	0,27
1812CS-183XJB_	Inductor, chip, ceramic core, 1812, 5%, L= 18 uH, Q= 30, SRF= 45 MHz, DCR= 10,5 Ohm, Irms= 160 mA, Topr= -40 to +125°C	0,27
1812CS-222XJL_	Inductor, chip, ceramic core, 1812, 5%, L= 2,2 uH, Q= 63, SRF= 170 MHz, DCR= 2,2 Ohm, Irms= 340 mA, Topr= -40 to +125°C	0,27
1812CS-392XJL_	Inductor, chip, ceramic core, 1812, 2%, L= 3,9 uH, Q= 69, SRF= 115 MHz, DCR= 5,4 Ohm, Irms= 230 mA, Topr= -40 to +125°C	0,27
1812CS-472XJL_	Inductor, chip, ceramic core, 1812, 5%, L= 4,7 uH, Q= 63, SRF= 115 MHz, DCR= 5,4 Ohm, Irms= 230 mA, Topr= -40 to +125°C	0,27
1812CS-822XJB_	Inductor, chip, ceramic core, 1812, 5%, L= 8,2 uH, Q= 47, SRF= 80 MHz, DCR= 7 Ohm, Irms= 200 mA, Topr= -40 to +125°C	0,27
1812LS-104XJB_	Inductor, chip, ferrite core, 1812, 5%, L= 100 uH, Q= 40, SRF= 8,5 MHz, DCR= 8 Ohm, Irms= 150 mA, Topr= -40 to +85°C	0,27
1812LS-123XJL_	Inductor, chip, ferrite core, 1812, 10%, L= 12 uH, Q= 42 MHz, SRF= 85 MHz, DCR= 2 Ohm, Irms= 310 mA, Topr= -40 to +85°C,	0,27
1812LS-153XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 15 uH, Q= 42, SRF= 45 MHz, DCR= 2,5 Ohm, Irms= 290 mA, Topr= -40 to +85°C	0,27
1812LS-154XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 150 uH, Q= 36, SRF= 11,3 MHz, DCR= 13 Ohm, Irms= 125 mA, Topr= -40 to +85°C	0,27
1812LS-183XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 18 uH, Q= 42, SRF= 37 MHz, DCR= 2,8 Ohm, Irms= 270 mA, Topr= -40 to +85°C	0,27
1812LS-223XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 22 uH, Q= 45, SRF= 32 MHz, DCR= 3,2 Ohm, Irms= 260 mA, Topr= -40 to +85°C	0,27
1812LS-224XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 220 uH, Q= 38, SRF= 6,0 MHz, DCR= 16,2 Ohm, Irms= 115 mA, Topr= -40 to +85°C	0,27
1812LS-274XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 270 uH, Q= 38, SRF= 5 MHz, DCR= 20,5 Ohm, Irms= 105 mA, Topr= -40 to +85°C	0,27
1812LS-333XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 33 uH, Q= 45, SRF= 23 MHz, DCR= 4 Ohm, Irms= 230 mA, Topr= -40 to +85°C	0,26
1812LS-334XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 330 uH, Q= 38, SRF= 4,5 MHz, DCR= 22,5 Ohm, Irms= 100 mA, Topr= -40 to +85°C	0,27
1812LS-394XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 390 uH, Q= 38, SRF= 3,5 MHz, DCR= 24,5 Ohm, Irms= 90 mA, Topr= -40 to +85°C	0,27
1812LS-474XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 470 uH, Q= 38, SRF= 3 MHz, DCR= 26,5 Ohm, Irms= 85 mA, Topr= -40 to +85°C	0,27
1812LS-683XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 68 uH, Q= 40, SRF= 16 MHz, DCR= 6 Ohm, Irms= 180 mA, Topr= -40 to +85°C	0,27
1812LS-823XJL_	Inductor, chip, ferrite core, 1812, 5%, L= 82 uH, Q= 40, SRF= 9 MHz, DCR= 7 Ohm, Irms= 170 mA, Topr= -40 to +85°C	0,27
1812SMS-22NGL_	Inductor, air core, 1812, 2%, L= 22 nH, Q= 135, SRF= 3,2 MHz, DCR= 4,2 mOhm, Irms= 3 A, Top= -40 to +125°C, SM pkg	0,29
1812SMS-68NGL_	Inductor, air core, 1812, 2%, L= 68 nH, Q= 120, SRF= 1,5 MHz, DCR= 8,2 mOhm, Irms= 2,5 A, Top= -40 to +125°C, SM pkg	0,29
7M2-101	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 0,1 uH, Q= 27, DCR= 0,124 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-103	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 10 uH, Q= 27, DCR= 2,42 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-104	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 100 uH, Q= 20, DCR= 24,25 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-151	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 0,15 uH, Q= 30, DCR= 0,151 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-152	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, L= 1,5 uH, Q= 27, DCR= 0,466 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-153	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 15 uH, Q= 20, DCR= 3,71 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-181	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 0,18 uH, Q= 30, DCR= 0,151 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-221	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 0,22 uH, Q= 35, DCR= 0,176 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-222	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 2,2 uH, Q= 27, DCR= 0,595 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-223	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 22 uH, Q= 20, DCR= 7,37 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63

7M2-332	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 3,3 uH, Q= 27, DCR= 1,04 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-333	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 33 uH, Q= 20, DCR= 13,34 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-472	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 4,7 uH, Q=270, DCR= 1,38 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-473	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 47 uH, Q= 20, DCR= 16,42 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-682	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 6,8 uH, Q= 27, DCR= 1,49 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M2-683	Inductor, tunable, "Slot Seven", 7mm, shielded with plastic sleeve, Lnom= 68 uH, Q= 20, DCR= 19,76 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,63
7M3-102	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 1,0 uH, Q= 60, DCR= 0,317 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-103	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 10 uH, Q= 35, DCR= 1,38 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-104	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 100 uH, Q= 40, DCR= 16,42 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-122	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 1,2 uH, Q= 45, DCR= 0,333 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-123	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 12 uH, Q= 35, DCR= 1,49 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-152	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 1,5 uH, Q= 45, DCR= 0,368 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-153	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 15 uH, Q= 35, DCR= 1,65 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-154	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 150 uH, Q= 40, DCR= 19,76 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-222	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 2,2 uH, Q= 45, DCR= 0,412 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-223	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 22 uH, Q= 35, DCR= 2,75 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-224	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 220 uH, Q= 40, DCR= 24,25 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-271	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 0,27 uH, Q= 50, DCR= 0,151 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-331	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 0,33 uH, Q= 50, DCR= 0,151 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-332	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 3,3 uH, Q= 40, DCR= 0,544 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-333	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 33 uH, Q= 40, DCR= 3,71 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-392	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 3,9 uH, Q= 40, DCR= 0,595 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-472	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 4,7 uH, Q= 40, DCR= 0,898 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,94
7M3-473	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 47 uH, Q= 40, DCR= 7,37 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-561	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 0,56 uH, Q= 60, DCR= 0,198 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-681	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 0,68 uH, Q= 60, DCR= 0,248 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
7M3-683	Inductor, tunable, "Slot Seven", 7mm, shielded with ferrite sleeve, Lnom= 68 uH, Q= 40, DCR=13,34 Ohm, Topr= -40°C to +85°C, plug-in pkg	0,91
A03TGL_	Inductor, air core, mini spring, 2%, turns= 3, L= 8 nH, Q= 140, SRF= 5 GHz, DCR= 2,6 mOhm, Irms= 4 A, Topr= -40°C to +125°C, SM pkg	0,25
A04TGL_	Inductor, air core, mini spring, 2%, turns= 4, L= 12,5 nH, Q= 137, SRF= 3,3 GHz, DCR= 3,4 mOhm, Irms= 4 A, Topr= -40°C to +125°C, SM pkg	0,25
A05TGL_	Inductor, air core, mini spring, 2%, turns= 5, L= 18,5 nH, Q= 132, SRF= 2,5 GHz, DCR= 3,9 mOhm, Irms= 4 A, Topr= -40°C to +125°C, SM pkg	0,25
B08TGL_	Inductor, air core, mini spring, 2%, turns= 8, L= 28 nH, Q= 105, SRF= 1,8 GHz, DCR= 6 mOhm, Irms= 4 A, Topr= -40°C to +125°C, SM pkg	0,25
B09TJ	Inductor, air core, mini spring, 5%, turns= 9, L= 35,5 nH, Q= 112, SRF= 1,5 GHz, DCR= 6,8 mOhm, Irms= 4 A, Topr= -40°C to +125°C, SM pkg	0,20
B10TJ	Inductor, air core, mini spring, 5%, turns= 10, L= 43 nH, Q= 106, SRF= 1,2 GHz, DCR= 7,9 mOhm, Irms= 4 A, Topr= -40°C to +125°C, SM pkg	0,20
DO1608C-153ML_	Inductor, power, 20%, L= 15 uH, DCR= 0,23 Ohm, SRF= 30 MHz, Isat= 0,9 A, Irms= 1,2 A, Topr= -40°C to +85°C, SM pkg	0,43
DO3316P-154ML_	Inductor, power, ±20%, L= 150 uH, DCR= 0,40 Ohm, SRF= 6 MHz, Isat= 1,0 A, Irms= 1,0 A, Topr= -40°C to +85°C, SM pkg	0,47

DS1608C-103ML_	Inductor, power, 20%, L= 10 uH, Q= 40, DCR= 0,075 Ohm, SRF= 38 MHz, Isat= 0,37 A, Topr= -40 to +85°C, SM pkg	0,63
DS5022P-223ML_	Inductor, power, 20%, L= 22 uH, DCR= 0,059 Ohm, SRF= 18 MHz, Isat= 6,0 A, Irms= 3,1 A, Topr= -40 to +85°C, SM pkg	0,97
M102	Inductors, tunable, kit, "Unicoil", 7/10mm, L =0,0435 uH-1,5 uH, 49 shielded, 49 unshielded (2 each)	102,53
(Mini-Circuits)		
B55-09-101	Capacitor, monolithic, 100 pF ± 5%, size=80x50, dielectric NPO, chip	0,27
B55-09-102	Capacitor, monolithic, 1000 pF ± 5%, size=80x50, dielectric NPO, chip	0,27
B55-09-220	Capacitor, monolithic, 22 pF ± 5%, size=80x50, dielectric NPO, chip	0,23
B55-09-221	Capacitor, monolithic, 220 PF ± 5%, size=80x50, dielectric NPO, chip	0,27
B55-09-470	Capacitor, monolithic, 47 pF ± 5%, size=80x50, dielectric NPO, chip	0,23
B55-09-471	Capacitor, monolithic, 470 pF ± 5%, size=80x50, dielectric NPO, chip	0,23
B55-09-680	Capacitor, monolithic, 68 pF ± 5%, size=80x50, dielectric NPO, chip	0,27
B55-09-681	Capacitor, monolithic, 680 pF ± 5%, size=80x50, dielectric NPO, chip	0,23
B55-10-104	Capacitor, monolithic, 0,100 uF ± 10%, size=120x60, dielectric X7R, chip	0,23
B55-10-223	Capacitor, monolithic, 0,022 uF ± 10%, size=120x60, dielectric X7R, chip	0,23
B55-10-473	Capacitor, monolithic, 0,047 uF ± 10%, size=120x60, dielectric X7R, chip	0,23
B55-10-683	Capacitor, monolithic, 0,068 uF ± 10%, size=120x60, dielectric X7R, chip	0,23
B55-11-103	Capacitor, monolithic, 0,010 uF ± 10%, size=80x50, dielectric X7R, chip	0,27
B55-11-222	Capacitor, monolithic, 2200 pF ± 10%, size=80x50, dielectric X7R, chip	0,23
B55-11-472	Capacitor, monolithic, 4700 pF ± 10%, size=80x50, dielectric X7R, chip	0,23
B55-11-682	Capacitor, monolithic, 6800 pF ± 5%, size=80x50, dielectric NPO, chip	0,23
B55-23-100	Capacitor, monolithic, 10 pF ± 5%, size=80x50, dielectric NPO, chip	0,23
(Voltronics Corp.)		
JR200	Capacitor, trimmer, ceramic, chip, C= 4,5-20,0 pF, +100% -0%, Vr=50 Vdc, Topr = -40°C to +85°C	1,80
JZ200	Capacitor, trimmer, ceramic, chip, C= 4,5-20,0 pF, +100% -0%, Vr= 50 Vdc, Topr = -40°C to +85°C	1,76
)		
K10-176-M47-5.6 пФ 01	2,86	
K10-176-M47-7.5 пФ 01	4,03	
K10-176-M47-9.1 пФ 01	4,03	
K10-69B-МПО-50B-160 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-33 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-330 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-39 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-390 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-43 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-51 пФ ±5%(0805)	"1" 3,58	
K10-69B-МПО-50B-510 пФ ±5%(0805)	"1" 5,86	

K10-69B-МПО-50B-56 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-75 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-82 пФ ±5%(0805)	3,58	
K10-69B-МПО-50B-820 пФ ±5%(0805)	7,72	
K10-69B-H30-50B-1500 пФ ±20%(0805)	2,22	
K10-69B-H30-50B-3300 пФ ±20%(0805)	2,22	
K73-17-630B-0.01 мкФ ±10% 01	0,01, с приемкой ОТК 5,20	
K73-17-630B-0.1 мкФ ±10% 01	0,1 мкФ, с приемкой ОТК 7,41	
(Infineon Technologies)		
SABC161U-LF	Microcontroller, high-performance 18 MIPS 16-Bit USB microcontroller, supply= 3,3 V, Topr= -40° to +85°C, plastic SM pkg 100L TQFP	3,65
(Fairchild Semiconductor)		
NC7SZ08M5	Ultra High Speed Series 2-Input AND Gate, Vcc= 1,8 - 5,5 V, Topr= -40° to +85°C, CMOS technology, plastic SM pkg 5L SOT23	0,95
(Hittite Microwave Corp.)		
HMC267QS1 6G	Modulator, QPSK, F(RF)= 5-6 GHz, IL= 9 dB, Ampl Bal= 2,5 dB, Ph Bal= 8°, Carrier Sup= 30 dBc, Vcntrl= 0/+5 Vdc, Topr= -40° to +85°C, plastic SM pkg 16L QSOP	11,35
(RF Micro Devices)		
RF2485	Modulator, I/Q, direct conversion, F(RF)= 200-600 MHz, BWmod= DC-100 MHz, Carrier Sup= 26 dB, NF= -149 dBm/Hz, supply= 4,5-5,5 V, Topr= -40° to +85°, plastic SM pkg SOIC-14	10,34
RF9958	Modulator/Upconverter, I/Q, dual conversion, F(RF)= 900-1000 MHz, BWmod= 50 MHz, Carrier Sup= 50 dB, Gn= 95 dB, NF= 16 dB, supply= 2,7-3,3 V, Topr= -40° to +85°, plastic SM pkg SSOP-28	14,85
Mini-Circuits)		
BTRM-50	Terminations, coaxial, 50 Ohm, F= DC-2 GHz, RL= 21 dB, IP(RF)= 0,5 W, Topr= -55° to +100°C, connector BNC(m)	12,53
BTRM-75	Terminations, coaxial, 75 Ohm, F= DC-1 GHz, RL= 20 dB (DC-1 GHz), IP(RF)= 0,5 W, Topr= -55° to +100°C, connector BNC(m)	13,93
LOUIS-50	Terminations, coaxial, 50 Ohm, F= DC-2 GHz, RL= 21 dB (DC-2 GHz), IP(RF)= 0,125 W, Topr= -55° to +100°C, connector DIN(m) with retaining sleeve	16,73
ROSE-50	Terminations, coaxial, 50 Ohm, F= DC-6 GHz, RL= 20 dB (DC-6 GHz), IP(RF)= 1 W, Topr= -55° to +100°C, connector SMB-PLUG	13,93
(Mini-Circuits)		
ADC-6-1R	Directional coupler, 50 Ohm, F= 5-200 MHz, coupling= 6,2±0,3 dB, mainline loss= 1,7 dB, Dir= 25 dB, IP= 0,5 W, Topr= -40° to +85°C, plastic SM pkg	11,95
ADC-10-4	Directional coupler, 50 Ohm, F= 5-1000 MHz, coupling= 10,5±0,5 dB, mainline loss= 0,8 dB, Dir= 40 dB, IP= 1 W, Topr= -40° to +85°C, plastic SM pkg	11,95
ADC-15-4	Directional coupler, 50 Ohm, F= 5-1000 MHz, coupling= 15,5±0,5 dB, mainline loss= 0,6 dB, Dir= 23 dB, IP= 1 W, Topr= -40° to +85°C, plastic SM pkg	11,95
ADC-20-4	Directional coupler, 50 Ohm, F= 5-1000 MHz, coupling= 20,0±0,5 dB, mainline loss= 0,5 dB, Dir= 21 dB, IP= 1 W, Topr= -40° to +85°C, plastic SM pkg	11,95
ADC-6-13	Directional coupler, 50 Ohm, F= 200-1300 MHz, coupling= 6,3±0,3 dB, mainline loss= 1,8 dB, Dir= 17 dB, IP= 0,5 W, Topr= -40° to +85°C, plastic SM pkg	11,95
BDCA-10-25	Bi-Directional coupler, 50 Ohm, F= 800-2500 MHz, coupling= 10,1±0,5 dB, mainline loss= 1 dB, Dir= 25 dB, IP= 50 W, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	10,95
BDCA-15-25+	Bi-Directional coupler, 50 Ohm, F= 800-2500 MHz, coupling= 15±1,7 dB, mainline loss= 0,5 dB, Dir= 27 dB, IP= 23 W, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	10,95

BDCA1-6-22	Bi-Directional coupler, 50 Ohm, F= 950-2200 MHz, coupling= 6,0±0,5 dB, mainline loss= 1,7 dB, Dir= 28 dB, IP= 44 W, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	8,95
BDCA-22-16	Bi-Directional coupler, 50 Ohm, F= 800-1600 MHz, coupling= 22,1±2 dB, mainline loss= 0,7 dB, Dir= 23 dB, IP= 35 W, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	8,33
D18P	Directional coupler, 50 Ohm, F= 1710-1990 MHz, coupling= 18,0±1,8 dB, mainline loss= 0,3 dB, Dir= 15 dB, IP= 1 W, Topr= -40° to +85°C, plastic SM pkg	9,95
D19G	Directional coupler, 50 Ohm, F= 1420-1660 MHz, coupling= 18,2±1,2 dB, mainline loss= 0,3 dB, Dir= 15 dB, IP= 1 W, Topr= -40° to +85°C, plastic SM pkg	9,95
DBTC-13-4+	Directional coupler, 50 Ohm, F= 5-1000 MHz, coupling= 13,0±0,5 dB, mainline loss= 0,7 dB, Dir= 18 dB, IP= 1 W, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	9,95
DBTC-17-5	Directional coupler, 50 Ohm, F= 50-2000 MHz, coupling= 17,7±0,9 dB, mainline loss= 1 dB, Dir= 20 dB, IP= 2 W, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	9,95
DBTC-17-5+	Directional coupler, 50 Ohm, F= 50-2000 MHz, coupling= 17,7±0,9 dB, mainline loss= 1 dB, Dir= 20 dB, IP= 2 W, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	9,95
DBTC-20-4	Directional coupler, 50 Ohm, F= 20-1000 MHz, coupling= 20,4±0,6 dB, mainline loss= 0,4 dB, Dir= 21 dB, IP= 1 W, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	9,95
TCD-13-4	Directional coupler, 50 Ohm, F= 5-1000 MHz, coupling= 13,0±0,5 dB, mainline loss= 0,7 dB, Dir= 18 dB, IP= 1 W, Topr= -40° to +85°C, open style, plastic base, SM pkg	9,45
ZEDC-15-2B-S	Directional coupler, 50 Ohm, F= 1-1000 MHz, coupling= 15,0±0,5 dB, mainline loss= 0,8 dB, Dir= 30 dB, IP= 3 W, Topr= -55° to +100°C, bracket, connector SMA(f)	90,93
ZFDC-20-4-S	Directional coupler, 50 Ohm, F= 1-100 MHz, coupling= 19,5±0,5 dB, mainline loss= 0,4 dB, Dir= 27 dB, IP= 2 W, Topr= -55° to +100°C, connector SMA(f)	97,93
(CHIPCON AS)		
CC1070	Transmitter, UHF, F(RF1)= 402-470 MHz, Fstep= 300 Hz and F(RF2)= 804-940 MHz, Fstep= 600 Hz, P(TX)= 20 to 10 dBm, ASK/ FSK/ GFSK modulation, data rate< 153,6 kbaud, supply= 2,1-3,6 V, Topr= -40°C to +105°C, CMOS technology, SM pkg QFN20	4,28
(RF Micro Devices)		
RF2516	Transmitter, VHF/UHF, F= 100-500 MHz, P(TX)= 10 dBm, supply= 2,25-3,6 V, Topr= -40° to +85°C, plastic SM pkg SSOP-16	6,51
RF2909	Transmitter, spread-spectrum, F= 100-1000 MHz, P(TX)= 17 dBm, supply= 2,7-5,0 V, Topr= -40° to +85°C, plastic SM pkg SSOP-24	7,65
(RF Monolithics, Inc.)		
AT1001	Transmitter, F= 433,92 MHz, P(TX)= 0 dBm, quartz SAW frequency stabilization, OOK/ASK modulation, data timing 100 us, supply= 2,7-3,3 V, Topr= -40° to +85°C, module	7,95
(Hittite Microwave Corp.)		
HMC183QS24	Switch, SP8T, F= DC-2 GHz, IL= 1,3 dB, Iso= 30 dB, IP1dB= 20 dBm, control= 0/ -5 V, Topr= -40° to +85°C, plastic SM pkg 24L QSOP	9,38
HMC199MS8	Switch, Bypass DPDT, F= DC-2,5 GHz, IL= 0,3 dB, Iso= 25 dB, IP1dB= 23 dBm, control= 0/ +5 V, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	2,64
HMC221	Switch, SPDT, reflective, F= DC-3 GHz, IL= 0,4 dB, Iso= 28 dB, IP1dB= 30 dBm, control= 0/+3 V, Topr= -40° to +85°C, plastic SM pkg SOT26	1,68
HMC224MS8	Switch, SPDT T/R, F= 5-6 GHz, IL= 1,2 dB, Iso= 31 dB, IP1dB= 33 dBm, control= TTL/CMOS, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	3,43
HMC245QS16	Switch, SP3T, F= DC-3,5 GHz, IL= 0,5 dB, Iso= 44 dB, IP1dB= 26 dBm, control= TTL/CMOS, Topr= -40° to +85°C, plastic SM pkg 16L QSOP	4,88
HMC252QS24	Switch, SP6T, F= DC-3 GHz, IL= 0,8 dB, Iso= 41 dB, IP1dB= 24 dBm, control= TTL/CMOS, Topr= -40° to +85°C, plastic SM pkg 24L QSOP	9,38
HMC253QS24	Switch, SP8T, F= DC-2,5 GHz, IL= 1,1 dB, Iso= 36 dB, IP1dB= 23 dBm, control= TTL/CMOS, Topr= -40° to +85°C, plastic SM pkg 24L QSOP	9,91
HMC284MS8G	Switch, SPDT, Hi Isolation, F= DC-3,5 GHz, IL= 0,5 dB, Iso= 45 dB, IP1dB= 25 dBm, control= 0/ +5 V, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	1,77
HMC321LP4	Switch, SP8T, F= DC-8 GHz, IL= 2,3 dB, Iso= 40 dB, IP1dB= 23 dBm, control= 0/+5 V, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	19,57
HMC322LP4	Switch, SP8T, F= DC-8 GHz, IL= 2,5 dB, Iso= 25 dB, IP1dB= 23 dBm, control= 0/ -5 V, Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	19,57
HMC344LP3	Switch, SP4T, F= DC-8 GHz, IL= 1,8 dB, Iso= 40 dB, IP1dB= 21 dBm, control= 0/ -5 V, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	17,71
HMC345LP3	Switch, SP4T, F= DC-8 GHz, IL= 2 dB, Iso= 32 dB, IP1dB= 21 dBm, control= 0/ +5 V, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	17,71
HMC348LP3	Switch, SPDT, CAVT, F= DC-2,5 GHz, IL= 0,6 dB, Iso= 58 dB, IP1dB= 28 dBm, control= 0/ +5 V, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	2,85
HMC349LP4C	Switch, SPDT, Hi Isolation, F= DC-4 GHz, IL= 0,9 dB, Iso= 65 dB, IP1dB= 31 dBm, control= 0/ -5 V, Topr= -40° to +85°C, plastic SM pkg 16L QFN	5,20
HMC393MS8G	Switch, DPDT, diversity, F= 5-6 GHz, IL= 1,2 dB, Iso= 20 dB, IP1dB= 30 dBm, control= 0/ +5 V, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	4,97
HMC427LP3	Switch, Transfer, F= DC-8 GHz, IL= 1,3 dB, Iso= 42 dB, IP1dB= 26 dBm, control= 0/ +5 V, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	36,02
(Integrated Device Technology, Inc.)		
QS3VH125S1	Switch, quad, active, F= 150 MHz, supply= 3,3 V, Topr= -40° to +85°C, plastic SM pkg 8L SOIC	1,70
(M/A-COM)		

SW-393	Switch, SPDT, 50 Ohm, F= 500-2000 MHz, IL= 1,6 dB, Iso= 42 dB, IP1dB= +26 dBm, control= 0/ +5 V, Topr= -40° to +85°C, GaAs MMIC, plastic SM pkg 8L SOIC	5,14
	(Mini-Circuits)	
M3SWA-2-50DR	Switch, SPDT, TTL driver, absorptive, F= DC-4500 MHz, IL= 0,7 dB, Iso= 65 dB, IP1dB= +25 dBm, control= 0/ +5 V, Topr= -55° to +100°C, plastic SM pkg 3x3 mm	14,95
MSW-2-20	Switch, SPDT, absorptive, F= DC-2000 MHz, IL= 0,3-0,75 dB, Iso= 55-24 dB, IP1dB= +25 dBm, control= -8 V to -5 V/ 0 V, Topr= -40° to +85°C, GaAs MMIC, plastic SM pkg	7,95
MSWT-4-20	Switch, Transfer, F= DC-2000 MHz, IL= 0,9-1,45 dB, Iso= 60-28 dB, IP1dB= +29 dBm, control= -8 V to -5 V/ 0 V, Topr= -40° to +85°C, GaAs MMIC, plastic SM pkg	9,95
RSW-2-25P	Switch, SPDT, reflective, F= DC-2500 MHz, IL= 0,5-1,2 dB, Iso= 75-42 dB, IP1dB= 29 dBm, control= 0/ +7 V, Topr= -40° to +85°C, GaAs MMIC, plastic SM pkg	15,95
ZFSW-2-46	Switch, SPDT, reflective, 50 Ohm, F= DC-4600 MHz, IL= 1,0 dB, Iso= 50 dB, IP1dB= +27 dBm, control= -8 V to -5 V/ 0 V, Topr= -55° to +100°C, connector SMA(f)	111,93
	(Peregrine Semiconductor Corp.)	
PE4230-21	Switch, SPDT reflective, 50 Ohm, F= DC-3000 MHz, IIP3= 50 dBm, IP1dB= 32 dBm, IL= 0,35 dB, Iso= 39 dB, supply= 2,7-3,3 V, plastic SM pkg, 8L MSOP	2,00
PE4231-01	Switch, SPDT reflective, 75 Ohm, F= DC-1300 MHz, IIP3= 80 dBm, IP1dB= 32 dBm, IL= 0,8 dB, Iso= 42 dB, supply= 2,7-3,3 V, plastic SM pkg, 8L MSOP	2,00
PE4235-01	Switch, SPDT reflective, 50 Ohm, F= DC-4000 MHz, IIP3= 36 dBm, IP1dB= 15 dBm, IL= 0,4 dB, Iso= 40 dB, supply= 2,7-3,3 V, plastic SM pkg, 6L DFN 3x3 mm	1,67
PE4239-01	Switch, SPDT reflective, 50 Ohm, F= DC-3000 MHz, IIP3= 45 dBm, IP1dB= 27 dBm, IL= 0,7 dB, Iso= 32 dB, supply= 2,7-3,3 V, plastic SM pkg, 6L SC70	0,94
PE4240-01	Switch, SPST absorptive, 75 Ohm, F= DC-1300 MHz, IIP3= 80 dBm, IP1dB= 30 dBm, IL= 0,75 dB, Iso= 45 dB, supply= 2,7-3,3 V, plastic SM pkg, 6L DFN 3x3 mm	3,10
PE4242-01	Switch, SPDT reflective, 50 Ohm, F= DC-3000 MHz, IIP3= 45 dBm, IP1dB= 27 dBm, IL= 0,7 dB, Iso= 32 dB, supply= 2,7-3,3 V, plastic SM pkg, 6L SC70	0,94
PE4246-01	Switch, SPST absorptive, 50 Ohm, F= DC-5000 MHz, IIP3= 50 dBm, IP1dB= 33 dBm, IL= 0,8 dB, Iso= 55 dB, supply= 2,7-3,3 V, plastic SM pkg, 6L DFN 3x3 mm	4,53
PE4257-01	Switch, SPDT absorptive, 50 Ohm, F= DC-3000 MHz, IIP3= 55 dBm, IP1dB= 31 dBm, IL= 0,75 dB, Iso= 66 dB, supply= 2,7-3,3 V, plastic SM pkg, 20L QFN 4x4 mm	1,62
PE4259-01	Switch, SPDT reflective, 50 Ohm, F= DC-3000 MHz, IIP3= 60 dBm, IP1dB= 34 dBm, IL= 0,3 dB, Iso= 32 dB, supply= 2,7-3,3 V, plastic SM pkg, 6L SC70	1,17
	(RF Micro Devices)	
RF2436	Switch, T/R, F= 100-2500 MHz, IL= 0,5 dB, Iso= 24 dB, IP1dB= 27 dBm, control= 0/ +0,7 V, Topr= -40° to +85°C, plastic SM pkg SOT23-5	2,82
	(Sirenza Microdevices, Inc.)	
SSW-408	Switch, SPDT, absorptive, 50 Ohm, F= DC-4000 MHz, IL= 0,9 dB, Iso= 22 dB, OP1dB= +36 dBm, control= -3 V/ +3 V or -10 V/ +10 V, Topr= -45° to +85°C, GaAs MMIC, plastic SM pkg	12,50
SSW-424	Switch, SPDT, absorptive, 50 Ohm, F= DC-6000 MHz, IL= 0,7 dB, Iso= 22 dB, OP1dB= +36 dBm, control= -3 V/ +3 V or -10 V/ +10 V, Topr= -45° to +85°C, GaAs MMIC, plastic SM pkg	10,50
SSW-508	Switch, SPST, absorptive, 50 Ohm, F= DC-4000 MHz, IL= 0,9 dB, Iso= 30 dB, OP1dB= +25 dBm, control= 0/ -5 V, Topr= -45° to +85°C, GaAs MMIC, plastic SM pkg	2,50
SSW-524	Switch, SPST, absorptive, 50 Ohm, F= DC-8000 MHz, IL= 0,8 dB, Iso= 40 dB, OP1dB= +25 dBm, control= 0/ -5 V, Topr= -45° to +85°C, GaAs MMIC, plastic SM pkg	11,45
	(CurrentRF)	
RFDAC2101	Frequency converter (up), F(RO)= 0-5,5 GHz, F(LO)= 0-4 GHz, F(IF)= 0-1,5 GHz, Gn Conv= -20 dB, OP1dB= +4 dB, supply= +3,3 V/155 mA, P(LO)= -10 to 0 dBm, Topr= -40° to +85°C, CMOS technology, module	210,00
	(Qualcomm, Inc.)	
U1000	Frequency converter (up), wideband, P(LO)= -6 to 0 dBm, F(RF)= 824-1910 MHz, F(LO)= 954-1780 MHz, F(IF)= 50-300 MHz, supply= 2,7-3,78 V, Topr= -30° to +80°C, plastic SM pkg 8L SOIC	3,50
U1100	Frequency converter (up), dualband, P(LO)= -6 to 0 dBm, F(RF1)= 1850-1910 MHz, F(RF2)= 824-849 MHz, F(LO)= 954-1780 MHz, F(IF)= 50-300 MHz, supply= 2,7-3,78 V, Topr= -30° to +80°C, plastic SM pkg 8L SOIC	3,70
	(Analog Devices)	
AD9763AST	Converter D/A, dual, 10-bit, Fclk= 125 MHz (125 MSPS), supply= +3 V/ +5 V, Topr= -40° to +85°C, CMOS technology, SM pkg 48L LQFP	17,90
	(Intersil Corp.)	
HI5731BIB	Converter D/A, 12-bit, Fclk= 100 MHz (100 MSPS), supply= +5 V/ -5,2 V, Topr= -40° to +85°C, CMOS technology, plastic SM pkg 28L SOIC	16,70
	(Agilent Technologies)	
ADCM-1650-3011	Camera , module	36,28
	(RF Micro Devices)	
RF2917	Receiver, FM/FSK, F= 300-1000 MHz, Sens(RX)= -101 dBm, supply= 2,7-5 V, Topr= -40° to +85°C, plastic SM pkg LQFP-32	17,15
	(Россия)	

Р1-8-0.062-100 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-121 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-154 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-200 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-249 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-301 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-51.1 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-61.9 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-75 Ом ±5% (0603) ОЖО.467.164 ТУ	Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.062-82.5 Ом ±5% (0603) ОЖО.467.164 ТУ	0603, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	4,42
Р1-8-0.125-10 Ом ±5% (0805) ОЖО.467.164 ТУ	0805, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	3,68
Р1-8-0.125-20.5 Ом ±5% (0805) ОЖО.467.164 ТУ	0805, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	3,68
Р1-8-0.125-33.2 Ом ±5% (0805) ОЖО.467.164 ТУ	0805, ряд Е48, ТКС= ±150 ppm/С°, Т= -60° до +100°С,	3,68
С2-29В-0.125-10 Ом ±1% 01	Т= -60° до +155°С, 2,07	
С2-29В-0.125-61,9 Ом ±1% 01	Е192, ТКС= ±(5,15,55) ppm/С°, Т= -60° до +155°С, 2,07	

C	C2-29B-0.125 82.5 Ом ±1% 01	E192, ТКС= ±(5,15,55) ppm/С°, Т= -60° до +155° С	2,07
	2-33Н-0.125 16 Ом ±5% 01	, E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	1,11
	C2-33Н-0.125 160 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,66
	C2-33Н-0.125 2.0 кОм ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 2.2 кОм ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 270 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 3.9 кОм ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 300 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,66
	C2-33Н-0.125 360 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 510 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 56 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 560 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 62 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,66
	C2-33Н-0.125 68 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	1,11
	C2-33Н-0.125 680 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,30
	C2-33Н-0.125 91 Ом ±5% 01	ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,66
	C2-33Н-0.25- 180 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,66
	C2-33Н-0.25- 75 Ом ±5% 01	, ряд E24, ТКС= ±(50,100,250,500,1000) ppm/С°, Т= -60° до +155°С,	0,66
	(Analog Devices)		
	AD9851BRS	Frequency synthesizer, clock drive DDS, 10-bit DAC, Fclk= 180 MHz, supply= 2,75-5,25 V, Topr= -40° to +85°С, parallel/serial interface, CMOS technology, SM pkg 28L SSOP	28,08
	AD9854ASQ	Frequency synthesizer, quadrature DDS, 12-bit DAC, Fclk= 300 MHz, supply= 3,3 V, Topr= -40° to +85°С, parallel/serial interface, CMOS technology, SM pkg 80L LQFP	49,28
	AD9954YSV	Frequency synthesizer, DDS, 14-bit DAC, Fclk= 400 MHz, PhN< -125 dBc/Hz (1 kHz), supply= 1,8 V, Topr= -40° to +85°С, parallel/serial interface, CMOS technology, SM pkg 48L TQFP	35,71
	(Motorola)		
	MC145152D W2	Frequency synthesizer, integer -N PLL, F= 20 MHz, dual prescaler 10-bit, supply= 3-9 V, Topr= -40° to +85°С, parallel programmable interface, CMOS technology, plastic SM pkg 28L SOG	4,96
	MC145158D W2	Frequency synthesizer, integer -N PLL, F= 20 MHz, dual prescaler 14-bit, supply= 3-9 V, Topr= -40° to +85°С, serial programmable interface, CMOS technology, plastic SM pkg 16L SOG	3,80
	MC145170D2	Frequency synthesizer, integer -N PLL, F= 185 MHz, prescaler 16-bit, supply= 2,7-5,5 V, Topr= -40° to +85°С, direct serial programmable interface, CMOS technology, plastic SM pkg 16L SOG	5,19
	MC145220DT	Frequency synthesizer, integer -N PLL, F= 1,1 GHz, dual prescaler 32/33 or 64/65 supply= 2,7-5,5 V, Topr= -40° to +85°С, direct serial programmable interface, CMOS technology, plastic SM pkg 20L TSSOP	5,15

	(National Semiconductor)	
LMX1600TM	Frequency synthesizer, dual, integer -N PLL, F= 2000 MHz/ 500 MHz, prescaler 32/33 or 8/9, serial interface, supply= 2,7-3,6 V, Topr= -40° to +85°C, BiCMOS technology, plastic SM pkg 16L TSSOP	1,76
LMX2330LTM	Frequency synthesizer, dual, integer -N PLL, F= 2500 MHz/510 MHz, prescaler 32/33 or 64/65, serial interface, supply= 2,7-5,5 V, Topr= -40° to +85°C, BiCMOS technology, plastic SM pkg 20L TSSOP	3,22
LMX2347TM	Frequency synthesizer, integer -N PLL, F= 2500 MHz, prescaler 32/33, serial interface, supply= 2,7-5,5 V, Topr= -40° to +85°C, BiCMOS technology, plastic SM pkg 16L TSSOP	3,35
LMX2350TM	Frequency synthesizer, dual, fractional -N/integer -N PLL, F= 2500 MHz/550 MHz, prescaler 16/17 or 32/33, serial interface, supply= 2,7-5,5 V, Topr= -40° to +85°C, BiCMOS technology, plastic SM pkg 24L TSSOP	5,46
LMX2353TM	Frequency synthesizer, fractional -N PLL, F= 2500 MHz, prescaler 16/17 or 32/33, serial interface, supply= 2,7-5,5 V, Topr= -40° to +85°C, BiCMOS technology, plastic SM pkg 16L TSSOP	4,38
LMX2354TM	Frequency synthesizer, dual, fractional -N/integer -N PLL, F= 2500 MHz/550 MHz, serial interface, supply= 2,7-5,5 V, Topr= -40° to +85°C, BiCMOS technology, plastic SM pkg 24L TSSOP	4,24
	(Peregrine Semiconductor Corp.)	
PE3236-21	Frequency synthesizer, integer -N PLL, F(RF)= 2200 MHz, Fref= 100 MHz, Fcomp= 20 MHz, prescaler 10/11, supply= 3 V/30 mA, serial/parallel programmable interface, CMOS technology, plastic SM pkg 44L PLCC	27,80
PE3240-11	Frequency synthesizer, integer -N PLL, F(RF)= 2200 MHz, Fref= 100 MHz, Fcomp= 20 MHz, prescaler 10/11, supply= 3 V/30 mA, serial programmable interface, CMOS technology, plastic SM pkg 20L TSSOP	5,71
PE3291-11	Frequency synthesizer, dual, fractional -N PLL, F(RF)= 1200 MHz, F(IF)= 550 MHz, Fref= 20 MHz, prescaler 32/33 and 16/17, supply= 3V/3,1 mA, serial programmable interface, CMOS technology, plastic SM pkg 20L TSSOP	4,43
PE3293-11	Frequency synthesizer, dual, fractional -N PLL, F(RF)= 1800 MHz, F(IF)= 550 MHz, Fref= 20 MHz, prescaler 32/33 and 16/17, supply= 3V/4 mA, serial programmable interface, CMOS technology, plastic SM pkg 20L TSSOP	4,13
PE3293-14	Frequency synthesizer, dual, fractional -N PLL, F(RF)= 1800 MHz, F(IF)= 550 MHz, Fref= 20 MHz, prescaler 32/33 and 16/17, supply= 3V/4 mA, serial programmable interface, CMOS technology, plastic SM pkg 24L BCC	4,13
PE3336-23	Frequency synthesizer, integer -N PLL, F(RF)= 3000 MHz, Fref= 100 MHz, Fcomp= 20 MHz, prescaler 10/11, supply= 3 V/30 mA, parallel/serial programmable interface, CMOS technology, plastic SM pkg 48L MLPQ	30,89
PE3341-01	Frequency synthesizer, integer -N PLL with Field-programmable EEPROM, F(RF)= 2700 MHz, Fref= 100 MHz, Fcomp= 20 MHz, prescaler 10/11, supply= 3 V/30 mA, serial programmable interface, CMOS technology, plastic SM pkg 24L TSSOP	9,14
	(Qualcomm, Inc.)	
Q2240I-1N	Frequency synthesizer, DDS, Fclk= 50 MHz, supply= 5 V, Topr= -40° to +85°C, 24-bit direct parallel interface, CMOS technology, SM pkg 44L PLCC	11,30
Q2240I-3S1	Frequency synthesizer, DDS, Fclk= 100 MHz, supply= 3,3 V/5 V, Topr= -40° to +85°C, 32-bit direct parallel interface, CMOS technology, SM pkg 64L PQFP	7,50
	(Silicon Laboratories, Inc.)	
Si4123-BT	Frequency synthesizer, integer -N PLL, dual, F(RF)= 900-1800 MHz, F(IF)= 62,5-1000 MHz, serial interface, supply= 2,7-3,6 V, Topr= -40° to +85°C, plastic SM pkg 24L TSSOP	16,97
	(Skyworks Solutions, Inc.)	
CX74038-12	Frequency synthesizer, dual, fractional -N/integer -N PLL, F(RF)= 100-2600 MHz, F(IF)= 800 MHz, Step size< 10 Hz, Ph N= -85 dBc/Hz (10 kHz), supply= 2,6-3,6 V, Topr= -40° to +85°C, serial interface, BiCMOS technology, SM pkg 20L TSSOP	6,46
CX74038-71	Frequency synthesizer, dual, fractional -N/integer -N, PLL, F(RF)= 100-2600 MHz, F(IF)= 800 MHz, Step size< 10 Hz, Ph N= -85 dBc/Hz (10 kHz), supply= 2,6-3,6 V, Topr= -40° to +85°C, serial interface, SM pkg 24L CSP	7,52
	(CurrentRF)	
CRF2101	Mixer, active, P(LO)= -10 to 0 dBm, F(RF)= 0-6,5 GHz, F(LO)= 0-5 GHz, F(IF)= 0-1,5 GHz, OP1dB= 4 dB, Gn Conv= -20 to 3 dB, Topr= -40° to +85°C, plastic SM pkg SOIC-8	7,14
	(Hittite Microwave Corp.)	
HMC175MS8	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 1,7-4,5 GHz, F(IF)= DC-1000 MHz, CL= 8 dB, P1(RF)= +12 dBm, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	4,34
HMC208MS8	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 700-2000 MHz, F(IF)= DC-500 MHz, CL= 9 dB, P1(RF)= +10 dBm, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	6,91
HMC218MS8	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 4,5-6 GHz, F(IF)= DC-1600 MHz, CL= 8 dB, P1(RF)= +10 dBm, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	3,52
HMC285	Mixer, single-balanced, P(LO)= +10 dBm, F(RF/LO)= 1700-3500 MHz, F(IF)= DC-900 MHz, CL= 9 dB, P1(RF)= +11 dBm, Topr= -40° to +85°C, plastic SM pkg SOT26	2,33
HMC410MS8 G	Mixer, High IP3, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 9-15 GHz, F(IF)= DC-2500 MHz, CL= 8 dB, P1(RF)= +14 dBm, IP3= +24 dBm, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	12,43
HMC411MS8 G	Mixer, double-balanced, P(LO)= 13 dBm, F(RF/LO)= 10-15 GHz, F(IF)= DC-3000 MHz, CL= 9 dB, P1(RF)= 9 dBm, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	10,41
HMC412MS8 G	Mixer, double-balanced, P(LO)= 13 dBm, F(RF/LO)= 9-15 GHz, F(IF)= DC-2500 MHz, CL= 8 dB, P1(RF)= 9,5 dBm, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	11,90

Модель	Назначение	Цена
HMC485MS8 G	Mixer, High IP3, P(LO)= -2 to +4 dBm, F(RF)= 1,7-2,2 GHz, F(IF)= 50-300 MHz, CL= 9 dB, P1(RF)= +21 dBm, IP3= +34 dBm, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	8,38
HMC527LC4	Mixer, I/Q IRM, F(RF)= 8,5-13,5 GHz, F(IF)= DC-2000 MHz, Gn Conv= -7,5 dB, Iso(LO/Rf)= 35 dB, Topr= -40° to +85°C, ceramic SM pkg 4x4 mm	34,86
(Mini-Circuits)		
ADE-1	Mixer, P(LO)= +7 dBm, F(RF/LO)= 0,5-500 MHz, F(IF)= DC-500 MHz, P1(RF)= +1 dBm, CL= 5,0 dB, Topr= -40° to +85°C, plastic SM pkg	10,45
ADE-1H	Mixer, P(LO)= +17 dBm, F(RF/LO)= 0,5-500 MHz, F(IF)= DC-500 MHz, P1(RF)= +14 dBm, CL= 5,3 dB, Topr= -40° to +85°C, plastic SM pkg	9,95
ADE-1MH	Mixer, P(LO)= +13 dBm, F(RF/LO)= 2-500 MHz, F(IF)= DC-500 MHz, P1(RF)= +9 dBm, CL= 8,0 dB, Topr= -40° to +85°C, plastic SM pkg	10,95
ADE-2ASK	Mixer, P(LO)= +7 dBm, F(RF/LO)= 1-1000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 9,5 dB, Topr= -40° to +85°C, plastic SM pkg	7,77
ADE-12	Mixer, P(LO)= +7 dBm, F(RF/LO)= 50-2000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 9,0 dB, Topr= -40° to +85°C, plastic SM pkg	14,95
ADE-12H	Mixer, P(LO)= +17 dBm, F(RF/LO)= 500-1200 MHz, F(IF)= DC-250 MHz, P1(RF)< +14 dBm, CL= 8,2 dB, Topr= -40° to +85°C, plastic SM pkg	20,95
ADE-17H	Mixer, P(LO)= +17 dBm, F(RF/LO)= 100-1700 MHz, F(IF)= 50-1500 MHz, P1(RF)< +14 dBm, CL= 9,5 dB, Topr= -40° to +85°C, plastic SM pkg	20,95
ADE-18	Mixer, P(LO)= +7 dBm, F(RF/LO)= 1700-2500 MHz, F(IF)= DC-600 MHz, P1(RF)< +1 dBm, CL= 7,3 dB, Topr= -40° to +85°C, plastic SM pkg	4,83
ADE-18W	Mixer, P(LO)= +7 dBm, F(RF/LO)= 1750-3500 MHz, F(IF)= DC-700 MHz, P1(RF)< +1 dBm, CL= 8,9 dB, Topr= -40° to +85°C, plastic SM pkg	15,95
ADE-20	Mixer, P(LO)= +7 dBm, F(RF/LO)= 1500-2000 MHz, F(IF)= DC-300 MHz, P1(RF)< +1 dBm, CL= 7,8 dB, Topr= -40° to +85°C, plastic SM pkg	16,95
ADE-30W	Mixer, P(LO)= +7 dBm, F(RF/LO)= 300-4000 MHz, F(IF)= DC-950 MHz, P1(RF)< +1 dBm, CL= 9,8 dB, Topr= -40° to +85°C, plastic SM pkg	20,95
ADE-35	Mixer, P(LO)= +7 dBm, F(RF/LO)= 1600-3500 MHz, F(IF)= DC-1500 MHz, P1(RF)< +1 dBm, CL= 9,8 dB, Topr= -40° to +85°C, plastic SM pkg	16,95
ADE-35MH	Mixer, P(LO)= +13 dBm, F(RF/LO)= 5-3500 MHz, F(IF)= 5-2500 MHz, P(RF)< +9 dBm, CL= 10,5 dB, Topr= -40° to +85°C, plastic SM pkg	16,73
ASK-1-KK81	Mixer, P(LO)= +7 dBm, F(RF/LO)= 1- 600 MHz, F(IF)= DC-600 MHz, P(RF)< +1 dBm, CL= 5,58 dB, Topr= -40° to +85°C, plastic SM pkg	9,73
JMS-1	Mixer, P(LO)= +7 dBm, F(RF/LO)= 2- 500 MHz, F(IF)= DC-500 MHz, P1(RF)< +1 dBm, CL= 8 dB, Topr= -40° to +85°C, ceramic SM pkg	6,93
JMS-2	Mixer, P(LO)= +7 dBm, F(RF/LO)= 20-1000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 9,5 dB, Topr= -40° to +85°C, ceramic SM pkg	10,43
JYM-30H	Mixer, P(LO)= +17 dBm, F(RF/LO)= 2-3000 MHz, F(IF)= 4-1400 MHz, P1(RF)< +10 dBm, CL= 10,5 dB, Topr= -40° to +85°C, plastic SM pkg	33,53
LRMS-1MH	Mixer, P(LO)= +13 dBm, F(RF/LO)= 2-500 MHz, F(IF)= DC-500 MHz, P1(RF)< +9 dBm, CL= 5,65 dB, Topr= -40° to +85°C, ceramic SM pkg	12,53
LRMS-2LHJ	Mixer, P(LO)= +10 dBm, F(RF/LO)= 5-1000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +5 dBm, CL= 6,44 dB, Topr= -40° to +85°C, ceramic SM pkg	12,53
LRMS-5J	Mixer, P(LO)= +7 dBm, F(RF/LO)= 5-1500 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 5,92 dB, Topr= -40° to +85°C, ceramic SM pkg	19,53
LRMS-11A	Mixer, P(LO)= +7 dBm, F(RF/LO)= 1500-1900 MHz, F(IF)= 40-400 MHz, P1(RF)< +1 dBm, CL= 7,44 dB, Topr= -40° to +85°C, ceramic SM pkg	23,73
LRMS-30J	Mixer, P(LO)= +7 dBm, F(RF/LO)= 200-3000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 6,8 dB, Topr= -40° to +85°C, ceramic SM pkg	12,95
LRMS-860	Mixer, P(LO)= +7 dBm, F(RF/LO)= 800-1050 MHz, F(IF)= DC-250 MHz, P1(RF)< +1 dBm, CL= 7,5 dB, Topr= -40° to +85°C, ceramic SM pkg	16,03
MBA-9	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 800-100 MHz, F(IF)= DC-200 MHz, P1(RF)< +1 dBm, CL= 9,0 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	15,33
MBA-9H	Mixer, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 800-1000 MHz, F(IF)= DC-200 MHz, P1(RF)< +10 dBm, CL= 9,0 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	13,93
MBA-9MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 800-100 MHz, F(IF)= DC-200 MHz, P1(RF)< +9 dBm, CL= 9,0 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,13
MBA-10L	Mixer, double-balanced, P(LO)= +3 dBm, F(RF/LO)= 800-1000 MHz, F(IF)= DC-200 MHz, P1(RF)= 0 dBm, CL= 9,5 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,95
MBA-10VL	Mixer, double-balanced, P(LO)= 0 dBm, F(RF/LO)= 800-1000 MHz, F(IF)= DC-200 MHz, P1(RF)= -3 dBm, CL= 9,8 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	8,33
MBA-12	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 800-2500 MHz, F(IF)= DC-500 MHz, P1(RF)< +1 dBm, CL= 9,0 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	10,95
MBA-12H	Mixer, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 800-2500 MHz, F(IF)= DC-200 MHz, P1(RF)< +10 dBm, CL= 9,0 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	13,93
MBA-12MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 800-2500 MHz, F(IF)= DC-500 MHz, P1(RF)< +9 dBm, CL= 9,5 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,13
MBA-15L	Mixer, double-balanced, P(LO)= +4 dBm, F(RF/LO)= 1200-2400 MHz, F(IF)= DC-600 MHz, P1(RF)= 0 dBm, CL= 8,5 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,95
MBA-15LH	Mixer, double-balanced, P(LO)= +10 dBm, F(RF/LO)= 1200-2400 MHz, F(IF)= DC-600 MHz, P1(RF)< +5 dBm, CL= 8,5 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,95

MBA-15MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 1400-2400 MHz, F(IF)= DC-600 MHz, P1(RF)< +9 dBm, CL= 8,5 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	12,95
MBA-18L	Mixer, double-balanced, P(LO)= +4 dBm, F(RF/LO)= 1600-3200 MHz, F(IF)= DC-500 MHz, P1(RF)< -1 dBm, CL= 8,9 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	9,73
MBA-18LH	Mixer, double-balanced, P(LO)= +10 dBm, F(RF/LO)= 1600-3200 MHz, F(IF)= DC-500 MHz, P1(RF)< +5 dBm, CL= 8,5 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,95
MBA-25L	Mixer, double-balanced, P(LO)= +4 dBm, F(RF/LO)= 2000-3000 MHz, F(IF)= DC-600 MHz, P1(RF)= 0 dBm, CL= 8,6 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	16,73
MBA-25LH	Mixer, double-balanced, P(LO)= +10 dBm, F(RF/LO)= 2200-3600 MHz, F(IF)= DC-500 MHz, P1(RF)< +5 dBm, CL= 9,2 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,95
MBA-25MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 2000-3000 MHz, F(IF)= DC-500 MHz, P1(RF)< +9 dBm, CL= 8,6 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	12,95
MBA-26	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 2200-2700 MHz, F(IF)= DC-500 MHz, P1(RF)< +1 dBm, CL= 8,0 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	8,33
MBA-35LH	Mixer, double-balanced, P(LO)= +10 dBm, F(RF/LO)= 3000-4000 MHz, F(IF)= DC-700 MHz, P1(RF)< +5 dBm, CL= 8,5 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	9,73
MBA-35MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 3000-4000 MHz, F(IF)= DC-700 MHz, P1(RF)< +9 dBm, CL= 8,7 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	11,13
MBY-20H	Mixer, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 1700-2200 MHz, F(IF)= DC-700 MHz, P1(RF)< +10 dBm, CL= 8,5 dB, Topr= -40° to +85°C, blue cell technology, open style, ceramic base, SM pkg	16,73
MCA-35H	Mixer, triple-balanced, P(LO)= +17 dBm, F(RF/LO)= 500-3500 MHz, F(IF)= 10-1500 MHz, P1(RF)< +14 dBm, CL= 8,9 dB, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	13,95
MCA-35H+	Mixer, triple-balanced, P(LO)= +17 dBm, F(RF/LO)= 500-3500 MHz, F(IF)= 10-1500 MHz, P1(RF)< +14 dBm, CL= 8,9 dB, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	13,95
MCA-35MH+	Mixer, triple-balanced, P(LO)= +13 dBm, F(RF/LO)= 500-3500 MHz, F(IF)= 10-1500 MHz, P1(RF)< +9 dBm, CL= 8,9 dB, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	12,95
MCA-50H	Mixer, triple-balanced, P(LO)= +17 dBm, F(RF/LO)= 1000-5000 MHz, F(IF)= 10-1500 MHz, P1(RF)< +14 dBm, CL= 7,3 dB, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	14,95
MCA1-12G	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 3,8-12 GHz, F(IF)= DC-1800 MHz, P1(RF)= +1 dBm, CL= 6,2 dB, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	15,95
MCA1-24LH+	Mixer, double-balanced, P(LO)= +10 dBm, F(RF/LO)= 300-2400 MHz, F(IF)= DC-700 MHz, P1(RF)< +5 dBm, CL= 6,5 dB, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	11,45
MCA1-24MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 300-2400 MHz, F(IF)= DC-700 MHz, P1(RF)< +9 dBm, CL= 6,1 dB, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	11,95
MCA1-42	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 1000-4200 MHz, F(IF)= DC-1500 MHz, P1(RF)< +1 dBm, CL= 8,9 dB, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	11,95
MCA1-60+	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 1600-6000 MHz, F(IF)= DC-2000 MHz, P1(RF)< +1 dBm, CL= 8,5 dB, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	12,95
MCA1-85L+	Mixer, double-balanced, P(LO)= +4 dBm, F(RF/LO)= 2800-8500 MHz, F(IF)= DC-1200 MHz, P1(RF)< 0 dBm, CL> 8,4 dB, Topr= -55° to +100°C, blue cell technology, open style, ceramic base, SM pkg	14,45
RMS-1	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 0,5-500 MHz, F(IF)= DC-500 MHz, P1(RF)< +1 dBm, CL= 8,5 dB, Topr= -55° to +100°C, ceramic SM pkg	8,75
RMS-2	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 5-1000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 9,5 dB, Topr= -40° to +85°C, ceramic SM pkg	9,73
RMS-2D	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 5-1000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 10 dB, Topr= -40° to +85°C, ceramic SM pkg	10,15
RMS-2U	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 10-1000 MHz, F(IF)= 10-750 MHz, P1(RF)< +1 dBm, CL= 9,5 dB, Topr= -40° to +85°C, ceramic SM pkg	16,03
RMS-5MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 10-1500 MHz, F(IF)= DC-900 MHz, P1(RF)< +9 dBm, CL= 9,5 dB, Topr= -40° to +85°C, ceramic SM pkg	22,33
RMS-11A	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 1500-1900 MHz, F(IF)= 40-400 MHz, P1(RF)< +1 dBm, CL= 9,0 dB, Topr= -40° to +85°C, ceramic SM pkg	23,73
RMS-860	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 800-1050 MHz, F(IF)= DC-250 MHz, P1(RF)< +1 dBm, CL= 7,5 dB, Topr= -40° to +85°C, ceramic SM pkg	16,03
SBL-1X	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 10-1000 MHz, F(IF)= 5-500 MHz, P1(RF)< +1 dBm, CL= 8,0 dB, Topr= -55° to +100°C, metal plug-in pkg	-
SCM-2500LH	Mixer, double-balanced, P(LO)= +10 dBm, F(RF/LO)= 500-2500 MHz, F(IF)= DC-500 MHz, P1(RF)< +5 dBm, CL= 10 dB, Topr= -40° to +85°C, plastic SM pkg	19,53
SKY-7G	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 2000-7000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 9,8 dB, Topr= -40° to +85°C, plastic SM pkg	23,73
SKY-60H	Mixer, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 2500-6000 MHz, F(IF)= DC-1500 MHz, P1(RF)< +14 dBm, CL= 9,7 dB, Topr= -40° to +85°C, plastic SM pkg	26,53
SKY-60MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 2500-6000 MHz, F(IF)= DC-1500 MHz, P1(RF)< +1 dBm, CL= 9,5 dB, Topr= -40° to +85°C, plastic SM pkg	25,13
SYM-11	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 1-2500 MHz, F(IF)= 10-500 MHz, P1(RF)< +1 dBm, CL= 9,8 dB, Topr= -40° to +85°C, plastic SM pkg	13,93
SYM-11H	Mixer, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 50-2000 MHz, F(IF)= 50-1950 MHz, P1(RF)< +10 dBm, CL= 9,0 dB, Topr= -40° to +85°C, plastic SM pkg	25,13
SYM-11LH	Mixer, double-balanced, P(LO)= +10 dBm, F(RF/LO)= 1-2000 MHz, F(IF)= 10-600 MHz, P1(RF)< +5 dBm, CL= 9,85 dB, Topr= -40° to +85°C, plastic SM pkg	16,73

SYM-11MH	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 50-2000 MHz, F(IF)= 50-1000 MHz, P1(RF)< +9 dBm, CL= 9,9 dB, Topr= -40° to +85°C, plastic SM pkg	22,33
SYM-18H	Mixer, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 5-1800 MHz, F(IF)= 10-1500 MHz, P1(RF)= +14 dBm, CL= 5,75 dB, Topr= -40° to +85°C, plastic SM pkg,	19,95
SYM-25DHW	Mixer, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 80-2500 MHz, F(IF)= DC-1000 MHz, P1(RF)= +14 dBm, CL= 8,6 dB, Topr= -55° to +100°C, plastic SM pkg	19,95
SYM-25DLHW	Mixer, double-balanced, P(LO)= +10 dBm, F(RF/LO)= 40-2500 MHz, F(IF)= DC-1000 MHz, P1(RF)= +5 dBm, CL= 8,8 dB, Topr= -40° to +85°C, plastic SM pkg	17,95
SYM-25DMHW	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 40-2500 MHz, F(IF)= DC-1000 MHz, P1(RF)= +9 dBm, CL= 9,0 dB, Topr= -40° to +85°C, plastic SM pkg	18,95
SYM-30DHW	Mixer, triple-balanced, P(LO)= +17 dBm, F(RF/LO)= 5-3000 MHz, F(IF)= 5-1500 MHz, P1(RF)= +14 dBm, CL=9,1 dB, Topr= -40° to +85°C, plastic SM pkg,	20,95
SYM-860	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 800-1050 MHz, F(IF)= DC-250 MHz, P1(RF)< +1 dBm, CL= 7,0 dB, Topr= -40° to +85°C, plastic SM pkg	12,53
TAK-5	Mixer, double-balanced, P(LO)=+ 7 dBm, F(RF/LO)=0,01-250 MHz, F(IF)=DC-250 MHz, P1(RF)< +1 dBm, CL= 8,5 dB, Topr= -55° to +100°C, metal plug-in pkg	32,13
TUF-1H	Mixer, double-balanced, P(LO)= +17 dBm, F(RF/LO)= 2- 600 MHz, F(IF)= DC-600 MHz, P1(RF)< +14 dBm, CL= 8 dB, Topr= -55° to +100°C, metal plug-in pkg	14,28
TUF-2	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 50-1000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 9 dB, Topr= -55° to +100°C, metal plug-in pkg	8,68
TUF-2SM	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 50-1000 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 9 dB, Topr= -55° to +100°C, metal SM pkg	8,68
TUF-3MHSM	Mixer, double-balanced, P(LO)= +13 dBm, F(RF/LO)= 0,15-400 MHz, F(IF)= DC-400 MHz, P1(RF)< +9 dBm, CL= 8 dB, Topr= -55° to +100°C, metal SM pkg	14,28
TUF-5	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 20-1500 MHz, F(IF)= DC-1000 MHz, P1(RF)< +1 dBm, CL= 9 dB, Topr= -55° to +100°C, metal plug-in pkg	14,63
TUF-11A	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 1400-1900 MHz, F(IF)= 40-500 MHz, P1(RF)< +1 dBm, CL= 8,6 dB, Topr= -55° to +100°C, metal plug-in pkg	26,53
TUF-11ASM	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 1400-1900 MHz, F(IF)= 40-500 MHz, P1(RF)< +1 dBm, CL= 8,6 dB, Topr= -55° to +100°C, metal SM pkg	26,53
TUF-860	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 800-1050 MHz, F(IF)= DC-250 MHz, P1(RF)< +1 dBm, CL= 7,75 dB, Topr= -55° to +100°C, metal plug-in pkg	14,63
TUF-860SM	Mixer, double-balanced, P(LO)= +7 dBm, F(RF/LO)= 800-1050 MHz, F(IF)= DC-250 MHz, P1(RF)< +1 dBm, CL= 7,75 dB, Topr= -55° to +100°C, metal SM pkg	14,63
UNCL-R1	Mixer, P(LO)= +7 dBm, F(RF/LO)= 10-500 MHz, F(IF)= DC-500 MHz, P1(RF)< -10 dBm, CL= 5 dB, Topr= -55° to +100°C, metal plug-in pkg	36,33
	(Peregrine Semiconductor Corp.)	
PE4134-01	Mixer, passive, quad, MOSFET, P(LO)= 10-17 dBm, F(LO)= 1540-1740 MHz, F(RF)= 1800-2000 MHz, F(IF)= 260 MHz, CL= 7,4 dB, Iso(LO/RF)= 31 dB, P1(RF)= +20 dBm, plastic SM pkg 6L MLPM	6,90
PE4135-01	Mixer, passive, quad, MOSFET, P(LO)= 10-17 dBm, F(LO)= 750-850 MHz, F(RF)= 820-920 MHz, F(IF)= 70 MHz, CL= 6,8 dB, Iso(LO/RF)= 32 dB, P1(RF)= +20 dBm, plastic SM pkg 6L MLPM	6,90
PE4140-01	Mixer, passive broadband quad MOSFET, P(LO)=17 dBm, F(LO)=1630-2130 MHz, F(RF)=1700-2200 MHz, F(IF)=70 MHz, CL=6,5 dB, Iso(LO/RF)=30 dB, plastic SM pkg 6L MLPM	4,93
	(RF Prime)	
LRFMS-1-SM6	Mixer, P(LO)= +7 dBm, F(RF/LO)= 0,5-500 MHz, F(IF)=DC-500 MHz, P(RF)<+17 dBm, CL= 6,0 dB, Topr= -55° to +100°C, SM pkg	2,65
	(Coaxial Components Corp.)	
1246-1	Connector, MCX(f), straight, for P,C, board, 50 Ohm, 75 Ohm, F= DC-6 GHz, Vrms= 335 V	7,42
1263-1	Connector, MCX(f), right angle, for P,C, board, 50 Ohm, 75 Ohm, F= DC-6 GHz, Vrms= 335 V	7,30
1422-24A-1	Connector, MCX(m), straight, for flexible cable RG174, 188A, 316 (crimp), 50 Ohm, 75 Ohm, F= DC-6 GHz, Vrms= 335 V	5,87
1M227-31-1	Connector, MMCX(m), right angle, for semi-rigid/flexible cable RG405 (solder), 50 Ohm, F= DC-6 GHz, Vrms= 170 V	10,94
1M230EM-1	Connector, MMCX(m), edge mount, for P,C, board, 50 Ohm, F= DC-6 GHz, Vrms= 170 V	7,50
1M231-1	Connector, MMCX(f), right angle, for P,C, board, 50 Ohm, F= DC-6 GHz, Vrms= 170 V	11,32
1M246-1	Connector, MMCX(f), straight, for P,C, board, 50 Ohm, F= DC-6 GHz, Vrms= 170 V	9,19
2541G-724A-7	Connector, coaxial, BNC(m), straight, for flexible cable RG174,178,188A,316 etc (crimp), retaining ring, 50 Ohm, F= DC-4 GHz, Vrms= 500 V	6,37
3113-9	Dust caps, SMA(m), without chain	4,22
3115EM-1-1	Connector, coaxial, SMA(f), straight, P,C, board, 50 Ohm, F= DC-18 GHz, Vrms= 500 V	19,72
3148-1	Connector, coaxial, SMA(m), straight, P,C, board, 50 Ohm, F= DC-18 GHz, Vrms= 500 V	23,81
3149-1	Connector, coaxial, SMA(m), right angle, P,C, board, 50 Ohm, F= DC-18 GHz, Vrms= 500 V	27,42
3183-1-9	Connector, coaxial, SMA(m), straight, for semi-rigid/ultra-flex cable RG402 (solder), retaining ring, 50 Ohm, F= DC-18 GHz, Vrms= 500 V	4,94
3207-1-1	Connector, coaxial, SMA(m), straight, for semi-rigid/ultra-flex cable RG402 (solder), 50 Ohm, F= DC-18 GHz, Vrms= 500 V	6,54
3210-1-1	Connector, coaxial, SMA(f), bulkhead, for semi-rigid/ultra-flex cable RG402 (solder), 50 Ohm, F= DC-18 GHz, Vrms= 500 V	21,84
3911A-1-1	Connector, coaxial, SMA(m), right angle, for flexible cable RG55, 58, 141, 142, 223, 303,400, LRM195 (clamp), 50 Ohm, F= DC-18 GHz, Vrms= 500 V	22,71

3917-3-9	Connector, coaxial, SMA(m), straight, for flexible cable RG174, 179, 187, 188, 136 (clamp), 50 Ohm, a= 0,116", F= DC-18 GHz, Vrms= 500 V	17,10
6225-1	Connector, SMB(m), straight, chassis receptacle, for cable (solder), 75 Ohm, F= DC-4 GHz, Vrms= 700 V	7,25
6240-7	Connector, SMB(m), straight, chassis receptacle, for cable (solder), 75 Ohm, F= DC-4 GHz, Vrms= 700 V	3,63
6M230-1	Connector, SSMB(m), straight, P,C, board, 50 Ohm, F= DC-12,4 GHz, Vrms= 250 V	6,42
8130B-1	Connector, SMC(m), straight, bulkhead, P,C, board, 50 Ohm, F= DC-10 GHz, Vrms= 700 V	4,51
8140-1	Connector, SMC(m), straight, chassis receptacle, for cable (solder), 50 Ohm, F= DC-10 GHz, Vrms= 700 V	7,25
	(Philips Semiconductors)	
HEF4046BPN	Phase-locked loop, F= 1-2,7 MHz, supply= 3-15 V, Topr= -40° to +85°C, CMOS technology, plastic 16L DIL (SOT38-1)	0,25
	(International Rectifier)	
IRLML6302	Transistor, P-channel MOSFET, V(br)dss= -20 V, Id= -0,78 A, Rds(on)= 0,6 Ohm, Pdiss= 540 mW, plastic SM pkg SOT-23	0,20
	(Motorola)	
MRF559	Transistor, NPN silicon, F= 870 MHz, Gn= 8 dB, PAE= 50 %, OP1dB> 20 dBm, OP= 0,5 W , Pdiss= 2 W, plastic SM pkg 4L Micro-X	5,50
	(Sirenza Microdevices, Inc.)	
SPF-2086TK	Transistor, pHEMT GaAs FET, F= 0,1-4 GHz, Gn= 17 dB, PAE= 50 %, OP1dB= 17 dBm , Pdiss= 400 mW, plastic SM pkg 4L Micro-X	6,45
	(WJ Communications, Inc.)	
FP2189	Transistor, HFET, F= 0,05-4 GHz, Gn= 19 dB, OP1dB= 31 dBm , Pdiss= 4 W, SM pkg SOT-89	10,16
	(AeroComm, Inc.)	
AC4490I-100M-5	Transceiver, F(RF)= 902-928 MHz, OP= 5-200 mW, Sens= -90 dBm, FHSS FSK modulation, data rate up to 115,2 Kbps, supply= 4,5-5,5 V, Topr= -40°C to +80°C, TTL serial interface, MMCX antenna, module 48,1x41,9x5,1 mm	141,57
	(CHIPCON AS)	
CC1020	Transceiver, F(RF1)= 424-470 MHz, Fstep< 300 Hz and F(RF2)= 848-940 MHz, Fstep< 600 Hz, OP= -20 to 2 dBm, Sens= -119 dBm , ASK/ FSK /GFSK modulation, data rate< 153,6 kbaud, supply= 2,3 V to 3,6 V, Topr= -40°C to +85°C, CMOS technology, SM pkg QFN32	9,86
CC1021	Transceiver, F(RF1)= 402-470 MHz, Fstep< 300 Hz and F(RF2)= 804-940 MHz, Fstep< 600 Hz, OP= -20 to 10 dBm, Sens= -113 dBm (38,4 kHz)/ -108 dBm (102,4 kHz), OOK/ASK/ FSK /GFSK modulation, data rate< 153,6 kbaud, supply= 2,3 V to 3,6 V, Topr= -40°C to +85°C	8,46
CC2400	Transceiver, F(RF)= 2400-2483 MHz, Fstep= 1 MHz, OP= 0 dBm, Sens= -85 dBm , FSK /GFSK modulation, data rate 10 kbps/250 kbps/1 Mbps, supply= 1,6 V to 3,6 V, Topr= -40°C to +85°C, CMOS technology, SM pkg QLP-48 7x7 mm	7,96
CC2420	Transceiver, F(RF)= 2400-2483,5 MHz, Fstep= 1 MHz/ 5 MHz, OP= 0 dBm, Sens= -94 dBm , O-QPSK modulation, data rate< 250 kbps, supply= 2,1 V to 3,6 V, Topr= -40°C to +85°C, CMOS technology, SM pkg QLP-48 7x7 mm	9,16
CC400	Transceiver, F(RF)= 300-500 MHz, Fstep= 5 kHz, OP= 0 to 14 dBm, Sens= -112 dBm, FSK modulation, data rate< 19,2 kbaud, supply= 2,7 V to 3,3 V, Topr= -30°C to +85°C, CMOS technology, SM pkg SSOP-28	15,92
CC900	Transceiver, F(RF)= 800-1000 MHz, Fstep= 250 Hz, OP= -20 to 4 dBm, Sens= -110 dBm, FSK modulation, data rate< 19,2 kbaud, supply= 2,7 V to 3,3 V, Topr= -30°C to +85°C, CMOS technology, SM pkg SSOP-28	15,92
	(MAXIM)	
MAX3222CPN	Transceiver, RS-232 interface, data rate< 120 kbps, supply= 3 V to 5,5 V, Topr= 0° to +70°C, CMOS technology, 18-pin plastic DIP pkg	2,95
	(RF Micro Devices)	
RF2907	Transceiver, F(RF)= 300-1500 MHz, P(TX)= +7 dBm, Sens= -97 dBm , AM/ASK/OOK modulation, data rate 2 kbps, supply= 2,7 V- 5 V, Topr= -40°C to +85°C, SM pkg SSOP-28	9,80
RF2908	Receiver w/PLL Frequency Synthesizer, direct conversion, spread spectrum, F(RF)= 700-1100 MHz, BW(IF)= 960 kHz, Step size= 300 kHz, Ph N= -66 dBc/Hz (10 kHz), Sens= -100 dBm, supply= 2,7 V to 3,6 V, Topr= -40°C to +85°C, plastic SM pkg LQFP-48	12,95
RF2926	Transceiver, dual conversion, F(RF)= 300-1000 MHz, BW(IF)= 130 MHz, P(TX)= +7 dBm, Sens= -99 dBm , FM/FSK modulation, supply= 2,7 V to 5 V, Topr= -40°C to +85°C, plastic SM pkg LQFP-48	13,95
RF2938	Transceiver, spread spectrum, F(RF)= 2,4 GHz, F(IF)= 45-500 MHz, P(TX)= +6 dBm, supply= 2,7 V to 3,6 V, Topr= -40°C to +85°C, plastic SM pkg TQFP-48	29,95
	(Coilcraft, Inc.)	
TTWB-1-B	Transformer, RF, ratio=1:1, BW(3dB)= 0,13-425 MHz, IP(RF)= 0,25 W, Idc= 250 mA, Iso= 400 V, Topr= -40° to +85°C, ceramic SM pkg	1,82
TTWB2010	Transformer, RF, ratio= 1:1, BW(3dB)= 0,0035-125 MHz, IP(RF)= 0,25 W, Idc= 250 mA, Iso= 400 V, Topr= -40° to +85°C, ceramic SM pkg	-
WB1040-SML_	Transformer, RF, ratio= 4:1, BW(3dB)= 0,2-300 MHz, IP(RF)= 0,25 W, Idc= 250 mA, Iso= 500 V, Topr= -40° to +85°C, plastic SM pkg	1,91
WB2010-SML_	Transformer, RF, ratio= 1:1, BW(3dB)= 0,005-100 MHz, IP(RF)= 0,25 W, Idc= 250 mA, Iso= 500 V, Topr= -40° to +85°C, plastic SM pkg	1,85
WB3010-1-SML_	Transformer, RF, ratio= 1:1, BW(3dB)= 0,04-175 MHz, IP(RF)= 0,25 W, Idc= 250 mA, Iso= 500 V, Topr= -40° to +85°C, plastic SM pkg	1,62

WB3010-SML_	Transformer, RF, ratio= 1:1, BW(3dB)= 0,005-100 MHz, IP(RF)= 0,25 W, Idc= 250 mA, Iso= 500 V, Topr= -40° to +85°C, plastic SM pkg	1,82
	(Mini-Circuits)	
ADT1-1	Transformer, RF, ratio= 1, BW(3dB)= 0,15-400 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	14,95
ADT1-1WT	Transformer, RF, 75 Ohm, ratio= 1, BW(3dB)= 0,4-800 MHz, IP(RF)= 0,5 W, Topr= -40° to +85°C, plastic SM pkg	14,95
ADT16-6	Transformer, RF, ratio= 16, BW(3dB)= 0,25-105 MHz, IP(RF)= 0,5 W, Topr= -20° to +85°C, plastic SM pkg	9,95
ADT2-1T	Transformer, RF, ratio= 2, BW(3dB)= 0,4-450 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	15,65
ADT2-1T-1P	Transformer, RF, ratio= 2, BW(3dB)= 8-600 MHz, IP(RF)= 1 W, Topr= -20° to +85°C, plastic SM pkg	14,25
ADT3-1T	Transformer, RF, ratio= 3, BW(2dB)= 1-500 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	15,45
ADT4-1T	Transformer, RF, ratio= 4, BW(3dB)= 9-625 MHz, IP(RF)= 1 W, Topr= -20° to +85°C, plastic SM pkg	15,95
ADT4-1WT	Transformer, RF, ratio= 4, BW(3dB)= 2-775 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	14,95
ADT4-6	Transformer, RF, ratio= 4, BW(3dB)= 0,07-250 MHz, IP(RF)= 0,5 W, Topr= -20° to +85°C, plastic SM pkg	9,95
ADT4-6T	Transformer, RF, ratio= 4, BW(3dB)= 0,06-300 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	9,50
ADT9-1T	Transformer, RF, ratio= 9, BW(2dB)= 1-250 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	15,95
ADTL1-18-75	Transformer, RF, 75 Ohm, ratio= 1, BW(2dB)= 5-1800 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	14,95
ADTL1-4-75	Transformer, RF, 75 Ohm, ratio= 1, BW(3dB)= 0,5-1000 MHz, IP(RF)= 1 W, Topr= -20° to +85°C, plastic SM pkg	14,95
JTX-2-10T	Transformer, RF, 75 Ohm, ratio= 2, BW(1dB)= 50-1000 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	11,95
T1-1T	Transformer, RF, ratio= 1, BW(3dB)= 0,08-200 MHz, IP(RF)=0,25 W, Topr= -20° to +85°C, plastic flat-pack pkg, case style W38	6,23
T1-6T	Transformer, RF, ratio= 1, BW(3dB)= 0,015-300 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic flat-pack pkg, case style W38	9,73
T1-1-X65	Transformer, RF, ratio= 1, BW(3dB)= 0,15-400 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic plug-in pkg, case style X65	4,55
T1-1-KK81	Transformer, RF, ratio= 1, BW(3dB)= 0,15-400 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	4,55
T16-1H-KK81	Transformer, RF, ratio=16, BW(3dB)= 7-85 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	9,03
T16-6T-KK81	Transformer, RF, ratio= 16, BW(3dB)= 0,03-75 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	7,91
T1-6-KK81	Transformer, RF, ratio= 1, BW(3dB)= 0,01-150 MHz, IP(RF)=0,25 W, Topr= -20° to +85°C, plastic SM pkg	7,91
T4-1-KK81	Transformer, RF, ratio= 4, BW(3dB)= 0,2-350 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	4,55
T4-6-KK81	Transformer, RF, ratio= 4, BW(3dB)= 0,02-200 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	7,91
T4-6T-KK81	Transformer, RF, ratio= 4, BW(3dB)= 0,02-250 MHz, IP(RF)=0,25 W, Topr= -20° to +85°C, plastic SM pkg	7,91
T-622-KK81	Transformer, RF, ratio= 1:1:1, BW(3dB)= 0,1-200 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	4,55
T-626-KK81	Transformer, RF, ratio= 1:1:1, BW(3dB)= 0,01-10 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	5,53
TC1.5-1	Transformer, RF, ratio= 1,5, BW(3dB)= 0,5-2200 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, ceramic base SM pkg	9,95
TC1-15	Transformer, RF, ratio= 1, BW= 350-1500 MHz, IP(RF)= 0,25 W, Topr= -40° to +85°C, open style, ceramic base SM pkg	9,95
TC1-1-13M	Transformer, RF, 50 Ohm, ratio= 1, BW= 4,5-3000 MHz, IP(RF)= 0,25 W, Topr= -40° to +85°C, open style, ceramic base SM pkg	9,95
TC16-1T	Transformer, RF, ratio= 16, BW(3dB)= 20-300 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, ceramic base SM pkg	9,95
TC2-1T	Transformer, RF, ratio= 2, BW(1dB)= 3-300 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, ceramic base SM pkg	9,95
TC4-14	Transformer, RF, ratio= 4, BW(3dB)= 200-1400 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, ceramic base SM pkg	9,95
TC8-1	Transformer, RF, ratio= 8, BW(3dB)= 2-500 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, ceramic base SM pkg	9,95
TC9-1	Transformer, RF, ratio= 9, BW(3dB)= 2-200 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, ceramic base SM pkg	9,95
TC9-1-75	Transformer, RF, 75 Ohm, ratio= 8, BW(3dB)= 0,3-475 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, ceramic base SM pkg	9,95

TCM2-1T	Transformer, RF, ratio= 2, BW(1dB)= 3-300 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, plastic base SM pkg	9,95
TCM4-1W	Transformer, RF, ratio= 4, BW(3dB)= 3-800 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, plastic base SM pkg	9,95
TCM4-6T	Transformer, RF, ratio= 4, BW(3dB)= 1,5-600 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, plastic base SM pkg	9,95
TCM4-14	Transformer, RF, ratio= 4, BW(3dB)= 200-1400 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, plastic base SM pkg	9,95
TCM4-25	Transformer, RF, ratio= 4, BW(3dB)= 500-2500 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, plastic base SM pkg	9,95
TCM8-1	Transformer, RF, ratio= 8, BW(3dB)= 2-500 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, open style, plastic base SM pkg	9,95
TCN4-22	Transformer, RF, ratio= 4, BW(3dB)= 1200-2200 MHz, IP(RF)= 5 W, Topr= -55° to +100°C, ceramic SM pkg	6,99
TMO1-1	Transformer, RF, ratio= 1, BW(3dB)= 0,15-400 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, upro-nickel plug-in pkg	8,75
TMO1-1T	Transformer, RF, ratio= 1, BW(3dB)= 0,05-200 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, upro-nickel plug-in pkg	11,13
TMO4-1	Transformer, RF, ratio= 4, BW(3dB)= 0,2-350 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, upro-nickel plug-in pkg	8,75
TT1-6-KK81	Transformer, RF, ratio= 1, BW(3dB)= 0,004-300 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, plastic SM pkg	9,73
TTCM4-4	Transformer, RF, ratio= 4, BW(3dB)= 0,5-400 MHz, IP(RF)= 0,25 W, Topr= -40° to +85°C, plastic SM pkg	9,95
TX9-1	Transformer, RF, ratio= 9, BW(3dB)= 1-200 MHz, IP(RF)= 0,25 W, Topr= -20° to +85°C, ceramic SM pkg	6,65
(RF Prime)		
RFTM-4A-Z	Transformer, RF, ratio= 1:4, BW(3dB)= 0,02-250 MHz, IP(RF)= 0,25 W, Topr= -55° to +100°C, plastic SM pkg	2,35
RFTM-3-SM6	Transformer, RF, ratio= 1:3, BW(3dB)= 0,06-300 MHz, IP(RF)= 0,25 W, Topr= -55° to +100°C, plastic SM pkg	1,95
(Toko)		
617DB-1010	Transformer, balun, ratio= 4, BW= 3,5-2000 MHz, open style SM pkg	2,10
(Hittite Microwave Corp.)		
HMC156C8	Frequency multiplier (x2), passive, Fin= 700-2400 MHz, CL= 15 dB, IP(RF)= 10-20 dBm, Iso(1Fo/4Fo)= 47/38 dB, Topr= -40° to +85°C, ceramic SM pkg 8L	58,80
HMC368LP4	Frequency multiplier (x2), active, Fin= 4500-8000 MHz, IP= 2 dBm, OP= 15 dBm, Ph N = -140 dBc/Hz (100 kHz), Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	38,22
HMC370LP4	Frequency multiplier (x4), active, Fin= 3600-4100 MHz, IP= -15 dBm, OP= -2 dBm, Ph N = -140 dBc/Hz (100 kHz), Topr= -40° to +85°C, plastic SM pkg QFN 4x4 mm	19,57
(Mini-Circuits)		
KBA-20	Frequency multiplier (x2), Fin= 1600-2200 MHz, CL= 12 dB, IP(RF)= +15 dBm, Topr= -40° to +85°C, blue cell technology, open style, ceramic base SM pkg	14,95
(RF Prime)		
RFDT-20-SM10	Frequency multiplier (x2), Fin= 1600-2200 MHz, CL= 11 dB, IP(RF)= 13 dBm, Topr= -55° to +10°C, blue cell technology, SM pkg	7,50
(Hittite Microwave Corp.)		
HMC278MS8 G	Amplifier, MPA, F= 1,7-3 GHz, Gn= 20 dB, NF= 6 dB, OP1dB= +19 dBm, supply= 3-5V/130 mA, Topr= -55° to +85°C, plastic SM pkg 8L MSOP	6,51
HMC308	Amplifier, MPA, driver, F= 1,3-3 GHz, Gn= 17 dB, NF= 9 dB, OP1dB= +15 dBm, supply= 3 V/35 mA or 5 V/40 mA, Topr= -40° to +85°C, plastic SM pkg SOT26	2,33
HMC315	Amplifier, MPA, F= DC-7 GHz, Gn= 14 dB, NF= 6,5 dB, OP1dB= +11 dBm, supply= 5-7 V/30-50 mA, Topr= -40° to +60°C, plastic SM pkg SOT26	1,79
HMC326MS8 G	Amplifier, MPA, HBT driver, F= 3-4,5 GHz, Gn= 21 dB, NF= 5 dB, OP1dB= +23,5 dBm, PAE> 40%, supply= 5 V/130 mA, Topr= -40° to +85°C, plastic SM pkg 8L MSOP	6,69
HMC373LP3	Amplifier, MPA/LNA, F= 0,7-1 GHz, Gn= 14 dB, NF= 0,9 dB, OP1dB= +21 dBm, supply= 5 V /90 mA, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	8,28
HMC453QS1 6G	Amplifier, HPA, F= 0,45-2,2 GHz, Gn= 14,5 dB, NF= 7 dB, OP1dB= +32 dBm, PAE= %, supply= V/ mA, Topr= -40° to +85°C, plastic SM pkg 16L QSOP	15,51
HMC455LP3	Amplifier, MPA, F= 1,7-2,5 GHz, Gn= 13 dB, NF= 6 dB, OP1dB= +27 dBm, PAE= 56%, supply= 5 V/150 mA, Topr= -40° to +85°C, plastic SM pkg QFN 3x3 mm	7,12
(Mini-Circuits)		
ERA-1SM	Amplifier, MPA, F= DC-8000 MHz, Gn= 9 dB/2 GHz, NF= 4,3 dB, OP1dB= +12 dBm, supply= 3,4 V/40 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	2,59
ERA-2	Amplifier, MPA, F= DC-6000 MHz, Gn= 13 dB/2 GHz, NF= 4 dB, OP1dB= +13 dBm, supply= 3,4 V/40 mA, Topr= -45° to +85°C, plastic drop-in pkg 4L Micro-X,	2,73
ERA-2SM	Amplifier, MPA, F= DC-6000 MHz, Gn= 13 dB/2 GHz, NF= 4 dB, OP1dB= +13 dBm, supply= 3,4 V/40 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	2,80
ERA-3SM	Amplifier, MPA, F= DC-3000 MHz, Gn= 16 dB/2 GHz, NF= 3,5 dB, OP1dB= +12,5 dBm, supply= 3,2 V/35 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	3,01

ERA-4	Amplifier, MPA, F= DC-4000 MHz, Gn= 11 dB/2 GHz, NF= 4,2 dB, OP1dB= +17,3 dBm, supply= 4,5 V/65 mA, Topr= -45° to +85°C, plastic drop-in pkg 4L Micro-X,	5,81
ERA-4SM	Amplifier, MPA, F= DC-4000 MHz, Gn= 11dB/2 GHz, NF= 4,2 dB, OP1dB= +17,3 dBm, supply= 4,5 V/65 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	5,88
ERA-5	Amplifier, MPA, F= DC-4000 MHz, Gn= 16 dB/2 GHz, NF= 4,3 dB, OP1dB= +18,4 dBm, supply= 4,9 V/65 mA, Topr= -45° to +85°C, plastic drop-in pkg 4L Micro-X,	5,81
ERA-5SM+	Amplifier, MPA, F= DC-4000 MHz, Gn= 16 dB/2 GHz, NF= 4,3 dB, OP1dB= +18,4 dBm, supply= 4,9 V/65 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	5,88
ERA-6	Amplifier, MPA, F= DC-4000 MHz, Gn= 10,5 dB/2 GHz, NF= 4,5 dB, OP1dB= +17,9 dBm, supply= 5 V/70 mA, Topr= -45° to +85°C, plastic drop-in pkg 4L Micro-X,	5,81
ERA-6SM	Amplifier, MPA, F= DC-4000 MHz, Gn= 10,5 dB/2 GHz, NF= 4,5 dB, OP1dB= +17,9 dBm, supply= 5 V/70 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	5,88
ERA-8SM	Amplifier, MPA, F= DC-2000 MHz, Gn= 17 dB/2 GHz, NF= 3,1 dB, OP1dB= +12,5 dBm, supply= 3,7 V/36 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	3,50
ERA-21SM	Amplifier, MPA, F= DC-8000 MHz, Gn= 11,2 dB/2 GHz, NF= 4,7 dB, OP1dB= +12,6 dBm, supply= 3,5 V/40 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	2,80
ERA-33SM	Amplifier, MPA, F= DC-3000 MHz, Gn= 15 dB/2 GHz, NF= 3,9 dB, OP1dB= +13,5 dBm, supply= 4,3 V/40 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	3,01
ERA-50SM	Amplifier, MPA, F= DC-1500 MHz, Gn= 16 dB/1,5 GHz, NF= 3,5 dB, OP1dB= 17,2 dBm, supply= 4,4 V/60 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	4,55
ERA-51SM	Amplifier, MPA, F= DC-4000 MHz, Gn= 14 dB/2 GHz, NF= 4,1 dB, OP1dB= +18,1 dBm, supply= 4,5 V/65 mA, Topr= -45° to +85°C, plastic SM pkg 4L Micro-X,	5,88
GALI-2	Amplifier, MPA, F= DC-8000 MHz, Gn= 12 dB/2 GHz, NF= 4,6 dB, OP1dB= +12,9 dBm, supply= 3,5 V/ 40 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	2,00
GALI-3	Amplifier, MPA, F= DC-3000 MHz, Gn= 17,5 dB/2 GHz, NF= 3,5 dB, OP1dB= +12,5 dBm, supply= 3,3 V/35 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	2,00
GALI-4	Amplifier, MPA, F= DC-4000 MHz, Gn= 11 dB/2 GHz, NF= 4 dB, OP1dB= +17,5 dBm, supply= 4,6 V/ 65 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	3,00
GALI-4+	Amplifier, MPA, F= DC-4000 MHz, Gn= 11 dB/2 GHz, NF= 4 dB, OP1dB= +17,5 dBm, supply= 4,6 V/ 65 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	3,00
GALI-5	Amplifier, MPA, F= DC-4000 MHz, Gn= 16 dB/2 GHz, NF= 3,5 dB, OP1dB= +18 dBm, supply= 4,4 V/65 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	3,00
GALI-39	Amplifier, MPA, F= DC-7000 MHz, Gn= 17,7 dB/2 GHz, NF= 4,9 dB, OP1dB= +10,5 dBm, supply= 3,5 V/35 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	2,40
GALI-52	Amplifier, MPA, F= DC-2000 MHz, Gn= 16 dB/2 GHz, NF= 2,7 dB, OP1dB= +15,5 dBm, supply= 4 V/50 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	2,60
GALI-74	Amplifier, LPA, F= DC-1000 MHz, Gn= 25 dB/0,1 GHz, NF= 2,7 dB, OP1dB= +19,2 dBm/0,1 GHz, supply= 4,8 V/80 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	4,70
GALI-S66	Amplifier, LPA, F= DC-3000 MHz, Gn= 15 dB/2 GHz, NF= 2,7 dB, OP1dB= +2,8 dBm, supply= 3,5 V/16 mA, Topr= -45° to +85°C, plastic SM pkg SOT-89	2,00
LEE-19	Amplifier, MPA, F= DC-8000 MHz, Gn= 9,6 dB/2 GHz, NF= 6,5 dB, OP1dB= +10,2 dBm, supply= 3,6 V/40 mA, Topr=-45° to + 85°C, plastic SM pkg 3x3 mm	3,36
LEE-29	Amplifier, MPA, F= DC-8000 MHz, Gn= 13,3 dB/2 GHz, NF= 5,5 dB, OP1dB= +10,9 dBm, supply= 3,6 V/40 mA, Topr= -45° to + 85°C, plastic SM pkg 3x3 mm	3,36
LEE-49	Amplifier, MPA, F= DC-5000 MHz, Gn= 12 dB/2 GHz, NF= 5,5 dB, OP1dB= +16,4 dBm, supply= 4,9 V/65 mA, Topr= -45° to + 85°C, plastic SM pkg 3x3 mm	5,04
LEE-59	Amplifier, MPA, F= DC-5000 MHz, Gn= 17,5 dB/2 GHz, NF= 4,5 dB, OP1dB= +17,3 dBm, supply= 4,8 V/65 mA, Topr= -45° to + 85°C, plastic SM pkg 3x3 mm	5,04
MAR-1SM	Amplifier, LPA, F= DC-1000 MHz, Gn= 13 dB/1 GHz, NF= 5,5 dB, OP1dB= +1,5 dBm, supply= 5 V /17 mA, Topr= -20° to + 85°C, plastic SM pkg 4L Micro-X,	1,82
MAR-2SM	Amplifier, LPA, F= DC-2000 MHz, Gn= 8,5 dB/2 GHz, NF= 6,5 dB, OP1dB= +4,5 dBm, supply= 5 V/25 mA, Topr= -20° to +85°C, plastic SM pkg 4L Micro-X,	2,00
MAR-3SM	Amplifier, MPA, F= DC-2000 MHz, Gn= 8 dB/2 GHz, NF= 6 dB, OP1dB= +10 dBm, supply= 5 V/35 mA, Topr= -20° to +85°C, plastic SM pkg 4L Micro-X,	2,10
MAR-6SM	Amplifier, LPA, F= DC-2000 MHz, Gn= 9 dB/2 GHz, NF= 3 dB, OP1dB= +2 dBm, supply= 3,5 V/16 mA, Topr= -20° to +85°C, plastic SM pkg 4L Micro-X,	2,03
MAR-7	Amplifier, LPA, F= DC-2000 MHz, Gn= 9 dB/2 GHz, NF= 5 dB, OP1dB= +5,5 dBm, supply= 4 V/22 mA, Topr= -20° to +85°C, plastic drop-in pkg 4L Micro-X,	2,45
MAR-7SM	Amplifier, LPA, F= DC-2000 MHz, Gn= 8,5 dB/2 GHz, NF= 5 dB, OP1dB= +5,5 dBm, supply= 4 V/22 mA, Topr= -20° to +85°C, plastic SM pkg 4L Micro-X,	2,52
MAR-8A	Amplifier, MPA, F= DC-1000 MHz, Gn= 20 dB/1 GHz, NF= 3,1 dB, OP1dB= +12,5 dBm, supply= 3,7 V/36 mA, Topr= -40° to + 85°C, plastiic drop-in pkg 4L Micro-X,	3,71
MAR-8ASM	Amplifier, MPA, F= DC-1000 MHz, Gn= 20 dB/1 GHz, NF= 3,1 dB, OP1dB= +12,5 dBm, supply= 3,7 V/36 mA, Topr= -40° to + 85°C, plastic SM pkg 4L Micro-X,	3,36
MAR-8SM	Amplifier, MPA, F= DC-1000 MHz, Gn= 19 dB/1 GHz, NF= 3,3 dB, OP1dB= +12,5 dBm, supply= 7,8 V/36 mA, Topr= -20° to + 85°C, non-hermetic plastic SM pkg 4L Micro-X,	2,45
MAV-11SM	Amplifier, MPA, F= 50-1000 MHz, Gn= 9 dB/1 GHz, NF= 3,6 dB, OP1dB= +17,5 dBm, supply= 5,5 V/60 mA, Topr= -20° to +85°C, plastic SM pkg 4L Micro-X,	3,15
MNA-2	Amplifier, MPA, F= 500-2500 MHz, Gn= 10,3 dB/2 GHz, NF= 5,4 dB, OP1dB= +17,7 dBm, supply= 2,8 V/60 mA and 5 V/76 mA, Topr= -40° to + 85°C, plastic SM pkg 3x3 mm	3,80

MNA-3	Amplifier, MPA, F= 500-2500 MHz, Gn= 13 dB/2 GHz, NF= 4,9 dB, OP1dB= +11,4 dBm, supply= 2,8 V/28 mA and 5 V/30 mA, Topr= -40° to + 85°C, plastic SM pkg 3x3 mm	3,20
MNA-4	Amplifier, MPA, F= 500-2500 MHz, Gn= 14 dB/2 GHz, NF= 4,8 dB, OP1dB= +19 dBm, supply= 2,8 V/67 mA and 5 V/75 mA, Topr= -40° to + 85°C, plastic SM pkg 3x3 mm	3,80
MNA-5	Amplifier, MPA, F= 500-2500 MHz, Gn= 17 dB/2 GHz, NF= 3,5 dB, OP1dB= +12,2 dBm, supply= 2,8 V/26 mA and 5 V/28 mA, Topr= -40° to + 85°C, plastic SM pkg 3x3 mm	3,20
MNA-6	Amplifier, MPA, F= 500-2500 MHz, Gn= 21,5 dB/2 GHz, NF= 2,9 dB, OP1dB= +18 dBm, supply= 2,8 V/65 mA and 5 V/72 mA, Topr= -40° to + 85°C, plastic SM pkg 3x3 mm	4,50
MNA-7	Amplifier, MPA, F= 1500-5900 MHz, Gn= 15 dB/2 GHz, NF= 6,9 dB, OP1dB= +15,6 dBm, supply= 2,8 V/65 mA and 5 V/73 mA, Topr= -40° to + 85°C, plastic SM pkg 3x3 mm	4,50
RAM-3	Amplifier, MPA, F= DC-2000 MHz, Gn= 8 dB/2 GHz, NF= 6 dB, OP1dB= +10 dBm, supply= 5 V/35 mA, Topr= -54° to +125°C, ceramic SM pkg 4L Micro-X	6,93
RAM-6	Amplifier, LPA/LNA, F= DC-2000 MHz, Gn= 9 dB/2 GHz, NF= 2,8 dB, OP1dB= +2 dBm, supply= 3,5 V /16 mA, Topr= -54° to +125°C, ceramic SM pkg 4L Micro-X	6,93
RAM-8	Amplifier, MPA/LNA, F= DC-1000 MHz, Gn= 19 dB/1 GHz, NF= 3 dB, OP1dB= +12,5 dBm, supply= 7,8 V /36 mA, Topr= -54° to +125°C, ceramic SM pkg 4L Micro-X	6,93
VAM-77	Amplifier, LPA, F= DC-6000 MHz, Gn= 11 dB/2 GHz, NF= 3,8 dB, OP1dB= +4 dBm, supply= 3,3 V/ 22 mA, Topr= -20° to +85°C, plastic SM pkg SOT-143	2,20
VAM-93	Amplifier, MPA, F= DC-3000 MHz, Gn= 17 dB/2 GHz, NF= 3,7 dB, OP1dB= +12,7 dBm, supply= 3,2 V/ 35 mA, Topr= -20° to +85°C, plastic SM pkg SOT-143	2,20
VNA-21	Amplifier, MPA, F= 500-2500 MHz, Gn= 12,6 dB/2 GHz, NF= 6,4 dB, OP1dB= +8,5 dBm, supply= 5 V/31 mA and 2,8 V/29 mA, Topr= -40° to +85°C, plastic SM pkg	3,60
VNA-23	Amplifier, MPA, F= 500-2500 MHz, Gn= 15,4 dB/2 GHz, NF= 4,7 dB, OP1dB= +10 dBm, supply= 5 V/32 mA and 2,8 V/29 mA, Topr= -40° to +85°C, plastic SM pkg	3,80
VNA-25	Amplifier, MPA, F= 500-2500 MHz, Gn= 16 dB/2 GHz, NF= 5,5 dB, OP1dB= +18,2 dBm, supply= 5 V/85 mA and 2,8 V/80 mA, Topr= -40° to +85°C, plastic SM pkg	4,95
	(Mitsubishi Electric Semiconductors)	
M67743L-01	Amplifier, HPA, F= 68-81 MHz, IP= 40 mW, OP=10 W, supply= 12,5 V, module	44,95
	(RF Micro Devices)	
NDA-212	Amplifier, MPA , F= DC-17 GHz, Gn= 6 dB, NF= 6,5 dB, OP1dB= +12,6 dBm, supply= 2,98 V/36 mA, Topr= -45° to +85°C, ceramic SM pkg MPGA 3x3	14,75
NDA-313	Amplifier	14,35
RF2044	Amplifier, MPA, F= DC-6000 MHz, Gn= 20 dB, NF= 4,1 dB, OP1dB= +18,5 dBm, supply= 4,3-5,3 V, Topr= -40° to +85°C, plastic SM pkg microX-CF	15,28
RF2046	Amplifier, MPA, F= DC-3000 MHz, Gn= 22 dB, NF= 3,8 dB, OP1dB= +12 dBm, supply= 3-4 V, Topr= -40° to +85°C, plastic SM pkg microX-CF	14,33
RF2126	Amplifier, HPA, linear, F= 1800-2500 MHz, Gn= 12 dB, OP= 1,3 W at 6 V, Eff= 45%, supply= 3-6,5 V, Topr= -40° to +85°, plastic SM pkg PSOP-8	20,68
RF2129	Amplifier, MPA, linear, F= 1800-2500 MHz, Gn= 27 dB, OP= 400 mW at 3,3 V, Eff= 42 %, supply= 3-5 V, Topr= -40° to +85°, plastic SM pkg PSOP-8	24,00
RF2138	Amplifier, HPA, linear, F= 800-950 MHz, Gn= 32 dB, OP= 4 W at 3,5 V, Eff= 58%, supply= 4,2- 6 V, Topr= -40° to +85°, ceramic SM pkg MP16K01A	13,75
RF2152	Amplifier, MPA, linear, F= 800-960 MHz, Gn= 30 dB, OP= 500 mW/1,1 W at 3 V, Eff= 36/45%, supply= 3- 5,2 V, Topr= -40° to +85°, plastic SM pkg PPSOP-16	26,05
RF2162	Amplifier, MPA, linear, 3 V, F= 800-960 MHz, Gn= 29 dB, OP= 800 mW at 3,4 V, Eff= 45%, supply= 3,4 V, Topr= -40° to +85°C, plastic SM pkg QLF-16	24,89
RF2163	Amplifier, HPA, linear, 3 V, F= 1800-2500 MHz, Gn= 19 dB, OP= 1,6 W at 3,3 V, Eff= 40%, supply= 3-5 V, Topr= -40° to +85°C, plastic SM pkg QFN-16	9,47
RF2189	Amplifier, MPA, linear, 3 V, F= 1800-2500 MHz, Gn= 20 dB, OP= 400 mW at 3,3 V, Eff= 42%, supply= 3-5 V, Topr= -40° to +85°C, plastic SM pkg QFN-16	7,60
RF2312	Amplifier, MPA, linear, F= DC-2500 MHz, Gn= 15 dB, NF= 3,8 dB, OP1dB= 20 dBm, supply= 5-12 V, Topr= -40° to +85°C, plastic SM pkg SOIC-8	11,63
RF2317	Amplifier, MPA, linear, F= DC-3000 MHz, Gn= 15 dB, NF= 4,9 dB, OP1dB= 26 dBm, supply= 9-12 V, Topr= -40° to +85°C, plastic SM pkg CJ2BAT0	12,06
RF2320	Amplifier, MPA, linear, F= 5-2500 MHz, Gn= 16 dB, NF= 1,6 dB, OP1dB= 22,5 dBm, supply= 6-9 V, Topr= -40° to +85°C, plastic SM pkg CJ2BAT0	8,43
RF2338	Amplifier, MPA, F= DC-6000 MHz, Gn= 12 dB, OP1dB= 10,5 dBm, supply> 3,6 V, Topr= -40° to +85°C, plastic SM pkg SOT23-5	3,13
RF2360	Amplifier, MPA, linear, F= 5-1500 MHz, Gn= 20 dB, NF= 1,2 dB, OP1dB= 24 dBm, supply= 6-9 V, Topr= -40° to +85°C, plastic SM pkg CJ2BAT0	10,95
RF2361	Amplifier, MPA/LNA, 3 V PA driver, F= 150-2500 MHz, Gn=20,5 dB, NF=1,4 dB, OP1dB= 15,5 dBm, supply= 2,5-6 V, Topr= -40° to +85°C, plastic SM pkg SOT23-5	3,41
RF2369	Amplifier, LPA/LNA, 3 V PA driver, F= 150-2500 MHz, Gn= 15,5 dB, NF= 1,6 dB, supply= 3 V, Topr= -40° to +85°C, plastic SM pkg SOT23-6	9,16
RF2376	Amplifier, linear variable gain, F= 800-1000 MHz, Gn= 27 dB, NF= 7 dB, supply= 2,8 V, Topr= -40° to +85°C, plastic SM pkg SOT23-6	12,45
RF2472	Amplifier, LPA/LNA, F= DC-6000 MHz, Gn= 14,6 dB, NF= 1,5 dB, OP1dB= -10 dBm, supply= 2,7-3,6 V, Topr= -40° to +85°C, plastic SM pkg SOT23-5	5,36
RF3806	Amplifier, HPA, pre-driver, F= 1500-2200 MHz, Gn= 19 dB, OP1dB= +36 dBm supply= 5-8 V, Tamb= +85°C, „2"x,2" SMD	26,86
	(Sirenza Microdevices, Inc.)	

NGA-286	Amplifier, MPA cascachable, F= DC-6000 MHz, Gn= 14,8 dB/ 2 GHz, NF= 3,4 dB, OP1dB= +15,2 dBm, supply= 4 V/50 mA, Topr= -45° to +85°C, GaAsHBT MMIC, plastic SM pkg 4L Micro-X	3,85
SGA-0163	Amplifier, LPA, cascachable, F= DC-4500 MHz, Gn= 12 dB/2 GHz, NF= 4,6 dB, OP1dB= -1,8 dBm, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg SOT-363	1,15
SGA-0363	Amplifier, LPA, cascachable, F= DC-5000 MHz, Gn= 17,2 dB/2 GHz, NF= 3 dB, OP1dB= 2,3 dBm, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg SOT-363	1,15
SGA-1263	Amplifier, LPA, cascachable, F= DC-4000 MHz, Gn= 13 dB/2GHz, NF= 2,8 dB, OP1dB= -5 dBm, supply= 2,6 V/10 mA, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg SOT-363	1,15
SGA-2163	Amplifier, LPA, cascachable, F= DC-5000 MHz, Gn= 10,2 dB/2GHz, NF= 4,1 dB, OP1dB= +7,5 dBm, supply= 2,2 V/ 20 mA, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg SOT-363	1,15
SGA-2186	Amplifier, LPA, cascachable, F= DC-5000 MHz, Gn= 9,3 dB/2GHz, NF= 4,7 dB, OP1dB= +7,5 dBm, supply= 2,2 V/20 mA, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg 4L Micro-X	1,57
SGA-2263	Amplifier, LPA, cascachable, F= DC-3500 MHz, Gn= 14 dB/ 2GHz, NF= 3,2 dB, OP1dB= +7 dBm, supply= 2,2 V/ 20 mA, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg SOT-363	1,20
SGA-2363	Amplifier, LPA, cascachable, F= DC-2800 MHz, Gn= 16,4 dB/2GHz, NF= 2,9 dB, OP1dB= +7 dBm, supply= 2,7 V/20 mA, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg SOT-363	1,15
SGA-4186	Amplifier, MPA, cascachable, F= DC-6000 MHz, Gn= 9,0 dB/2GHz, NF= 4,7 dB, OP1dB= +12,4 dBm, supply= 3,2 V/45 mA, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg 4L Micro-X	2,02
SGA-5389	Amplifier, MPA, cascachable, F= DC-4500 MHz, Gn= 15,4 dB/2GHz, NF= 3,5 dB, OP1dB= +15 dBm, supply= 3,6 V/60 mA, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg SOT-89	1,62
SGA-7489	Amplifier, MPA, F= DC-3000 MHz, Gn= 18,3 dB/2GHz, NF= 2,9 dB, OP1dB= +20,3 dBm, supply= 5 V, Topr= -40° to +85°C, SiGeHBT MMIC, plastic SM pkg SOT-89	2,96
SNA-300	Amplifier, MPA, cascachable, F= DC-3000 MHz, Gn= 22 dB/2 GHz, NF= 4 dB, OP1dB= +10 dBm, supply= 4 V/35 mA, Topr= -45° to +85°C, GaAs MMIC, chip DIE	9,95
SXT-289	Amplifier, MPA, F= 1800-2500 MHz, Gn= 15 dB/2 GHz, NF= 4,4 dB, OP1dB= +23,5 dBm, supply= 5 V/105 mA, Topr= -40° to +85°C, GaAs MMIC, plastic SM pkg SOT-89	9,68
	(WJ Communications, Inc.)	
AH110-89	Amplifier, MPA, F= 50-2000 MHz, Gn= 20,5 dB, NF= 5,2 dB, OP1dB= +23 dBm, supply= 8 V/100 mA, Topr= -40° to +85°C, SM pkg SOT-89	5,95
AH22	Amplifier, MPA, F= 50-1000 MHz, Gn= 14,5 dB, NF= 4,5 dB, OP1dB= +24 dB, supply= 5 V/150 mA, Topr= -40° to +85°C, SM pkg SOIC-8	11,00
AH4	Amplifier, MPA/LNA, F= 250-6000 MHz, Gn= 13,5 dB, NF= 2,7 dB, OP1dB= +21 dBm, supply= 5 V/120 mA, Topr= -40° to +80°C, SM pkg LGA 3x3	8,75
	(Mini-Circuits)	
ELS-1300	Electronic Line Stretcher, F= 750-1300 MHz, IP= 10 dBm, Ph R= 360°, RL= 10-12 dB, Vcntrl= 1-25 V, Topr= 0° to +50°C, connector SMA(f)	209,93
	(Coilcraft, Inc.)	
D101	Filters, low pass, LC, kit, serie P, poles: 3 and 7, Fcutoff(-3dB)= 0,30-500 MHz, Imp=50 Ohm, Six 7-pole, Six 3-pole filters (2 of each)	102,53
P7LP-155	Filter, low pass LC, 7-pole, 50 Ohm, Fcutoff(-3dB)= 1,5 MHz, Irms= 200 mA, IL= 0,3 dB, Topr= -40°C to +85°C, plug-in pkg	2,99
P7LP-304	Filter, low pass LC, 7-pole, 50 Ohm, Fcutoff(-3dB)= 0,30 MHz, Irms= 100 mA, IL= 0,3 dB, Topr= -40°C to +85°C, plug-in pkg	2,99
P7LP-306	Filter, low pass LC, 7-pole, 50 Ohm, Fcutoff(-3dB)= 30 MHz, Irms= 400 mA, IL= 0,3 dB, Topr= -40°C to +85°C, plug-in pkg	2,99
P7LP-307	Filter, low pass LC, 7-pole, 50 Ohm, Fcutoff(-3dB)= 300 MHz, Irms= 600 mA, IL= 0,3 dB, Topr= -40°C to +85°C, plug-in pkg	2,99
P7LP-507	Filter, low pass LC, 7-pole, 50 Ohm, Fcutoff(-3dB)= 500 MHz, Irms= 600 mA, IL= 0,3 dB, Topr= -40°C to +85°C, plug-in pkg	2,99
P7LP-604	Filter, low pass LC, 7-pole, 50 Ohm, Fcutoff(-3dB)= 0,60 MHz, Irms= 200 mA, IL= 0,3 dB, Topr= -40°C to +85°C, plug-in pkg	2,99
P7LP-605	Filter, low pass LC, 7-pole, 50 Ohm, Fcutoff(-3dB)= 6,0 MHz, Irms= 250 mA, IL= 0,3 dB, Topr= -40°C to +85°C, plug-in pkg	2,99
P7LP-606	Filter, low pass LC, 7-pole, 50 Ohm, Fcutoff(-3dB)= 60 MHz, Irms= 500 mA, IL= 0,3 dB, Topr= -40°C to +85°C, plug-in pkg	2,99
S3HP306	Filter, high pass LC, 3-pole, 50 Ohm, Fcutoff(-3dB)= 30 MHz, Irms= 300 mA, IL= 0,3 dB, Topr= -40° to +85°C, SM pkg	2,00
S3HP606	Filter, high pass LC, 3-pole, 50 Ohm, Fcutoff(-3dB)= 60 MHz, Irms= 300 mA, IL= 0,3 dB, Topr= -40° to +85°C, SM pkg	2,00
	(K&L Microwave, Inc.)	
3DH35-1012.5/U72-1.8	Filter, bandpass, ceramic, 3-pole, 50 Ohm, Fco= 1012,5 MHz, BW(1dB)= 72 MHz, VSWR= 2,0:1, Topr= -40° to +85°C, .5" x .5" SMD	-
	(Mini-Circuits)	
HFCN-7	Filter, high pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 700 MHz, VSWR= 1,5:1, IP(RF)= 7 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	3,68
HFCN-12	Filter, high pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 1180 MHz, VSWR= 1,5:1, IP(RF)= 7 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	3,68
HFCN-650	Filter, high pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 650 MHz, VSWR= 1,5:1, IP(RF)= 7 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	6,99

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LFCN-2250	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 2575 MHz, VSWR= 1,2:1, IP(RF)= 10 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg,	6,99
LFCN-2400	Filter, low pass, 5-pole, 50 Ohm, Fcutoff(3dB)= 2800 MHz, VSWR= 1,2:1, IP(RF)= 9 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	6,99
LFCN-2500	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 3075 MHz, VSWR= 1,2:1, IP(RF)= 10 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	6,99
LFCN-2600	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 3125 MHz, VSWR= 1,2:1, IP(RF)= 10 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg,	6,99
LFCN-2750	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 3150 MHz, VSWR= 1,2:1, IP(RF)= 10 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	6,99
LFCN-2850	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 3300 MHz, VSWR= 1,2:1, IP(RF)= 10 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg,	6,99
LFCN-3000	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 3600 MHz, VSWR= 1,2:1, IP(RF)= 10 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	6,99
LFCN-5000	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 5580 MHz, VSWR= 1,2:1, IP(RF)= 9 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	6,99
LFCN-6000	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 6800 MHz, VSWR= 1,3:1, IP(RF)= 9 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	6,99
LFCN-6700	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 7600 MHz, VSWR= 1,3:1, IP(RF)= 9 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	6,99
LFTC-850	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 1078 MHz, VSWR= 1,2:1, IP(RF)= 16 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	8,95
LFTC-1350	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 1550 MHz, VSWR= 1,2:1 IP(RF)= 15 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	8,95
LFTC-1700	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 1980 MHz, VSWR= 1,2:1, IP(RF)= 14 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	8,95
LFTC-5400	Filter, low pass, 7-pole, 50 Ohm, Fcutoff(3dB)= 6410 MHz, VSWR= 1,1:1, IP(RF)= 19 W, Topr= -55° to +100°C, blue cell technology, ceramic SM pkg	8,95
NBP-10.7	Filter, low pass, coaxial, 50 Ohm, Fco= 10,7 MHz, BW(3dB)= 8,9-12,7 MHz, IP(RF)= 0,5 W, Topr= -55° to +100°C, connector N(m)/N(f)	61,53
PLP-15	Filter, low pass, 50 Ohm, Fcutoff(3dB)= 17 MHz, VSWR= 1,7:1, IP(RF)= 0,5 W, Topr= -55° to +100°C, metal plug-in pkg	16,03
PLP-200	Filter, low pass, 50 Ohm, Fcutoff(3dB)= 210 MHz, VSWR= 1,7:1, IP(RF)= 0,5 W, Topr= -55° to +100°C, metal plug-in pkg	16,03
PLP-300	Filter, low pass, 50 Ohm, Fcutoff(3dB)= 297 MHz, VSWR= 1,7:1, IP(RF)= 0,5 W, Topr= -55° to +100°C, metal plug-in pkg	16,03
SCLF-700	Filter, low pass, 50 Ohm, Fcutoff(3dB)= 770 MHz, VSWR= 1,7:1, IP(RF)= 0,5 W, Topr= -40° to +85°C, plastic SM pkg	18,13
SCLF-21.4	Filter, low pass, 50 Ohm, Fcutoff(3dB)= 24,5 MHz, VSWR= 1,7:1, IP(RF)= 0,5 W, Topr= -40° to +85°C, plastic SM pkg	16,03
VLF-1700	Filter, low pass, coaxial, 7-pole, Fcutoff(3dB)= 2050 MHz, VSWR= 1,2:1, IP(RF)= 10 W, Topr= -55° to +100°C, connector SMA(m)/SMA(f)	30,73
(Sawtek, Inc.)		
855653	Filter, bandpass, SAW, 50 Ohm, Fco= 374 MHz, BW= 17 MHz, IL= 11 dB, Topr= -40° to +85°C, ceramic SM pkg 7,0x5,5 mm	16,83
EMI/RFI (Coilcraft, Inc.)		
0805USB-902MB_	Filter, USB2,0 common mode, F= 10-500 MHz, Att= 8,7 - 30,5 dB, L= 560 nH ± 20%, DCR= 0,65 Ohms, Irms= 400 mA, Topr= -40° to +85°C, SM pkg	0,77